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Recent advancements in graphitic carbon nitride based direct Z- and S-scheme heterostructures for photocatalytic H₂O₂ production

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Escalating global energy demands and the pressing need for sustainable and environmentally friendly energy sources have intensified research in the field of renewable energy, particularly solar energy. Hydrogen peroxide (H₂O₂), as a green and sustainable oxidant, is important for environmental remediation, chemical synthesis, and as a next-generation energy fuel. Solar energy harnessed in photocatalysis enables light-driven H₂O₂ production, offering an eco-friendly synthesis method. High-performance photocatalysts are essential for achieving viable solar H₂O₂ synthesis. Photocatalysis, particularly using g-C₃N₄, a visible-light-responsive metal-free semiconductor, presents a promising avenue for future large-scale H₂O₂ production. This is due to its unique properties, such as its oxygen-reduction-friendly conduction band, tuneable molecular structure, stability, cost-effectiveness, Earth abundance, facile synthesis, non-toxicity, numerous active sites, surface imperfections and high selectivity for H₂O₂ generation, making it a vital material in the renewable energy sector. However, challenges like rapid exciton recombination, limited light absorption capacity, suboptimal electrical conductivity, low specific surface area, and slow water oxidation kinetics need to be addressed to enhance its catalytic efficiency. Hence, the development of direct Z- or more relevant S-scheme heterostructures of g-C₃N₄ could promote the charge carrier separation efficiency, optimize the redox potential and improve the photocatalytic activity significantly. This review focuses on g-C₃N₄ as a photocatalyst, emphasizing its properties and the potential of direct Z- and S-scheme heterojunctions in photocatalytic H₂O₂ production. It introduces the background and surge in research on these heterojunctions, covers design principles, charge transfer mechanisms, advanced characterization methods, driving force enhancement strategies, Fermi level adjustment tactics, and principles of H₂O₂ production, including formation pathways, kinetics, detection, and performance evaluation. It offers insights into g-C₃N₄-based heterostructures' potential for application in H₂O₂ production and concludes with future prospects and challenges, focusing on strategies to enhance yields and suggesting new research directions.

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1. Introduction

The search for renewable energy sources has become a critical focus for society, as on-going reliance on non-renewable fossil fuels has led to significant environmental and energy challenges.¹ Among the various renewable options such as wind, tidal, ocean currents, and hydroelectric energy, solar energy stands out for its almost limitless potential and environmental benefits.^{2,3} Sunlight provides an impressive 1.19×10^{17} J to the Earth per second, offering a clean and abundant source for energy production.⁴ Research into solar fuels, particularly

since the pioneering work of Fujishima and Honda on water splitting, has gained widespread attention.⁵ These fuels provide a way to convert sunlight into other forms of energy or valuable chemicals, a concept inspired by nature's photosynthesis where plants and organisms turn CO₂ into carbohydrates.⁶ This biological process has served as a model for green solar-to-chemical conversions, including ammonia synthesis, hydrogen (H₂) evolution, and hydrocarbon production. However, despite their promise, the current state of solar fuels is not yet cost-competitive with fossil fuels.⁷ One widely considered approach to cost-effective solar fuel production is the generation of H₂ through the water splitting reaction.^{8,9} Unfortunately, water-splitting systems face multiple challenges, including high production costs, complex synthesis conditions, and the low energy density of H₂ generated.¹⁰ Therefore, H₂O₂ as a liquid is easier to store and transport

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than H_2 gas, making it a promising fuel for rockets and new energy vehicles like jet cars.^{11–13} Additionally, H_2O_2 as a safe and efficient green oxidant has received immense research interest in sectors such as pulp and textile manufacturing for decolourization processes,¹⁴ as well as in chemical production,¹⁵ remediation of wastewater,¹⁶ metal mining,¹⁷ detergents,¹⁸ and fuel cell technologies,¹⁹ as illustrated in Fig. 2. The anticipated worth of H_2O_2 is projected to rise from \$3.86 billion in the year 2023 to \$4.09 billion in 2024; with an estimated yearly expansion rate of 6.16%, the market is expected to attain a valuation of \$5.87 billion by 2030.²⁰ Its high active oxygen content and safe byproducts, *i.e.* water and oxygen, make it ideal for environmental clean-up. Unlike traditional disinfectants, H_2O_2 does not produce harmful byproducts, a feature increasingly valued during times of high demand like the COVID-19 crisis.²¹ In environmental remediation, it sterilizes bacteria and breaks down organic pollutants through advanced oxidation processes (AOPs), generating hydroxyl radicals *via* Fenton-like reactions or UV exposure.²² Overall, its efficiency, safety, and versatility make H_2O_2 a go-to for both cleaning and potential energy storage. Presently, the anthraquinone (AQ) oxidation method dominates industrial H_2O_2 production and is responsible for the vast majority of the total output.^{23,24} However, this process has inherent limitations, such as high energy requirements, resource-intensive reactions, and complex operation, purification and transportation steps. Additionally, it generates a considerable amount of hazardous byproducts. Given these constraints, alternative methods like photocatalysis and electrocatalysis are attracting increasing research attention.^{25–30} Although electrocatalysis yields more H_2O_2 , its high energy input restricts its broad application. On the other hand, semiconductor based photocatalysis operates under ambient conditions and offers a more sustainable approach by converting water (H_2O) and oxygen (O_2) into H_2O_2 , using cost-effective and abundant raw

materials, solely powered by renewable solar energy.^{31–33} Moreover, it offers the advantage of on-demand, on-site production, thereby mitigating the risks associated with the handling and distribution of concentrated H_2O_2 . This makes photocatalysis an increasingly attractive route for decentralized and environmentally friendly H_2O_2 production. With its promise for a greener and more cost-effective H_2O_2 synthesis, the field of photocatalytic H_2O_2 production is experiencing rapid growth. The concept of generating H_2O_2 through photocatalysis was originally introduced by Baur and Neuweiler in 1927.³⁴

A number of semiconductors, namely metal oxides,³⁰ metal sulfides,^{35–37} metal phosphides,^{38,39} transition metal dichalcogenides,⁴⁰ transition metal oxyhydroxides,⁴¹ metal-organic frameworks (MOFs),^{42–44} carbon-based semiconductors,^{45–47} metal-free organic semiconductors like $g-C_3N_4$,^{48–50} resins,^{51–58} covalent triazine frameworks (CTFs),⁵⁹ covalent organic frameworks (COFs),^{60,61} covalent heptazine frameworks (CHFs)⁶² and Bi-containing semiconductors,^{63–65} have been extensively investigated for photocatalytic H_2O_2 production. Despite significant research, the field still faces challenges such as low photoconversion efficiency and rapid e^-/h^+ pair recombination, which limit its practical applications. In light of these challenges and considering the environmental benefits of reduced metal utilization, there is an urgent demand for the development of innovative, visible-light-responsive, metal-free photocatalysts to maximize the overall efficiency of solar energy utilization.

Among the plethora of semiconductor photocatalysts studied, graphitic carbon nitride ($g-C_3N_4$) has gained significant interest, particularly in the area of photocatalytic H_2O_2 production. This attention can be attributed to its advantageous electronic band structure, exceptional physicochemical stability, facile synthesis methods, cost-effectiveness, and high resistance to photocorrosion.^{66–72} Additionally, the specific alignment of its conduction and valence bands



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favours oxygen (O_2) reduction while concurrently limiting the undesired oxidative breakdown of H_2O_2 , which gives it an edge over oxide-based alternatives.⁷³ This benefit is further amplified by its high selectivity in generating H_2O_2 through a mechanism involving the formation of superoxide radicals (O_2^-) and subsequent 1,4-endoperoxide intermediates on its melem units. These intermediates effectively inhibit O–O bond cleavage, optimizing H_2O_2 yield during oxygen reduction.⁷⁴ In a pioneering study, Shiraishi and colleagues were the first to showcase the capability of a $g-C_3N_4$ structure to photocatalytically produce H_2O_2 in a water/alcohol mixture. Despite this breakthrough, the process exhibited low efficiency when no sacrificial agent was involved, primarily due to the speedy recombination of charge species and insufficient O_2 adsorption on the catalyst's surface.⁷⁴ In the case of unmodified $g-C_3N_4$, several obstacles impede its practical utility. These challenges encompass rapid charge carrier recombination, limited light absorption capacity, suboptimal electrical conductivity, low specific surface area, and slow water oxidation kinetics due to the weak oxidation ability of holes. To optimize the photoconversion efficiency of pure $g-C_3N_4$, a multitude of nanoengineering strategies have been effectively deployed. These include elemental substitutions with metals and non-metals, the introduction of defects, precise control over morphological attributes, surface functionalization techniques, and the construction of heterojunctions.^{69,75–77} These approaches aim to enlarge the light absorption spectrum and separation efficiency of photoinduced charge carriers. However, it is challenging to significantly enhance both the oxidation and reduction capabilities of $g-C_3N_4$ using a single modification approach. This is because the efficacy of $g-C_3N_4$ largely relies on the potentials of its VB and CB to facilitate specific half-reactions, namely $OH^-/^{\bullet}OH$ and $O_2/^{\bullet}O_2^-$ thermodynamically. Additionally, optimizing $g-C_3N_4$ for enhanced visible light absorption is often at odds with achieving strong

redox potentials. Because enhanced light absorption typically requires a narrower band gap, while stronger redox abilities necessitate more negative potentials for the CB and more positive potentials for the VB, numerous techniques have been suggested for altering the properties of $g-C_3N_4$. However, when considering multiple objectives at once, only the formation of heterojunctions that combine $g-C_3N_4$ with other suitable semiconductor materials seems to comprehensively address all of the concerns previously mentioned.^{77–81}

To date, a diverse array of heterojunctions involving $g-C_3N_4$ have been engineered (Fig. 3) based on the band positions and charge separation mechanism. These include type II, Z-scheme, and S-scheme heterojunctions.^{82–84} Among the variety of heterojunctions, establishing a Z-scheme or S-scheme heterojunction between $g-C_3N_4$ and another oxidative semiconductor presents a viable and logical solution for a singular modification strategy of $g-C_3N_4$. The crux of this approach lies in establishing a robust and closely-knit interface between $g-C_3N_4$ and the other semiconductor, one that features well-aligned CB and VB edges. When materials with different work functions come into contact, an internal electric field is created between them. This field can expedite the movement of photoexcited electron–hole pairs and curtail exciton recombination.^{85,86} Moreover, this well-structured composite not only augments the absorption of visible light but also assures significant oxidation and reduction abilities for photogenerated holes and electrons, respectively. Both of these properties are important for improving the photocatalytic performance.

On the basis of the inimitable advantages of direct Z- and S-scheme heterojunctions in preserving the strong redox ability of the photocatalytic system, Z- and S-scheme-based photocatalysts were widely explored in photocatalytic H_2O_2 production. In particular, numerous articles using $g-C_3N_4$ -based Z- and S-scheme heterojunctions for photocatalytic H_2O_2 pro-



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duction have emerged; therefore, an exhaustive overview of this topic is highly in demand. This work discusses a new breakthrough in g-C₃N₄-based Z-scheme and S-scheme heterojunctions towards H₂O₂ production under visible light illumination (Fig. 4). We exclusively focus on g-C₃N₄ as a photocatalyst with a detailed discussion of its properties and its Z-scheme and more relevant S-scheme heterojunctions for photocatalytic H₂O₂ applications (Fig. 1). In this review, first of all, the proposed background and upsurge in research on direct Z- and S-scheme heterojunctions are elaborately introduced. Secondly, the design principles and characterization methods of Z- and S-scheme heterojunctions have been systematically described. Moreover, the photocatalytic applications of current advancements in g-C₃N₄-based direct Z- and S-scheme heterojunctions have been described in detail, with respect to H₂O₂ generation, highlighting the important finding of the recently reported state of the art. The review also systematically describes the fundamentals of H₂O₂ evolution along with a brief description of the peroxide formation pathway over g-C₃N₄ and detection techniques. We have included a short narrative on different types of reaction conditions for optimising photocatalytic H₂O₂ generation efficiency. Finally, we try to summarize the future prospects of this emerging area of research towards green fuel generation along with the associated challenges and measures taken to address the issues encountered.

2. Graphitic carbon nitride (g-C₃N₄): a sustainable photocatalyst

Graphitic carbon nitride (g-C₃N₄), the most stable allotrope composed of the abundant elements carbon and nitrogen, is a noteworthy metal-free conjugated organic n-type semiconductor. Since its discovery in 2009 by Wang *et al.*, g-C₃N₄ has gained significant attention in the arena of photocatalysis, especially for its role in photocatalytic hydrogen production through water splitting.⁸⁷ Its robust physicochemical stability, abundance on Earth, desirable electronic band structure, and straightforward preparation process make it an excellent photocatalyst.^{88,89} Interestingly, the early version of this material, known as “melon”, was first created by Berzelius in 1834 and later named by Liebig.⁹⁰ Despite its long history, the application of g-C₃N₄ in heterogeneous catalysis only began around 2006, marking a new era in its utilisation. Carbon nitride is known for its diverse structural forms, including α-C₃N₄, β-C₃N₄, cubic-C₃N₄, pseudocubic-C₃N₄, and notably, graphitic-C₃N₄ (g-C₃N₄). The latter, g-C₃N₄, is particularly esteemed as the most stable allotrope, thanks to its outstanding chemical and thermal stability.⁹¹ Studies on the inner workings of g-C₃N₄ have unveiled its intricate structure, which is composed of tri-s-triazine/heptazine (C₆N₇) aromatic heterocycle rings, each featuring secondary nitrogen atoms (Fig. 5). Notably, the tri-s-triazine/heptazine (C₆N₇) components within g-C₃N₄ have been identified as more energetically stable compared to s-triazine (C₃N₃) units, with this stability manifesting as a 30 kJ mol^{−1} lower energy level.⁹² Each layer in the planar structure of g-C₃N₄ is an alternating arrangement of carbon and nitrogen. These rings are linked by planar tertiary amino groups, creating a two-dimensional, pi-conjugated, polymeric structure. This arrangement results in a delocalized π-electron cloud, which underlies the minimal basic nature of the tertiary amines present. Additionally, these layers are held together by weak van der Waals forces, with a notable gap of 0.326 nm between them. This gap facilitates exfoliation of the material into two-dimensional graphitic nanosheets. In each layer, the atoms are strategically organized in a honeycomb configuration and are strongly bonded through covalent bonds, endowing g-C₃N₄ with its highly stable physicochemical properties.^{93,94} Moreover, g-C₃N₄ stands out among its five structural phases by having the lowest band gap. This feature is primarily due to the presence of sp²-hybridized carbon and nitrogen atoms, which facilitate π-conjugated electronic structures.⁷² The electronic structure of g-C₃N₄ is remarkably efficient for visible light absorption, a feature linked to its moderate band gap energy, approximately estimated at 2.7 eV. Additionally, the material exhibits band edge potentials of +1.6 eV for the VB and −1.1 eV for the CB, when measured against the normal hydrogen electrode (NHE). These values align with an optical wavelength in the vicinity of 460 nm, which gives g-C₃N₄ its distinctive yellow colour, a direct result of its specific absorption profile within this wavelength range.⁹⁵ Analysis of the HOMO and LUMO reveals that the VB of g-C₃N₄ primarily



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ication, Prof. Parida (Director) started the ‘Centre for Nano Science and Nano Technology’, a research unit of Siksha ‘O’ Anusandhan (Deemed to be University), Bhubaneswar. His research interests include the design and development of advanced materials encompassing fine chemical, energy generation/storage and environmental applications. He has published more than 509 research articles and review articles in renowned international journals. He has 30 773 citations to his credit with an h-index of 94 and an i10-index of 422. He has featured in the global 2% scientist list for the last four years. For more details see: <https://kmparidaimmt.weebly.com/>.



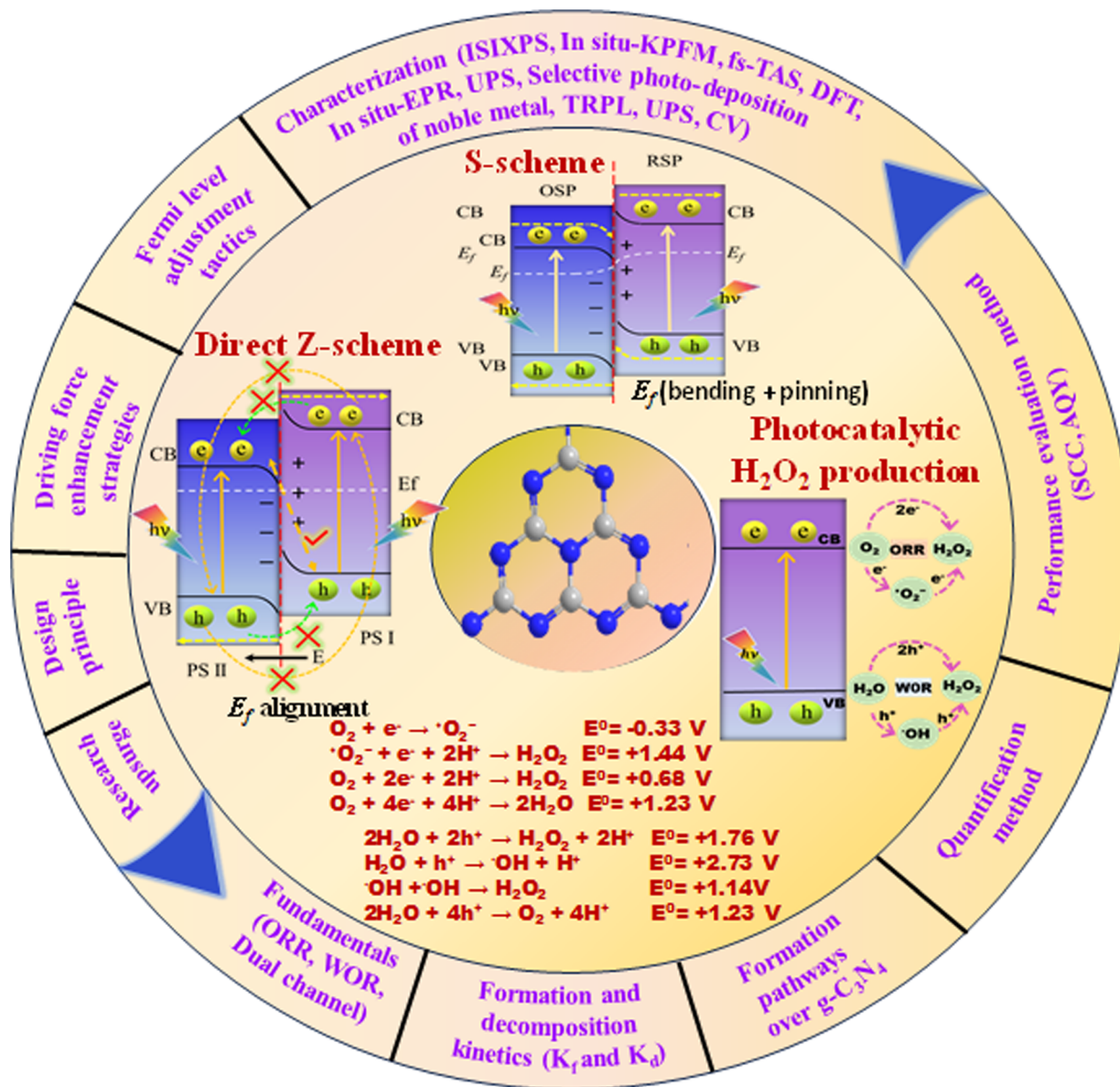


Fig. 1 Comprehensive overview of the key themes and topics covered in the review.

consists of 2p orbitals of nitrogen, while the CB contains 2p orbitals of both carbon and nitrogen.⁹² This structural arrangement endows $g\text{-C}_3\text{N}_4$ with a considerably negative CB, thereby enhancing the reducing power of electrons. This feature makes it highly effective for various catalytic reactions.⁹² Additionally, $g\text{-C}_3\text{N}_4$ exhibits exceptional thermal stability up to 600 °C in air. This resilience is attributed to its aromatic C–N heterocycles. Its chemical stability is equally impressive; it remains stable and does not dissolve in a range of substances, including water, acids, alkalis, and several organic solvents such as alcohols, diethyl ether, and toluene.⁶⁹ This resistance to solvents renders $g\text{-C}_3\text{N}_4$ a versatile material, especially suitable for liquid-phase reactions in a variety of solutions. Beyond its chemical and physical properties, $g\text{-C}_3\text{N}_4$ is also recognized for its biocompatibility and environmentally friendly attributes,

making it an attractive material for diverse applications. Despite extensive research, the practical application of pristine $g\text{-C}_3\text{N}_4$ faces several challenges. These include rapid recombination and inefficient separation of charge carriers due to the merging of N 2p and C 2p states in the CB, and structural irregularities or defects. Additionally, its limited electron mobility, stemming from poor conductivity, and suboptimal solar energy absorption or weak response to visible light further restricts its use. The material's low specific surface area ($10\text{--}15 \text{ m}^2 \text{ g}^{-1}$) results in fewer active sites, impacting its hydrophilicity, crystallinity, and surface properties, while its moderately positive VB energy limits its oxidation capability. The structure of $g\text{-C}_3\text{N}_4$ is comprised of two types of carbon atoms: sp^2 hybridized carbon (N–C=N) and nitrogen-bridging carbon (C–NH₂), as well as three types of nitrogen atoms, namely pyri-

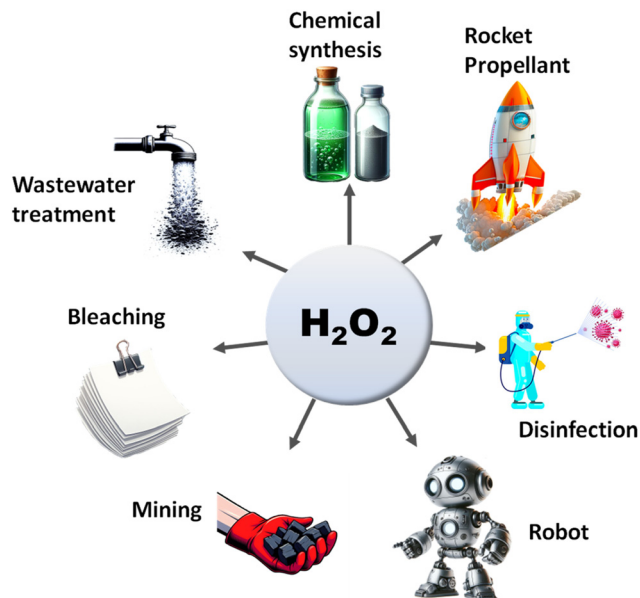


Fig. 2 Diverse applications of hydrogen peroxide.



Fig. 3 Illustration of charge transfer mechanisms in different $g\text{-C}_3\text{N}_4$ -based heterojunctions.

dine nitrogen ($\text{C-N}=\text{C}$), central nitrogen (N-(C)_3), and amino nitrogen (C-N-H). Pyridine nitrogen acts as a site for oxidation reactions on the surface of $g\text{-C}_3\text{N}_4$, while carbon atoms, pyridine nitrogen, and central nitrogen serve as reduction centres during photocatalytic reactions.⁵⁰ However, the bridge-connected nitrogen cannot be photoexcited, leading to the blocking of charge flow between triazine units and impeding inter-layer charge carrier transfer due to weak van der Waals forces. This leads to the recombination of photoinduced charged

species, diminishing the photocatalytic performance. Furthermore, the replacement of highly electronegative nitrogen in the structure by carbon contributes to high symmetry, slowing internal electron transport and e^-/h^+ pair recombination. Given that $g\text{-C}_3\text{N}_4$ is synthesized through the thermal condensation of nitrogen-rich molecules, and the composition of the precursor is adjustable, it is possible to design and construct electron transfer channels within its structure. These channels can break the structural symmetry, enhancing charge transport and separation. To address these issues sustainably, numerous modification approaches have been explored, such as controlling structural defects,⁷⁶ doping with metals or non-metals,⁹⁶ incorporating functional groups,⁷¹ altering its morphology and dimensionality,⁹⁷ introducing metal constituents,⁹¹ employing exfoliation,⁸⁹ and heterojunction formation.⁹⁸ Among these strategies, designing heterojunction structures based on $g\text{-C}_3\text{N}_4$, using semiconductors with varying bandgaps, has become a focal point. These structures are advantageous for separating electron-hole pairs and leveraging the synergistic benefits of different components to enhance performance. Currently, there is growing excitement around the construction of Z- and S-scheme heterostructures using $g\text{-C}_3\text{N}_4$ as a component to balance its strong reducing ability in the CB, offset its weak ability to oxidize holes, and ultimately improve the charge separation efficiency.⁸⁶

The planar structure of $g\text{-C}_3\text{N}_4$ makes it a suitable candidate for the construction of Z- and S-scheme photocatalytic systems. This is particularly due to its increased surface area, which can be easily achieved through a facile exfoliation process. This larger surface area offers a huge number of active sites for photocatalytic reactions, leading to enhanced catalytic activity. Additionally, $g\text{-C}_3\text{N}_4$ has garnered considerable interest as a reduction photocatalyst for its significant capabilities in environmental applications, specifically in various photocatalytic reduction processes. Researchers have been exploring the coupling of $g\text{-C}_3\text{N}_4$ with a wide range of oxidation semiconductor photocatalysts to create Z- and S-scheme nanocomposites. This area of study is crucial for several reasons. Firstly, it helps to maintain a higher redox capability, which is essential for efficient catalytic reactions. Secondly, it enhances the ability to harness solar radiation, making the photocatalytic system more energy-efficient.

3. Construction of heterojunctions

Heterojunctions, which arise from the fusion of two semiconductors with unique bandgaps and electron configurations, lead to the phenomenon of band bending at their interfaces. These interfaces can be differentiated into two distinct types based on their bandgap alignments and the relative positions of their valence bands (VB) and conduction bands (CB): type-II (staggered-gap) and the Z-scheme heterojunction.

The type-II heterojunction is recognized for its advantageous alignment where the VB and CB of S2 are higher in



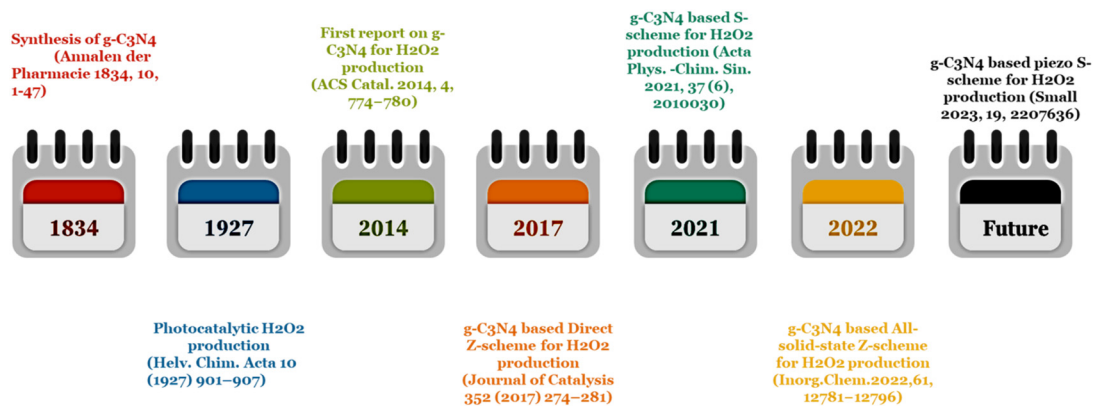


Fig. 4 Evolutionary timeline of g-C₃N₄-based Z- and S-scheme heterojunctions in photocatalytic hydrogen peroxide production.

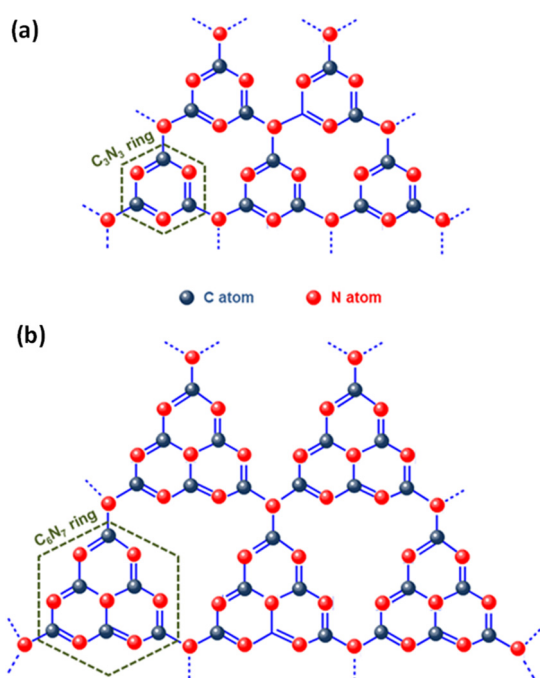


Fig. 5 Structural representation of (a) s-triazine and (b) tri-s-triazine rings within g-C₃N₄. The figures are adapted with permission from ref. 88. Copyright 2020, Wiley-VCH.

energy than those of S1 (as depicted in Fig. 6). This promotes the separation of electrons and holes upon light illumination; electrons move from a higher to a lower energy state, with holes moving in the reverse direction, thereby spatially separating them, but at the expense of the redox potential of the system, adversely affecting photocatalytic processes. Furthermore, the movement of charge carriers would be progressively impeded as like charge carriers continue to build up in their populations. Further in-depth analysis of the charge transfer process revealed a decrease in redox potential, leading to slower redox reaction rates due to the relocation of electrons to the less reductive CB of S1 and the accumulation of holes in the less oxidative VB of S2. This situation also led to the dissi-

pation of some amount of energy unproductively, without directly contributing to photocatalytic reactions.⁹⁹ Additionally, the proposed charge separation process is impeded by electrostatic repulsion between like charges, such as electrons in the CBs of semiconductors and holes in their VBs. Furthermore, the CB of S1 contains a limited array of molecular orbitals with nearly continuous energy levels, each capable of holding just two electrons. Upon photoexcitation, these orbitals fill up with photoinduced electrons, preventing electrons from the CB of S2 from entering. This situation is akin to a hotel where rooms (orbitals) can only be reoccupied once the initial guests (electrons in S1) have vacated, leaving no vacancy for new guests (electrons from S2) until the former are moved elsewhere.⁸⁶ This observation contributed significantly to the emergence of the Z-scheme family. The Z-scheme heterojunction approach has been recognized as a promising alternative to type-II heterojunctions in this context. Moreover, a novel charge transfer configuration, termed the S-scheme heterojunction, has also been recently introduced.¹⁰⁰ This new paradigm is gradually establishing a foothold in the realm of photocatalysis, with Z-scheme and S-scheme heterojunctions already having a wide range of applications.

3.1. Z-Scheme-based heterojunctions

The Z-scheme concept emerges from the natural photosynthesis process performed in plants' chlorophyll pigment to facilitate the thermodynamically uphill conversion of water and carbon dioxide into oxygen and carbohydrates (Fig. 7).

This transformation is facilitated through a two-step photoexcitation process under solar energy irradiation, enabling plants to exploit solar energy efficiently with a quantum efficiency approaching 100%. This model represents the natural and intricate mechanisms by which plants harness solar energy to perform essential life-sustaining transformations.¹⁰¹ Basically, photosystem I (PS I) and photosystem II (PS II) are the two main components of chlorophyll, which are connected in series *via* an electron transfer chain. PS I and PS II harvest solar energy, corresponding to wavelengths of $\lambda \leq 700$ nm and $\lambda \leq 680$ nm, respectively, in the chlorophyll reac-





Fig. 6 Suggested charge transfer pathway in conventional type-II heterojunctions and associated challenges.



Fig. 7 Diagrammatic representation of the natural photosynthesis process.

tion centres and electrons are excited from the highest occupied molecular orbital (HOMO) to the lowest unoccupied molecular orbital (LUMO). After that, the photoinduced electrons in the LUMO of PS II recombine with the HOMO of ferredoxin-NADP reductase (PS I) via an electron transfer chain, which stimulates chemical osmotic potential that causes the transformation of adenosine diphosphate (ADP) into adenosine triphosphate (ATP). The photoexcited electrons accumulated in the HOMO of PS I drift to ferredoxin-NADP⁺ reductase through ferredoxin for the conversion of NADP⁺ into NADPH coenzyme in which the reduction of carbon dioxide to carbohydrate occurs. The photogenerated holes that are present in

the HOMO of PS II act as an oxygen-evolving centre, where the accumulated photogenerated holes oxidize water molecules at the manganese-calcium oxide cluster. Both the above-discussed processes occur simultaneously at different regions of the chlorophyll pigment in plants. This type of charge transfer demonstrates the robust redox ability of PS I and PS II, which is different from the conventional type-II heterojunction. The electron flow path of the cascade profile resembles the letter 'Z' of the English alphabet, from which the name of the Z-scheme system is derived. Thus, excellent redox potential, as well as efficient charge carrier separation, can be attained in the Z-scheme system by the combination of reduction and oxi-



dation semiconductors. Inspired by the unique features of the natural Z-scheme photosynthesis process, the biomimetic artificial Z-scheme photocatalysts synthesized have been extensively studied in the last 30 years, indicating extraordinary advancement in the field of research. The ground-breaking idea of the artificial Z-scheme model was first initiated by Bard in 1979 by imitating the natural photosynthesis process of plants by employing a shuttle redox pair as an electron transport pathway between two photosystems to maximize the redox potential of the photocatalytic heterojunction systems.¹⁰² The accumulation of photoinduced electrons in the CB of PS I make it an electron surplus region, which shows strong reduction potential and suppresses photodegradation from self-oxidation. Similarly, PS II serves as a hole-rich region by the accumulation of photoinduced holes in the VB of PS II, which show a strong oxidation ability and protect PS II from photoreduction. However, this statement reveals that PS II should be a semiconductor with a strong oxidation ability, while PS I should have a strong reduction ability to protect against the corresponding photooxidation and photoreduction and simultaneously promote hydrogen peroxide production. Hence, photocatalysts having poor resistance towards photooxidation cannot be employed as PS II. In summary, a photocatalyst with a smaller resistance to photoreduction is not appropriate for use as PS I.¹⁰³

Furthermore, the number of photoinduced electron and hole pairs in the photocatalytic Z-scheme heterojunction system is just half of that in the conventional photocatalytic system because of the recombination of excitons *via* the electron mediator. However, the Z-scheme heterojunction can efficiently reduce bulk electron-hole recombination and increase the lifespan of photoinduced charge carriers in the isolated photosystem. Based on the condition of whether an additional charge mediator is introduced or not, and the type of the electron mediator taken for charge carrier transfer, the Z-scheme photocatalytic systems can be classified into two types: indirect Z-scheme systems and direct Z-scheme systems (PS-PS systems), respectively.¹⁰⁴

3.1.1. Indirect Z-scheme heterojunctions. The Z-scheme charge transfer path of photoinduced electrons and holes, which is not possible directly but requires an electron mediator, is called an indirect Z-scheme system. On account of the species applied as an electron mediator, indirect Z-scheme systems can be categorised as conventional liquid-phase Z-scheme systems (PS-A/D-PS systems) and all-solid-state Z-scheme systems (PS-C-PS systems).¹⁰⁵

3.1.1.1. Conventional Z-scheme systems. The conventional Z-scheme photocatalyst, the PS-A/D-PS system, involves an electron acceptor/donor (A/D) pair in the liquid phase and two photosystems (PS II and PS I), where this pair operates much like a Ferris wheel between the two photosystems, but without any physical contact between PS II and PS I (Fig. 8a).¹⁰⁶ The direction of electron transport from the CB of PS II to the VB of PS I relies on the below-mentioned redox reactions of the A/D pair:

Forward reactions:



When the photocatalysts are exposed to photons having energy equal to or higher than the bandgap energy (E_g), photoexcitation occurs. Then the reduction of the electron acceptor (A) takes place by the transfer of photoexcited electrons from the CB of PS II to the electron donor (D), and simultaneously, the created electron donor (D) will revert back into its oxidized form (*i.e.*, electron acceptor, A) by consuming the photoinduced holes from the VB of PS I. As a result, the photogenerated electrons from the CB of PS II are indirectly transported to recombine with the photogenerated holes from the VB of PS I with the assistance of the regeneration of the A/D redox pair. The net effect is that photoinduced electrons in the CB of PS I and photoinduced holes in the VB of PS II are efficiently separated (*i.e.*, the system shows largely suppressed charge recombination) and accumulate in the highest possible CB and lowest

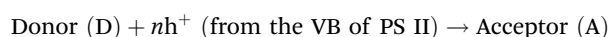
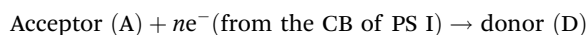


Fig. 8 (a) Suggested (solid lines) and favored (dotted lines) charge transfer pathways in conventional liquid-phase Z-scheme heterojunctions. (b) Diagrammatic depiction of the Brownian movement of photocatalyst particles and thermal movement of redox couple ions in a solution.

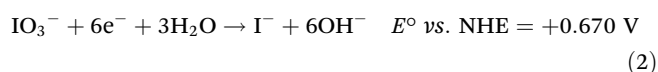
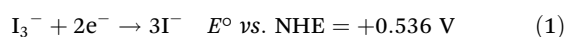
possible VB, providing a considerably large redox potential for the photocatalytic surface redox reaction from the combination of the two photosystems.

Due to the free thermal motion of redox ion pairs in the liquid phase, rapid Brownian movement of photocatalyst nanoparticles and the absence of spatial constraints between redox ion pairs and surface-active sites of photocatalysts, thermodynamically favourable unwanted backward reactions occur (Fig. 8b).¹⁰⁷ Particularly, the photoexcited electrons in PS I possess a higher reduction potential than those in PS II. So, the redox pair acceptors are more prone to receive electrons from PS I instead of PS II. In a similar way, photoinduced holes in PS II have a higher oxidation potential than those in PS I. Therefore, the donor of redox pairs is more willing to give electrons to PS II on behalf of PS I. Hence, the system cannot assure a strong redox potential, which has a negative impact on the photocatalytic reaction.⁹⁹ The commonly utilised electron mediators for the PS-A/D-PS Z-scheme systems are IO_3^-/I^- , $\text{Fe}^{3+}/\text{Fe}^{2+}$, $[\text{Co}(\text{bpy})_3]^{3+/2+}$, $[\text{Co}(\text{phen})_3]^{3+/2+}$, VO_2^+ , and VO^{2+} .¹⁰⁸

Backward reactions:



Most of the redox pair mediators show light-shielding effects since the redox couples strongly absorb visible light and show colour, which reduces the supply of solar photons and their subsequent utilization. Redox couples are generally pH sensitive and difficult to keep in their long-term active state, which restricts the implementation of redox couples to operate PS-A/D-PS systems over a wide range of pH values. For example, simple ion redox cycles like iodate/iodine (IO_3^-/I^-) can only operate effectively under more basic conditions of $\text{pH} \geq 9$ due to the presence of active IO_3^-/I^- ion pairs instead of inactive I_3^-/I^- formation, available under lower pH conditions (eqn (1) and (2)). Similarly, $\text{Fe}^{3+}/\text{Fe}^{2+}$ redox pairs are only stable under more acidic conditions of pH less than 2.5 due to the formation of $\text{Fe}(\text{OH})_3$ precipitate through Fe^{3+} hydrolysis at high pH.¹⁰⁸



Achieving electron transport *via* an aqueous environment between photocatalyst nanoparticles and redox ion pairs presents a significant challenge, due to the absence of free electrons in water. Furthermore, the reactions of ionic redox couples are only possible under liquid phase conditions; this restricts their application to solid and gas phase photocatalysis. Such PS-A/D-PS systems also cannot be used for the degradation of pollutants in the solution because the latter probably hinders the forward redox reaction of the A/D pair, resulting in limited uses of the PS-A/D-PS systems in the field of photocatalytic water splitting.¹⁰³ In order to address the above-discussed problems, the redox couple mediator-free all-solid-state Z-scheme has been proposed.

3.1.1.2. All-solid-state Z-scheme systems. In the solid-state Z-scheme mechanism, the A/D pair of a conventional liquid-phase Z-scheme system is exchanged for a solid-state conductive material (C) as the electron transfer bridge connecting the two semiconductors (Fig. 3), which are either noble metals (Au, Ag, Cu, Bi, Pd and Pt nanoparticles) or carbon-based materials like graphene, reduced graphene oxide (rGO), exfoliated graphite, graphene oxide, carbon dots (CDs), MXene, and carbon nanotubes (CNTs), broadening its application from liquid to gas ranging from H_2O splitting to CO_2 reduction. First, Tada *et al.* introduced the idea of solid-state Z-scheme systems by applying 'Au' as a solid-state conductive material in the development of the $\text{CdS}/\text{Au}/\text{TiO}_2$ ternary system in 2006 for the photocatalytic water splitting reaction.¹⁰⁹ Basically, a minimal interfacial Ohmic contact resistance is developed between a solid-state semiconductive material and two semiconductors (PS I and PS II system) at the junction interface; this generates an outstanding interparticle electron transfer capability by reducing the electron transfer path from the CB of PS II to the VB of PS I. Although the use of a solid conductive material extends the application scope, as well as improves the stability and recovery of the photocatalyst, it still has some drawbacks. Firstly, because of their strong reducing capabilities, the photoinduced electrons from the CB of PS II tend to recombine with the photoinduced holes from PS I, which possess high oxidizing capabilities, especially across solid conductors. Secondly, electron transfer through certain metal conductors, such as Au, having a higher work function (lower Fermi level, E_f) than those of PS I and PS II, faces challenges owing to the presence of dual Schottky barriers at the interfaces where the semiconductors meet the metal. Excited electrons of PS I and PS II naturally move towards a metal conductor having a larger work function. Additionally, to ensure the conductor particles are exactly positioned between two photocatalysts, it is challenging to accurately manage the synthesis process from the perspective of material design. The bulk conductor particles are most likely haphazardly distributed on the photocatalyst surface and exhibit point-to-point interfacial contact with the semiconductor, suggesting that they may serve as cocatalysts rather than charge-transfer shuttles.^{86,110} Appropriate preparation techniques are crucial for the creation of diverse PS-C-PS systems to make sure that the PS and the electron mediator are in close interfacial contact. PS-C-PS system development is constrained since the PS and solid-state conductive material must be integrated together as a single unit, in contrast to the flexibility of the PS-A/D-PS system. By applying a controlled synthesis procedure, the ideal geometrically precise positioning of the solid conductor sandwiched between two semiconductors is quite imprecise. The usage of noble metals as electron mediators is rare, expensive, photocorrosive, and displays a shielding effect, which greatly limits their viability for real applications.⁹⁹ Challenges persist with regard to the dynamics of electron transfer within liquid Z-scheme configurations, as these mechanisms have yet to be fully resolved. To summarize, the challenge of electron transfer within liquid Z-scheme systems continues to be an open question.



3.1.2. Direct Z-scheme photocatalytic systems. A recently developed Z-scheme heterostructure is referred to as a direct Z-scheme (Fig. 9), in which there is a direct surface connection between the semiconductors and no mediator stands between them.¹¹¹ Grätzel initially illustrated the idea of a mediator-free Z-scheme in 2001 through the implementation of a WO_3/dye -sensitized TiO_2 tandem cell.¹¹² This approach was further advanced by Wang and colleagues in 2009, who developed a ZnO/CdS Z-scheme heterojunction system.¹¹³ But Liu and associates were the first researchers who used the term “direct Z-scheme” in a review article in 2010.¹¹⁴ Later, Yu *et al.* also showed strong proof of charge transfer occurring in a direct

Z-scheme configuration.¹¹⁵ In addition, inheriting all the benefits of the all-solid-state Z-scheme heterojunction, this photocatalytic system also addresses all of its drawbacks. Contrary to conventional Z-scheme systems, which utilize redox mediators (as seen in Fig. 3), the direct Z-scheme heterostructure notably inhibits backward reactions due to the lack of redox mediators, and the shielding effect provided by the charge mediators can also be substantially diminished. Furthermore, photocatalysts with a direct Z-scheme display resilience against corrosion. For example, in the case of employing an Ag-based material as the oxidizing agent within a direct Z-scheme heterostructure, the recombination of photo-



Fig. 9 Comparison of charge transfer pathways in (a–c) direct Z-scheme versus (d–f) p–n junction.



In the direct Z-scheme, the CB and VB potentials of PS I are positioned at a higher level along with a lower work function or higher Fermi level in comparison with PS II, as indicated in Fig. 9a. When PS I and PS II are in close proximity to one another under dark conditions, there will be a spontaneous flow of electrons from PS I to PS II at the interfacial surface. This process will continue until PS I and PS II have achieved equilibrium in their Fermi levels, as depicted in Fig. 9b. Consequently, PS I and PS II become oppositely charged, *i.e.*, positive and negative, due to the loss and gain of electrons, respectively, at their interface, resulting in the establishment of an internal built-in electric field that is directed from PS I to PS II. At the same time, upward and downward band bending occurs at the interface region of PS I and PS II because of the donation and accumulation of electrons, respectively, which forms a potential barrier. Under light irradiation, the photo-generated electrons in the CB of PS II and holes in the VB of PS I are more prone to recombine at the contact interface under the influence of the three factors (*i.e.*, internal built-in electric field, band edge bending, and coulombic attraction between electrons and holes) that act as the driving force for recombination (see Fig. 9c).¹¹⁶ In this instance, the Z-scheme charge transfer method is favoured. On the other hand, factors like the internal built-in electric field, inducing an extra potential barrier caused by band edge bending, and coulombic repulsion inhibit the type II like charge transfer (*i.e.*, flow of photoinduced electrons from the CB of PS I to the CB of PS II, as well as photoinduced electrons from the VB of PS II to the VB of PS I), which are not suitable for Z-scheme charge transfer pathways as illustrated in Fig. 9c. Finally, weak charge carriers are removed *via* recombination, while the powerful photo-generated electrons and holes are conserved in the CB of PS I and the VB of PS II, respectively, to participate in the specific surface redox reaction. It should be highlighted that the electric field induced in this process also plays a significant role in suppressing the recombination of photoinduced electrons present in the CB of photosystem I (PS I) and photoinduced holes in the VB of photosystem II (PS II), as outlined in Fig. 9c. Conversely, the p-n heterojunction is a subclass of the type II system illustrated in Fig. 9d, substantially differing from the direct Z-scheme system depicted in Fig. 9a. The Fermi level of

Analogous to direct Z-scheme photocatalysts, all-solid-state photocatalysts similarly demonstrate bending at the edges of the VB and CB. This behaviour is primarily observed at the interface of the metal and the semiconductor in these all-solid-state photocatalysts. In situations where the metal demonstrates a larger work function than the semiconductor ($\phi_m > \phi_s$), there is a movement of free electrons from the semiconductor towards the metal. This directional transfer results in an upward bending of the semiconductor band edge, a phenomenon induced by the generated electric field. Conversely, if the metal possesses a smaller work function than the semiconductor ($\phi_m < \phi_s$), there will be a migration of free electrons in the opposite direction, that is, from the metal to the semiconductor, causing the semiconductor band edge

to bend downward. For conventional Z-scheme photocatalysts, direct interfacial contact between two distinct photocatalysts does not exist. Consequently, there is no redistribution of free electrons between the two photocatalysts, and no internal electric field forms between them. In this context, the edges of the VB and CB of each component remain unaffected when conventional Z-scheme photocatalysts are constituted.

3.1.2.1. Theoretical requirements for the formation of a direct Z-scheme heterojunction. Direct Z-scheme heterojunction preparation has four fundamental prerequisites. First, the energy bands of two semiconductors should be aligned in a staggered pattern as that of a type II heterojunction. The second need is that a strong oxidation potential should be present in one semiconductor while a strong reduction potential is present in the other. Third, the reductive side photocatalyst should have higher CB and VB positions and a higher Fermi level (smaller work function) than the one used in the oxidative side. Fourth, photosystem II should be a semiconductor with a strong oxidation ability, while photosystem I should have a strong reduction ability to protect them from the corresponding photooxidation and photoreduction and simultaneously promote hydrogen peroxide production. Hence, a photocatalyst with weak resistance to photooxidation cannot be used as PS II. In the same way, a photocatalyst with weak resistance to photoreduction is not suitable as PS I. Therefore, for the system as a whole to attain the desired level of stability over time, PS I and PS II must have a high resistance to photoreduction and photooxidation processes, respectively.¹¹⁹ The direct Z-scheme effectively addresses the limitations found in the type-II heterojunction, conventional Z-scheme, and all-solid-state Z-scheme systems, but it does not completely answer certain scientific questions. One significant issue is the difficulty in establishing an interfacial built-in electric field (IEF) at identical Fermi levels when two semiconductors are juxtaposed. This is because the potential difference tends to disappear, subsequently impeding charge transfer at the interface.¹²⁰ In response to these unresolved questions, Fu and colleagues proposed an alternative as a potential solution: the step-scheme (S-scheme) photocatalytic system.

To address the challenges and discrepancies observed in charge transfer within type-II heterojunctions, the traditional Z-scheme, and both all-solid-state and direct Z-scheme systems, a novel S-scheme heterojunction paradigm was introduced, building upon the principles of the direct Z-scheme heterojunction. Since Fu *et al.* (Yu's group) unveiled the concept of S-scheme photocatalytic systems in 2019,¹⁰⁰ there has been growing interest in S-scheme heterojunctions. This approach offers a clear representation of electron transfer, resembling an upward movement on a staircase or appearing as an "N" shape on a microscopic scale. The development of S-scheme heterojunctions was, therefore, a natural progression in the field. The distinctive benefits of S-scheme heterojunctions, including efficient separation and transport of photo-generated carriers and a strong redox capacity, have catalyzed rapid advancements in the domain. To fully understand the

S-scheme photocatalytic heterojunctions, one must delve into their formation and progression.

4. Fundamentals of S-scheme heterojunctions

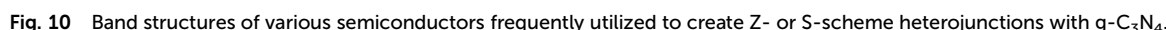
4.1. Construction of S-scheme heterostructures

At its core, an S-scheme heterostructure is established between two intimately connected semiconductors that exhibit a staggered band alignment, akin to those seen in a type II configuration (see Fig. 11a). Yet, what differentiates the S-scheme heterostructure photocatalyst is its unique charge transfer mechanism. While type II is commonly employed, it is not without its thermodynamic and kinetic limitations, leading to a diminished redox capability. Drawing inspiration from the direct Z-scheme, the S-scheme heterojunction is comprised of an oxidation semiconductor photocatalyst (OSP) and a reduction semiconductor photocatalyst (RSP). A semiconductor photocatalyst characterized by a higher conduction band minimum (CBM), a higher valence band maximum (VBM), and an elevated Fermi level is designated as the reduction semiconductor photocatalyst (RSP). Conversely, the counterpart in this relationship is identified as the oxidation semiconductor photocatalyst (OSP). Common examples of OSPs and RSPs are depicted in Fig. 10. For the S-scheme heterojunction to form, the CB, VB, and E_f of the RSP should be positioned higher and should have a lower work function compared to those of the OSP.

Here, we examine the development of the S-scheme heterojunction between two n-type semiconductors. Given that the RSP has a higher E_f than the OSP, as depicted in Fig. 11a, when the RSP and OSP come into contact under dark conditions, there will be a spontaneous migration of free electrons from the RSP to the OSP (Fig. 11b) *via* the interface to attain Fermi-level equilibrium only at the exact contact point and Fermi level bending within the interface zone developing depletion and accumulation layers of electrons at the interface in the RSP and OSP respectively, since the RSP side loses electrons and is positively charged and *vice versa* (Fig. 11c). There will be a gradual reduction and increment of the Fermi levels of the RSP and OSP, respectively, near the interface zone until Fermi level equilibrium is reached, as confirmed by the surface potential results. However, the Fermi level of the bulk remains as before.¹²¹

Upon close interaction, four areas emerge, each having its own unique electron density profile: the OSP bulk, the OSP interface, the RSP interface, and the RSP bulk (see Fig. 11d).²⁴ Given that E_f is influenced by electron density, its value should differ across these four regions. An increase in electron density at the OSP interface (or a decrease at the RSP interface) leads to a corresponding elevation (or reduction) in E_f . Furthermore, the extent of the interface region is influenced by the disparity in the Fermi levels between the OSP and RSP. At the same time, upward and downward band edge bending occurs at the interface region of the RSP and OSP because of the donation





the probability of charge recombination within either the OSP or RSP is notably reduced in such a scenario. On the other hand, an interfacial built-in electric field, band edge bending, and coulombic repulsion inhibit double charge transfer like type-II. Meanwhile, the photogenerated electrons exhibit a greater potential in the CB of one semiconductor (RSP), whereas the photogenerated holes possess a higher potential in the VB of another semiconductor (OSP). Concurrently, electrons in the CB of the RSP and holes in the VB of the OSP migrate toward the surface of the photocatalyst due to the influence of the IEF, where catalytic reactions take place. This strategy leverages the interfacial electric field as a driving

Under ideal conditions, when semiconductors with distinct Fermi levels are in contact with each other, electron movement aligns these levels, as shown in Fig. 9a and b. According to this theoretical assumption, the interfacial electric field in the heterojunction should weaken and eventually vanish under dark conditions, leading to a deviation from S-scheme transfer post-light illumination due to the loss of its driving force.^{99,122} Contrary to this theoretical expectation, the sustained migration of photoinduced charge carriers *via* the S-scheme in such heterojunctions has been confirmed through numerous sophisticated characterization techniques, presenting a stark contradiction to the initial assumption. This discrepancy stems from the actual equilibrium condition of the Fermi level at the heterojunction, which significantly differs from the idealized predictions.¹²³ In a perfect scenario, Fermi levels within a heterojunction would align without considering the impact of surface states. Yet, interfacial defects and the resulting high contact resistance in real-world heterojunctions lead to Fermi level pinning, as strongly supported by surface potential tests.¹²⁴ Even when equilibrium is achieved, a persistent potential difference between the interface of two semiconductors is observed.¹²⁵ Furthermore, the variance in electron density at the interface of the heterojunction causes the bending of Fermi levels, as illustrated in Fig. 11c.⁹⁹ This occurs as electrons move from the E_f of the reduction photo-

catalyst to that of the oxidation photocatalyst, reducing electron density at the interface compared to the internal area and thus bending the Fermi levels. Such dynamics establish a dynamic equilibrium within the components of the heterojunction, ensuring a continuous driving force for the perseverance of S-scheme charge transfer.

The driving force behind carrier separation within the interface of the heterojunction is a pivotal factor, traditionally considered solely due to the interfacial built-in electric field. Yet, recent research suggests that the diffusion effect contributes to charge separation, where the variance in electron concentration across the S-scheme heterojunction enables diffusion-controlled carrier separation to surpass that of the interfacial electric field of the heterojunction.¹²⁶ Moreover, two critical aspects, namely, effective interfacial contact area and interfacial contact resistance, must be considered for optimizing charge separation. The effective interfacial contact area is crucial as it defines the extent of the driving force, with a larger area enhancing the carrier separation efficiency.¹²⁷ On the other hand, the interfacial contact resistance significantly affects the rate at which charge carriers migrate; excessively high resistance can impede carrier movement. Therefore, improving lattice matching is essential for constructing S-scheme heterojunctions that facilitate efficient carrier migration.¹²⁸

4.3. Design principles of S-scheme heterojunctions and theoretical requirements for implementing S-scheme charge transfer mechanisms

In general, to assemble an S-scheme heterostructure, two individual n-type semiconductors are chosen, which serve as the oxidation semiconductor photocatalyst (OSP) and the reduction semiconductor photocatalyst (RSP).¹²⁹ However, as research and development progress, several questions arise: (i) Can p-type based semiconductors also be used in the creation of S-scheme photocatalysts? In this context, to answer the above question, several reports proposed that S-scheme photocatalysts could definitely be established by using p-type semiconductors.^{99,130} Which means both the RSP and OSP can be n-type or p-type semiconductors and *vice versa*. For constructing an S-scheme heterojunction, the major crucial point is that the RSP semiconductor has a higher CB and Fermi level than those of the OSP. Mainly, four feasible scenarios, (1) n-n heterojunction, (2) p-n heterojunction, (3) n-p heterojunction, and (4) p-p heterojunction, are valid options to meet the aforementioned condition. It is noteworthy that experimental verification has been obtained for all four forms of heterojunctions.^{131,132} Type-II and S-scheme charge transfers in semiconductor heterojunctions are often confused with each other because their formation mechanisms and the interleaving of semiconductor energy bands, along with electron transfer dynamics in the dark state, are very similar. In the n-type semiconductor heterojunction, when the CB of PS1 is more negative and its Fermi level is higher than those of PS2, electron transfer follows an S-scheme, not type-II, as electrons move from the higher E_f of PS1 to the lower E_f of PS2 due to

the unbalanced state of E_f under dark conditions, creating an interfacial electric field (IEF) directed from PS1 to PS2. This setup makes type-II charge transfer impossible: the interfacial energy band of PS1 with a higher E_f bends upward, hindering electron movement towards the interface and favouring hole migration, while the interfacial band of PS2 with a lower E_f bends downward, facilitating the opposite. Consequently, this mismatch in band bending and electric field direction exclusively supports S-scheme electron transfer, as shown in Fig. 12a and b. This principle similarly applies to two p-type semiconductors that are in contact, where a higher Fermi level and more negative CB position of PS1 compared to PS2 also lead to S-scheme transfer, as illustrated in Fig. 12c and d.¹²³ Additionally, when an n-type and a p-type semiconductor come into contact, the relationship between their Fermi levels and CB positions determines the charge transfer type: a higher Fermi level and more negative CB in the n-type results in S-scheme transfer (Fig. 12e and f), whereas a more negative CB and lower Fermi level in the p-type align with type-II transfer conditions, as the interfacial electric field direction aligns with the band bending state (Fig. 12g and h).

In summary, the electron transfer type between semiconductors that are in contact in a heterojunction hinges on the relative positions of their CB and Fermi levels. For two semiconductors that are in contact, S-scheme transfer occurs when the more negative CB of the semiconductor accompanies

a higher Fermi level, whereas type-II transfer takes place when the more negative CB of the semiconductor accompanies a lower Fermi level. It is important to highlight that the charge transfer direction is determined by the positions of the energy bands of the constituent semiconductor within the heterojunction, and this is not influenced by the type of semiconductor involved.

4.4. Tactics for Fermi level adjustment to facilitate type-II to S-scheme transfer conversion

Adjusting the Fermi levels between semiconductors can significantly influence the electron transfer mechanisms, facilitating a shift from type-II to S-scheme transfer. The direction of band bending at the interface is critical for determining the nature of electron transfer, whether it be type-II or S-scheme. By modifying the relative positions of E_f , one can change the band bending direction, thereby switching the electron transfer mechanism and enhancing carrier separation efficiency.^{133–135} This strategy of Fermi level adjustment is a key method for controlling carrier dynamics within heterojunctions. For example, Huang and colleagues successfully altered electron transfer in a $C_3N_4/W_{18}O_{49}$ system by adjusting the relative positions of E_f .¹³⁶ Meanwhile, PS1 and PS2 are in contact, and an electric field is generated from PS2 to PS1 at their interface due to the lower Fermi level of PS1 than that of PS2. This field directs electrons to consumption at PS2 while accumulating at

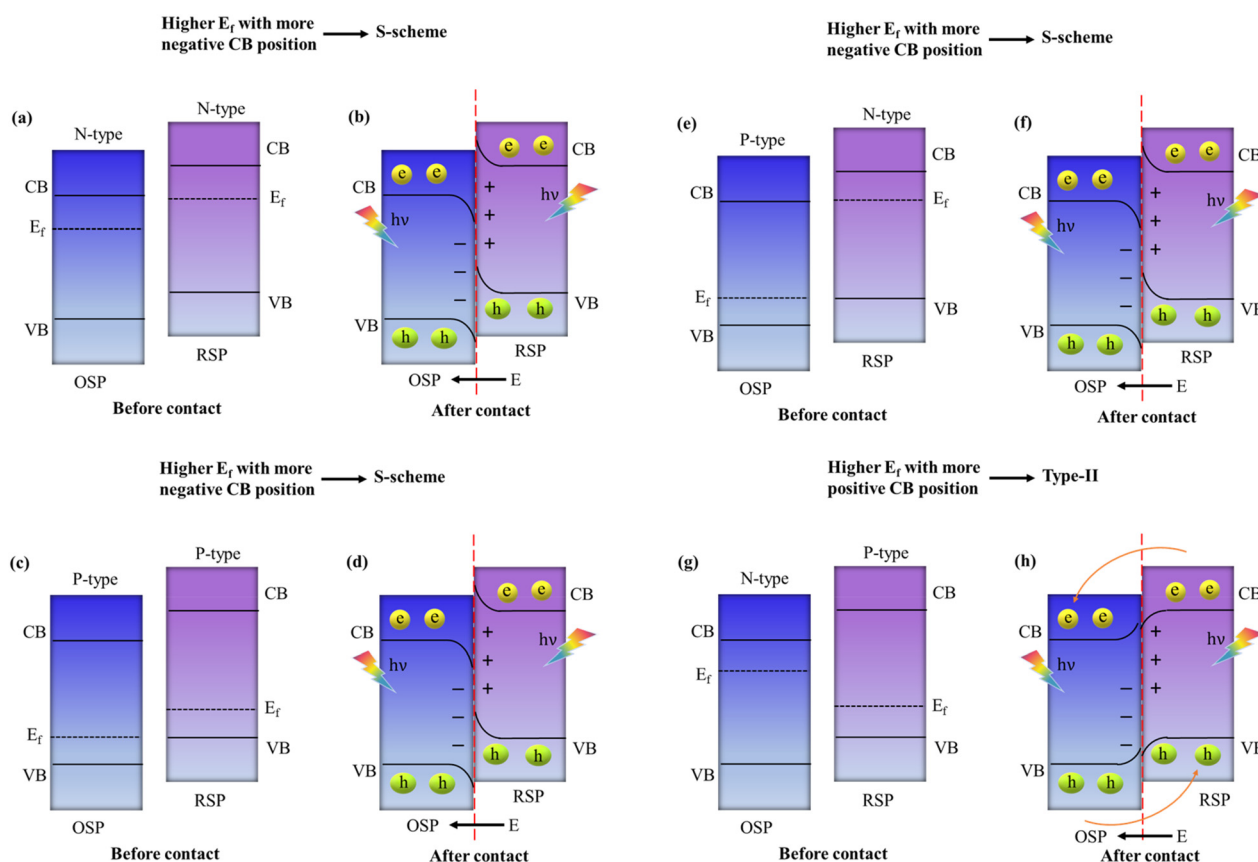


Fig. 12 Criteria for initiating (a–f) S-scheme and (g and h) type-II charge transfer mechanisms.



PS1, causing the interfacial energy band to bend downwards and upwards for PS1 and PS2, leading to a type-II electron transfer mechanism. Interestingly, the study found that adsorbing triethanolamine on PS1 raised its Fermi level above that of PS2. This adjustment reversed the band bending directions, upward for PS1 and downward for PS2, facilitating an S-scheme charge transfer. This discovery highlights a method for controlling the pathways of carrier transfer.¹²³ In addition to molecular adsorption, non-metallic doping is another effective method for altering Fermi levels. For instance, Kim and co-workers enhanced the Fermi level in C_3N_4 by doping with boron. They observed that when boron-doped C_3N_4 was combined with ZnO, resulted in a reversed interfacial band bending state, providing a shift in the charge transfer mechanism.¹³⁴ Moreover, the creation of interfacial chemical bonds can also adjust the Fermi levels and change the band bending directions, offering another avenue for control.¹³⁵ While it is theoretically feasible to transition the electron transfer dynamics from type-II to S-scheme through Fermi level adjustments, in practice, the Fermi level in semiconductor heterojunctions may remain fixed due to significant contact resistance. Consequently, a comprehensive set of characterization tools is recommended to verify the potential for actual Fermi level modification.

4.5. Enhancing the driving force behind S-scheme transfer: approaches and strategies

The interfacial electric field is key to driving S-scheme charge transfer effectively, with its strength being crucial for charge carrier separation efficiency.^{137–139} To boost this strength, various strategies have been devised, including the development of dual S-scheme heterojunctions.¹⁴⁰ Moreover, these heterojunctions are also involved in three distinct photocatalyst systems to address the challenges such as less interfacial contact and the weak driving force seen in single component S-scheme heterojunctions. Under dark conditions, when oxidation-type (OSP) and reduction-type (RSP) photocatalysts are juxtaposed, energy band bending and the creation of an internal electric field occur at the interface, resulting in the accumulation of electron and hole pairs in the OSP and RSP, respectively. Upon illumination, the electric field drives the electrons from the CB of the OSP to recombine with holes present in the VB of the RSP, facilitating the accumulation of high redox potential electron and hole pairs in the CB of the RSP and the VB of the OSP, respectively. This dual arrangement creates two interfacial electric fields, providing excellent spatial charge carrier separation and transfer compared to that in single S-scheme based heterojunctions, thereby significantly boosting the photocatalytic efficiency.¹⁴¹ Moreover, precisely increasing the Fermi level gradient and widening the Fermi level gap serve as another potent method to amplify both the strength of the interfacial electric field as a driving force, and expanding the space-charge region, thereby strongly promoting more directed carrier transport.¹²⁵ Additionally, creating interfacial chemical bonds further strengthens the built-in electric field and speeds up charge carrier transport, demon-

strating a multifaceted approach to improving the efficacy of S-scheme electron transfer mechanisms.^{142–144} Moreover, it should be noted that, beyond semiconductor materials, organic compounds with comparable lowest unoccupied molecular orbital (LUMO) and highest occupied molecular orbital (HOMO) energy levels can also be integrated into S-scheme heterojunctions.¹⁴⁵

In summary, the initial concept of S-scheme heterojunctions has evolved from n-n type to encompass various possibilities. This expansion opens up new avenues for the design and manipulation of diverse S-scheme heterojunctions in future research and applications for effective charge carrier separation and enhanced photocatalytic activities. For clarity, Table 1 summarizes the specific differences between direct Z-scheme and S-scheme heterostructures. Table 2 details a comparison of different types of heterojunctions, focusing on their band positions and mechanisms for charge transfer and separation. Additionally, we discuss several characterisation methods to verify direct Z- or S-scheme charge dynamics and provide multiple instances of g- C_3N_4 -based direct Z- or S-scheme heterojunction systems for photocatalytic H_2O_2 evolution.

5. Characterization techniques for direct Z- or S-scheme heterojunction photocatalysts

To date, three characterization techniques (*i.e.*, *ex-situ/in situ* light illuminated XPS, surface potential measurement by *in situ*-KPFM and fs-TAS) have been developed to directly confirm the formation of direct Z and S-scheme heterojunctions.

5.1. *In situ/ex situ* illuminated X-ray photoelectron spectroscopy (ISIXPS)

To confirm the pathway of photogenerated electron-hole transfer in S-scheme heterojunctions, the *in situ* light illuminated XPS (ISIXPS) technique was first suggested by Yu and colleagues and is recognized as a particularly effective and influential method. XPS, or X-ray photoelectron spectroscopy, is a sophisticated method for surface examination that offers insights into the elemental composition, content percentages, electronic states, and bonding patterns of different materials.¹⁴⁶ This technique is useful for detecting alterations to the elemental binding energy when the chemical surroundings, *i.e.* electron density of an element, are changed. For instance, when there is a reduction in the electron density of a particular element, it results in a positive shift in binding energy, whereas a rise in electron density causes a negative shift.

In S-scheme photocatalytic systems upon light irradiation, both the OSP and RSP of the heterojunction experience a reduction or increment in electron density because of the distinctive exciton migration dynamics of the S-scheme, which is caused by the movement of photoexcited electrons from the CB of the OSP into the VB of the RSP, influenced by an interfacial electric field (IEF). Consequently, this process leads to a lowered



Table 1 Difference between direct Z-scheme and S-scheme heterostructures

Entry	Direct Z-scheme	S-Scheme
1	When semiconductors with distinct Fermi levels are in contact with each other, the electron movement aligns these levels. According to this theoretical assumption, the interfacial electric field in the heterojunction should diminish over time and eventually vanish under dark conditions, meaning that carrier migration post-light irradiation would not follow the direct Z-scheme due to the loss of its driving force, which is clearly at odds with experimental observations from surface potential tests	Interfacial defects and the resulting high contact resistance in actual synthesized heterojunctions lead to Fermi level pinning, as strongly supported by surface potential tests. Even when equilibrium is achieved, a persistent potential difference between the interface of two semiconductors is observed. Furthermore, the variance in electron density at the interface of the heterojunction causes interfacial Fermi level bending. This occurs as electrons move from the E_F of the reduction photocatalyst to that of the oxidation photocatalyst, reducing electron density at the interface compared to the internal area and thus bending the Fermi levels at the interface. Such dynamics establish a dynamic equilibrium within the components of a heterojunction, ensuring the continuous driving force for the perseverance of S-scheme charge transfer. The Fermi level of the bulk remains unchanged, allowing photoinduced charge carriers to retain their original high redox potential in the respective semiconductor components
2	It is silent about the nature of the charge transfer direction	The charge carrier transfer direction is determined by the positions of the energy bands of the constituent semiconductors within the heterojunction, and is not influenced by the type of semiconductor involved
3	It does not address the intensity of interfacial band edge bending, which creates an additional potential barrier to inhibit type-II like charge transfer	The intensity of interfacial band edge bending is directly related to the Fermi level gap between two semiconductors. The literature reports that type-II charge transfers often occur when semiconductors with small Fermi level differences form an S-scheme heterojunction. In such cases, the reduction photocatalyst is preferentially excited, causing both type-II and S-scheme transfers to coexist. Conversely, a large Fermi level difference dominates the S-scheme migration path
4	It does not address the factors influencing the extent of the interfacial space-charge region and the strength of the interfacial electric field	The strategy of precisely increasing the Fermi level gradient and widening the Fermi level gap between OSP and RSP amplifies both the strength of the interfacial electric field as a driving force and expands the interfacial space-charge region, thereby strongly promoting more directed carrier transport
5	The direct Z-scheme does not address the switching of carrier transfer	By modifying the relative positions of the Fermi levels, one can change the interfacial band bending direction, thereby switching the electron transfer mechanism, which is a key method for controlling carrier dynamics within the heterojunctions

binding energy in the RSP and an increased binding energy in the OSP under illumination conditions. XPS characterization thus facilitates monitoring of the directional charge migration related to specific elements, providing a detailed analysis of the associated OSP and RSP semiconductor structures.¹⁰⁷

During XPS analysis, a solid specimen, connected electrically to apparatus, will be placed in an ultrahigh vacuum environment, typically maintained below 10^{-9} Pa. Upon exposure of the sample surface to high-energy X-ray beams, such as 1486.6 eV for Al K α X-rays, the electrons gain enough energy to be ejected from the surface into the vacuum, leading to atom ionization. This phenomenon is also known as the photoelectric effect (as illustrated in Fig. 13a).

These ejected electrons, or photoelectrons, possessing varying kinetic energies (E_k), traverse through the XPS device's analysis slit. The ensuing electron current, indicative of the rate of photoelectron emission and contingent on E_k , is then documented (Fig. 13b).¹⁴⁷ On a microscopic scale, atomic orbital energies are quantized, meaning every electron possesses a distinct energy level. Based on their proximity to the nucleus, ranging from near to far, the atomic orbitals can be categorized into distinct types like 1s, 2s, 2p, and 3s. The energy needed to knock out an electron from the material is

termed its ionization or binding energy (E_b). Notably, electrons residing in inner orbitals (e.g., 1s) exhibit a higher E_b than those in outer orbitals (e.g., 2p). The inner-shell electrons can be excited by X-rays due to their extraordinarily powerful energy (for example, the energy ($h\nu$) of Al K α X-rays is 1486.6 eV). With enough energy, the photoexcited electrons can overcome the barriers of the sample's work function (W_s) and binding energy (E_b), allowing them to eventually be ejected from the surface of the sample with E_k . As a result, E_b can be determined using the following eqn (3):¹⁴⁸

$$E_b = h\nu - E_k - W_s \quad (3)$$

In XPS experiments, E_b of the inner-shell electrons is determined by measuring the kinetic energy (E_k) of emitted photoelectrons. By analyzing this E_b value, one can discern the elements present in the sample, as each element typically possesses a distinct E_b value. A shift or change in E_b of electrons in the inner shell, also called the chemical shift, occurs when an electron loses or gains an electron in the outer orbitals of the atom. For instance, a carbon atom contains two electrons in each of its 1s, 2s, and 2p orbitals, as depicted in Fig. 13c. The nucleus of carbon contains six protons and six neutrons,





Table 2 Comparison of various types of heterojunctions based on the band positions and charge transfer/separation mechanism

Entry	Type	Charge transfer mode and rate	Scope of implementation	Benefits	Main challenges
1	Type-II	Nil and moderate	—	Improve charge separation efficiency	• Rapid recombination • Sluggish charge migration • Reduced redox potential • Charge-separation efficiency at the cost of reduced redox ability • Strong pH dependency (harsh operational conditions);
2	Traditional liquid phase Z-scheme	Redox ion pairs and slow	Liquid phase	Excellent light transmittance	(I) The IO_3^-/I^- system operates effectively only at pH levels above 9 due to the formation of inactive I_3^- at lower pH values (II) $\text{Fe}^{3+}/\text{Fe}^{2+}$ remains stable only under acidic conditions with a pH below 2.5, as $\text{Fe}(\text{OH})_3$ precipitates at higher pH values • The shielding effect is due to light absorption by the redox mediator. For example, aqueous Fe^{3+} absorbs light strongly up to 464 nm • Reverse reaction arises from the back donation of charge carriers • Both PS I and II are needed, each with appropriate oxidation and reduction capabilities, to initiate redox reactions involving various A/D pairs • Limited to the liquid phase due to the ionic characteristics of redox pairs, hindering scalability potential • Expensive manufacturing and light-blocking properties • While there is flexibility in designing the PS-A/D-PS system, creating the PS-C-PS system is more restrictive because both the PS and electron mediator must be integrated into a single unit • Expensive electron mediators, such as metals and nanocarbons, are necessary to regulate directional electron transfer • Appropriate preparation methods are vital for diverse PS-C-PS system development: (i) To guarantee close interfacial contact between the PS and electron mediator (ii) To achieve a balance between the level of reduction in the nanocarbon mediator and the overall hydrophilicity of the composites • There is considerable uncertainty regarding the mechanism of electron transfer • Prevent the recombination of electron-hole pairs • Quantum efficacy • PS-PS systems exhibit less efficient directional electron transfer compared to PS-C-PS systems due to the lack of an electron mediator • The creation of an interfacial electric field heavily relies on the characteristics of PS I and PS II, where PS I possesses a higher Fermi level than PS II • Different direct Z-scheme verification tests are necessary to differentiate from heterojunction type photocatalytic systems • Mainly confined to powdered photocatalysts, not applicable to photochemistry and solar cells with an external circuit; insufficient management of reaction thermodynamics and dynamics in S-scheme photocatalysts
3	All-solid-state Z-scheme	Conductor and moderate	Liquid and gas phases	Enhance conductivity, improve electron transfer, and establish excellent interfacial connections	
4	Direct Z-scheme	Built-in interfacial electric field and fast	Liquid and gas phases	Strong redox power	
5	S-Scheme	Built-in interfacial electric field and fast	—	Adjustable built-in interfacial electric field intensity, stable interfacial carrier transportation, strong redox capability	

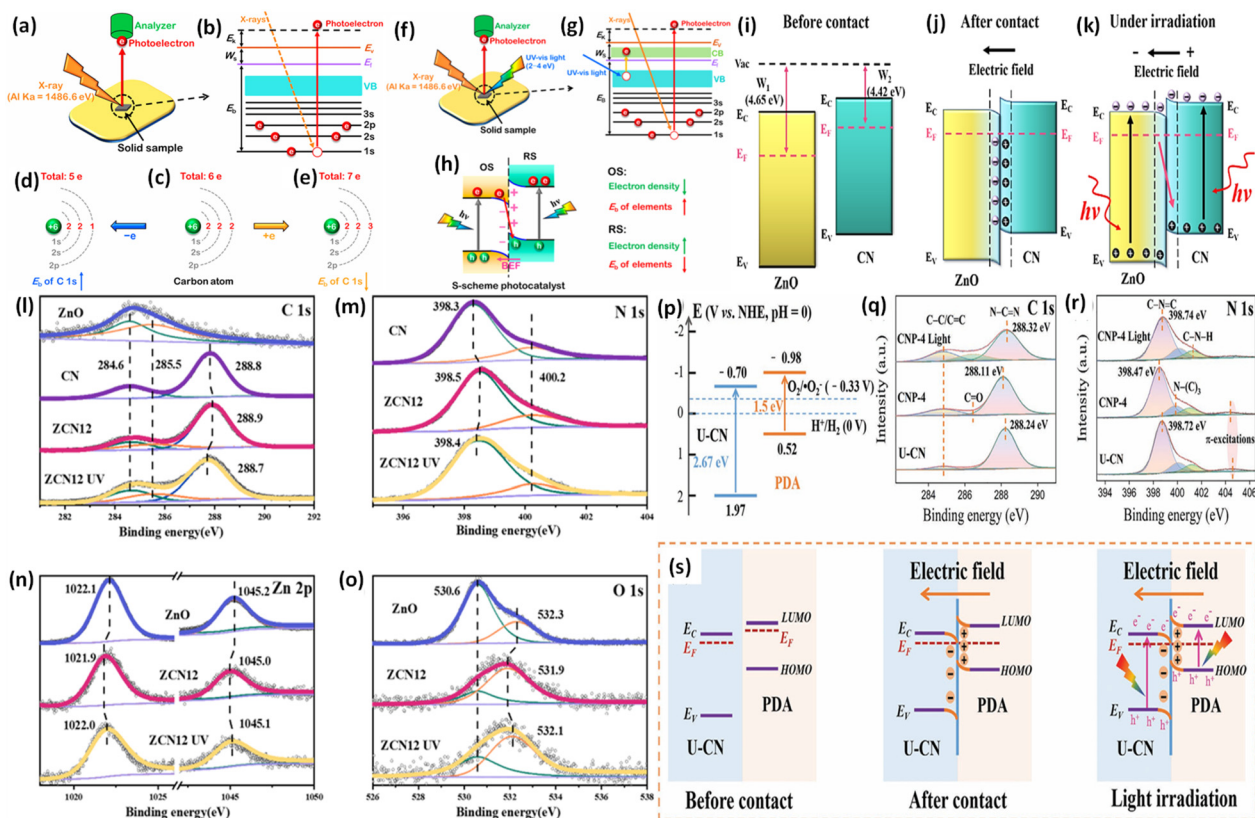


Fig. 13 (a) Illustration of the XPS measurement principle. (b) Photoelectron production during XPS studies under X-ray irradiation. (c–e) Impact on the binding energy (E_b) of C 1s following electron loss or gain. (f) Detailed schematic of the working principle of ISIXPS analysis under dual irradiation with UV-visible light and X-rays. (g) Electron excitation processes during ISIXPS measurements under simultaneous UV-visible light and X-ray irradiation. (h) Variations in electron density and elemental binding energy (E_b) of an S-scheme heterojunction photocatalyst under photoexcitation. The figures are adapted with permission from ref. 149. Copyright 2022, ACS. (i–k) Light-induced S-scheme charge transfer process between ZnO and CN. Spectra of (l) C 1s, (m) N 1s, (n) Zn 2p, and (o) O 1s in ZnO, CN, and ZCN12 measured using high-resolution ISI-XPS in the dark and under UV light illumination. The figures are adapted with permission from ref. 151. Copyright 2021, ACS. (p) Arrangement of band structures of U-CN and PDA. *In situ* XPS measurements of (q) C 1s and (r) N 1s for U-CN and CNP-4. (s) The S-scheme charge transfer process occurring within the CNP-4 heterojunction. The figures are adapted with permission from ref. 152. Copyright 2023, Wiley-VCH.

hence possessing six positive charges. Two fundamental forces bind the nuclei and electrons of atoms together: the coulombic force, which is caused by protons, and the nuclear force, which is influenced by protons as well as neutrons. As the carbon nucleus has a fixed number of protons and neutrons, the overall attractive force remains consistent. When a carbon atom loses a valence electron from the 2p orbital, its electron count is reduced to five (as shown in Fig. 13d). This loss enhances the force exerted on each remaining electron, resulting in an increase in E_b of the C 1s electron. On the other hand, if a carbon atom gains an electron in the 2p orbital, its electron count rises to seven, reducing the force per electron and thereby decreasing E_b of C 1s (illustrated in Fig. 13e). Electron acceptance or loss can be challenging in some situations. For instance, in covalent compounds, atomic orbitals hybridize to form new molecular orbitals, altering the electron distribution and density. Hence, E_b of C 1s will likewise change depending on the chemical environment in which the carbon atom is found. When the electron density around a carbon atom is reduced, E_b of C 1s is increased and *vice versa*.

While these shifts in E_b might be subtle compared to direct electron acceptance or loss, they remain detectable through XPS techniques.¹⁴⁹ ISIXPS emerges as a vital tool to confirm the electron transfer routes in S-scheme semiconductor materials. In this technique, a combination of high-energy X-rays and ultraviolet-visible (UV-vis) light is employed to irradiate the sample's surface, as depicted in Fig. 13f. The resulting excited photoelectrons with kinetic energy (E_k) then leave the sample surface, enter the vacuum, and are captured by the analyzer. To delve deeper into the role of UV-vis light during ISIXPS experiments, electron excitation processes are detailed in Fig. 13g. The inner-shell electrons can be excited by X-rays with very high energy (Al K α = 1486.6 eV), allowing them to overcome the barriers of binding energy (E_b) and work function (W_s) to emerge as free photoelectrons carrying E_k ultimately. In contrast, the energy of UV-vis light (between 2 and 4 eV) is significantly lower compared to X-rays. As a result, it can only excite the valence electrons to move from the VB to the CB, while ensuring these excited electrons remain bound to the atom's nucleus, as shown in Fig. 13g. Therefore, following



excitation of the outer-shell valence electrons, the analyzer in ISIXPS measurements detects E_b of electrons in the inner shell. As valence electrons move from the VB to the semiconductor's CB, photogenerated electrons are formed through the excitation process. These energized electrons can transfer between two semiconductors while residing in them. Like conventional XPS analysis, the loss of photogenerated electrons causes a reduction in electron density and an increase in elemental binding energy (E_b), while the acceptance of photogenerated electrons results in increased electron density and a decrease in E_b . As per the previous discussion, the proof of electron movement in S-scheme heterojunctions under dark conditions and during light exposure can be obtained by combining normal XPS and ISIXPS data analysis. The variation in E_b of an individual element can be utilized to approximate the alteration in electron density. This enables the determination of electron movement directions in S-scheme heterojunctions.¹⁵⁰ Conventional XPS reveals the electron flow dynamics between the RSP and OSP upon intimate interaction. Given that the RSP possesses a higher Fermi level (E_f) than the OSP, electrons migrate from the RSP to OSP after coming into contact. Analyzing the RSP post-contact reveals a decline in its electron density compared to its pre-contact state, which marks an upsurge in E_b of its constituent elements. In contrast, the post-contact OSP showcases an enhanced electron density in the S-scheme photocatalytic system compared to its initial state, implying a consequent decrease in its E_b . Additionally, the migration pathway of photoexcited electrons in the S-scheme heterojunction can be verified using ISIXPS. When subjected to light, photoinduced electrons in the CB of the OSP are driven to move to the VB of the RSP by the interfacial built-in electric field (IEF), resulting in a decrease in the electron density of the OSP and an increase in the RSP as visualized in Fig. 13h. As a result, under light irradiation, the elemental E_b of the OSP increases, and that of the RSP decreases in the S-scheme photocatalyst.¹⁴⁹

On the basis of XPS and ISIXPS mechanistic analyses, we present two case studies that utilize ISIXPS to unveil the charge transfer dynamics within S-scheme heterojunctions. For example, Liu's group prepared an S-scheme heterojunction between MOF-derived ZnO and g-C₃N₄ (CN) through a two-step calcination process.¹⁵¹ The CB and Fermi level (E_f) of CN are positioned higher than those in ZnO, making them suitable for the development of an S-scheme heterojunction. To validate charge carrier transfer in the ZnO/CN (ZCN-12) S-scheme heterojunction photocatalyst, both conventional XPS and ISIXPS tests are carried out. When ZnO and CN come into close contact, there will be spontaneous diffusion of electrons from CN to ZnO *via* their interfaces because E_f of CN is higher than that of ZnO to attain Fermi level equilibrium at the exact contact point, developing depletion and accumulation regions of electrons at the interface of CN and ZnO, respectively, since CN loses electrons and becomes positively charged and *vice versa*. At the same time, upward and downward band bending occurs at the interface region of CN and ZnO because of the donation and accumulation of elec-

trons, respectively. Simultaneously, an interfacial electric field is formed, which is directed from CN to ZnO. Therefore, relative to CN, the C 1s and N 1s peak positions in the ZCN12 composite move to a higher E_b , implying a reduction in electron density within the CN component of ZCN12 (as seen in Fig. 13l and m). On the other hand, when set against ZnO, the Zn 2p and O 1s peak positions in the ZCN12 composite tend to a lower E_b (illustrated in Fig. 13n and o). This suggests increased electron density in ZnO, implying that ZnO receives electrons from CN. These shifts in electron density between CN and ZnO confirm electron migration from CN to ZnO after contact in the absence of light (Fig. 13i and j). During ISIXPS experiments, the sample surface is exposed to UV light with a wavelength of 365 nm. In the ZCN12 compound, there is a noticeable shift to a lower binding energy (E_b) for the C 1s and N 1s peaks (as seen in Fig. 13l and m), whereas the Zn 2p and O 1s peaks shift to a higher E_b (as illustrated in Fig. 13n and o). This suggests an increase in electron density in the CN regions and a decrease in the ZnO part. Such observations reinforce the idea of photogenerated electron migration from ZnO to CN when subjected to UV light, a process visually mapped out in Fig. 13k. Through the findings from both regular XPS and ISIXPS, the electron movement patterns in the ZnO/g-C₃N₄ S-scheme heterojunction are clearly demonstrated. Similarly, Zhang *et al.* successfully developed a 2D/2D close contact S-scheme heterojunction system, C₃N₄/PDA (CNP), through the *in situ* self-polymerization method, showing an excellent H₂O₂ production efficiency.¹⁵² The band diagrams for U-CN and PDA are illustrated in Fig. 13p. When compared to individual U-CN, the observed C 1s and N 1s peaks in CNP-4 move to a lower E_b after contact in the absence of light (as depicted in Fig. 13q and r). No significant variations are evident post-PDA deposition, implying that the primary peaks in CNP-4 are derived from U-CN. These findings indicate an increased electron density in U-CN and a reduced one in PDA within CNP-4. This validates electron movement from PDA to U-CN when they come into contact without light exposure (see Fig. 13s). When exposed to light, the C 1s and N 1s peaks of CNP-4 exhibit a shift toward an elevated E_b , as seen in Fig. 13q and r. This shift suggests a reduction in electron density within U-CN and a corresponding increase in PDA, signifying the migration of photogenerated electrons from U-CN towards PDA, a process supported by the IEF as demonstrated in Fig. 13s. Through the combined insights from XPS and ISIXPS studies, the pathway of electron transfer in the C₃N₄/PDA (CNP) S-scheme heterojunction is elucidated both in the absence of light and upon photoactivation. To sum up, XPS and ISIXPS stand out as highly sensitive tools capable of identifying minor shifts in elemental E_b resulting from variations in electron density, in both the absence and presence of light. These shifts in elemental E_b effectively represent the interactions and electron movements between two components. Additionally, XPS and ISIXPS serve as widely applicable techniques for tracking electron transfer within heterojunction photocatalysts.



5.2. Surface potential

Atomic force microscopy (AFM) emerged in 1985, pioneered by scientists at IBM.¹⁵³ This cutting-edge technique is renowned for delivering detailed images and insights into surface characteristics and material properties on the nanoscale. Essentially, AFM operates by using a probe to “sense” or “interact” with a material’s surface, enabling evaluations of its morphology, roughness, and composition. An advanced extension of AFM is Kelvin probe force microscopy (KPFM). This technique broadens the horizons of AFM by measuring the surface potential or work function of catalysts.¹⁵⁴ The above can be achieved when employing a conductive tip in AFM followed by applying a minor amount of alternating current voltage (V_{AC}) inside the tip as well as the material under observation (Fig. 14a). This process helps in measuring the contact potential difference. Furthermore, a bias voltage (V_{DC}) enables the measurement of the electrostatic force through V_{CPC} with the conductive tip. KPFM provides insights into the complex electrical characteristics and charge orientation of the material’s surface.

Merging the functionalities of AFM and KPFM in a singular device provides dual advantages: it captures both the physical

topography and the electrical attributes at the nanoscale. Such a combination becomes pivotal when delving into surface electronic characteristics, including aspects like charge deviation distribution, surface potential fluctuation, and work function difference. This integrated AFM-KPFM approach enables a richer exploration of how surface structures are interlinked with their local electronic attributes, as shown in Fig. 14b. The localized surface potential, represented as $\varphi = \varphi(x, y)$, is intimately connected with the electronic distribution over the material. One is able to derive this potential through counterbalancing the electrostatic force across the tip as well as the specimen. By adjusting the bias voltage, one can identify the surface potential at particular points (local surface potential) over the specimen.¹⁵⁵ Fig. 14b illustrates a typical depiction of beam deflection AFM and demonstrates the ability of AFM-KPFM to offset electrostatic forces by applying a bias voltage to the specimen. Utilizing *in situ* atomic force microscopy in combination with Kelvin probe force microscopy (AFM-KPFM) in potential mode offers a way to assess the charge dynamics, specifically examining the movement of photoexcited electrons from the oxidation semiconductor to the reduction semiconductor of a heterojunction

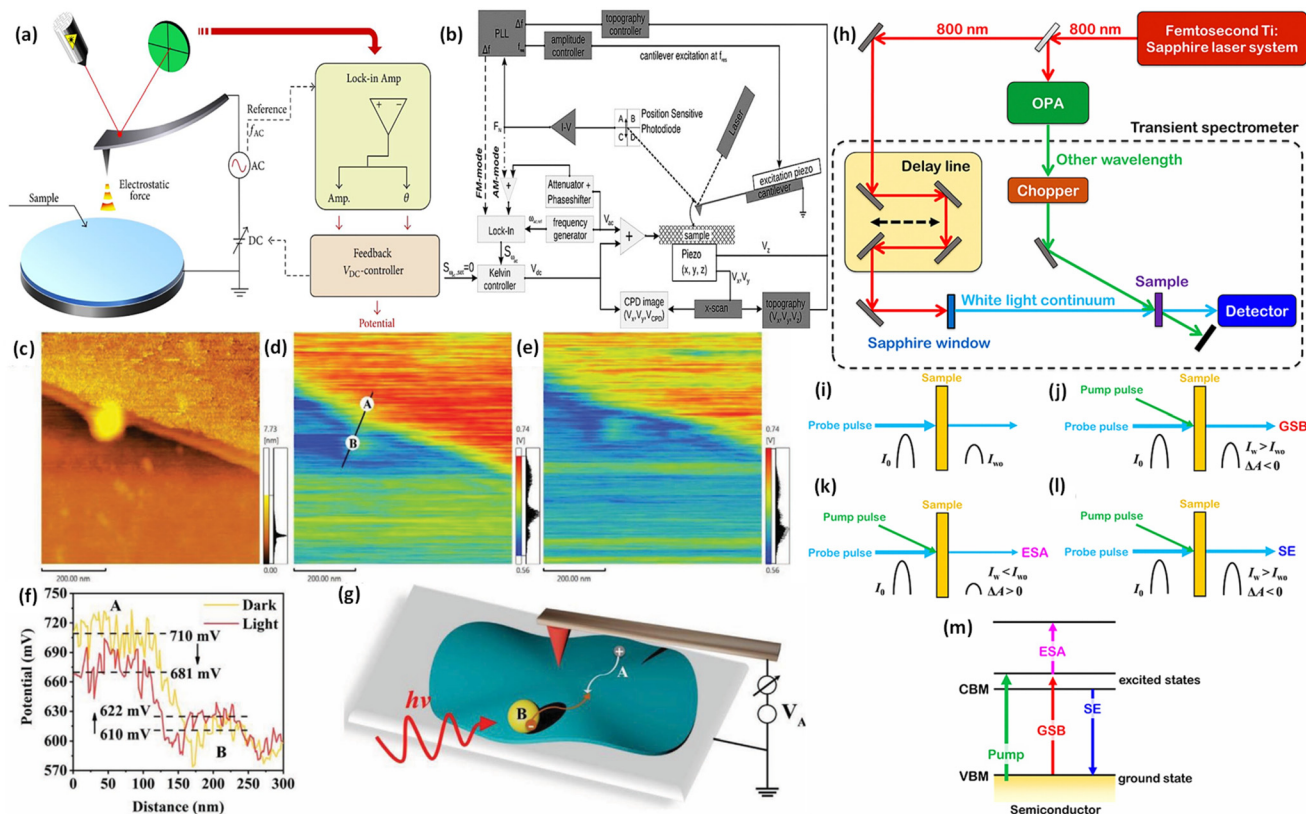


Fig. 14 (a) *In situ* AFM-KPFM principles and operation. (b) A typical beam deflection setup for AFM. The figures are adapted with permission from ref. 156. Copyright 2024, Elsevier. (c) AFM picture from the CP photocatalytic system. Surface potential variation in CP in the dark (d) and under light illumination (e). (f) The surface potential measured through line scanning. (g) Schematic representation of *in situ* light irradiated KPFM. The figures are adapted with permission from ref. 157. Copyright 2021, Wiley-VCH. (h) Schematic illustration of the operation of the fs-TAS instrument. The intensity of the probe pulse subsequent to traversing the specimen (i) in the absence of the pump pulse and (j–l) with it. Three distinct signals, GSB, ESA, and SE, can be discerned through the utilisation of pump pulse excitation. (m) Correlations between relaxation and electron transition pathways in the semiconductor. The figures are adapted with permission from ref. 161. Copyright 2023, RSC.

Transient absorption spectroscopy (TAS) is a valuable tool for investigating ultrafast electron dynamics within photoexcited semiconductors, offering temporal resolution ranging from femtoseconds to picoseconds. The femtosecond transient absorption spectroscopy (fs-TAS) method is frequently employed as a “pump–probe” technique, offering a potent means to investigate the electronic state configuration and charge dynamics in semiconductor materials. More specifically, it offers a dynamic representation of carrier occupation across semiconductor energy levels over time.¹⁵⁸ Furthermore, fs-TAS unravels the intricate relaxation pathways through which photoexcited electron transfer occurs from the high energy CB to the low energy VB of a photocatalyst.¹⁵⁹ By analyzing fs-TAS data, the charge dynamics of heterojunction photocatalysts can be revealed, allowing us to determine the cause of enhanced catalytic efficiency.¹⁶⁰ In practical fs-TAS experiments, a monochromatic laser known as a “pump pulse” of high energy is used to excite a semiconductor photocatalyst. Subsequently, a white pulse called a “probe pulse” of low energy is employed to estimate the number of photoinduced charge carriers in excited CB and ground state VB energy levels. The time delay between the laser and the white pulse is adjusted using an optical delay line. By using an optical delay

line, the time delay between the laser and the white pulse can be monitored. The relaxation process is explained by analyzing the fluctuation between the number of photoexcited charge carriers and the delay time.¹⁶¹ The fs-TAS setup consists of three key elements: a Ti-sapphire laser system that produces an 800 nm femtosecond beam, an optical parametric amplifier (OPA), and a transient spectrometer (Fig. 14h). A beam splitter divides this beam into two distinct beams with different intensities. Following this, the beam with higher intensity is modulated by a chopper and utilized to generate a shorter wavelength pulse through the OPA. This pump pulse is then used to excite electrons of the semiconductor photocatalyst from the VB to the CB. On the other hand, the beam with lower intensity passes through an optical delay line and interacts with sapphire, producing a continuous white pulse. This white pulse serves as a probe pulse, which is directed at the sample. A critical step is the precise alignment of the pump and probe pulses at the same point on the sample. As the probe pulse passes through the sample and reaches the detector, the pump pulse is blocked by a stopper after it has passed through the sample.

The optical delay line enables the adjustment of the path difference between the probe and pump pulses, creating a controlled delay time between them. This delay enables the two pulses to arrive at the sample at different moments. By assessing the absorption of the probe pulse in both the presence and absence of pump pulse illumination, while varying the delay time between them, differential optical absorption spectra of the sample can be obtained. Changes in the signal intensity of the probe pulse as it passes through the sample indicate variations in the number of excited carriers.¹⁶² Therefore, examining these signals offers information about the relaxation dynamics of excitons as they move from a higher energy state to a lower one. The fs-TAS spectrum is a particular form of differential optical absorption spectrum obtained from transmittance measurements. Generally, the detector evaluates the transmittance (T) of the sample, and the absorbance (A) of the sample can be calculated as follows:¹⁶³

$$A = -\log T = \log(I_0/I)$$

In this context, I_0 and I denote the intensity of the probe pulse before and after it travels through the sample, respectively. Additionally, the change in absorption of the probe pulse (ΔA) for the sample is defined as follows:

$$\Delta A = A_w - A_{w0} = \log(I_0/I_w) - \log(I_0/I_{w0}) = \log(I_{w0}/I_w)$$

In this case, A_w and A_{wo} represent the absorption of the probe pulse by the sample with and without excitation by the pump pulse, respectively. I_w and I_{wo} denote the intensities of the probe pulse after traversing the sample with and without excitation by the pump pulse, respectively. It is crucial to note that ΔA changes with both the wavelength of the probe pulse and the time delay between the pump and probe pulses. As the delay time is adjusted by the optical delay line, ΔA is recorded at various wavelengths.¹⁶⁴

Consequently, a three-dimensional image function, $\Delta A(\lambda, t)$, depicting the relationship between wavelength and delay time is obtained. This three-dimensional image enables an examination of how ΔA varies with wavelength at a constant delay time and how it changes with delay time at a specific wavelength, reflecting the variation in the number of excited state charge carriers over delay time at that wavelength. Following this, we explore the relationship between ΔA and the carrier kinetics of the sample. In the absence of a pump pulse, when only the probe pulse illuminates the semiconductor photocatalyst, the semiconductor absorbs part of the probe pulse. The intensity of absorption depends on the number of ground state electrons in the VB and the semiconductor's absorption coefficient, as shown in Fig. 14i. When the pump pulse is introduced to the semiconductor sample, ground state electrons in the VB are excited and transition to the CB of the semiconductor. This leads to a decrease in the number of electrons in the VB and an increase in the CB. When the semiconductor sample is then illuminated by the probe pulse, the absorption of the probe pulse is reduced ($I_w > I_{w0}$) due to the decreased number of ground state electrons in the VB, resulting in a negative ΔA signal, commonly known as ground state bleaching (GSB), as depicted in Fig. 14j. Additionally, some of the electrons in the excited state absorb the probe pulse that was not absorbed by the ground state electrons, moving to higher energy excited states. As a result, the absorption of the probe pulse by the sample increases ($I_w < I_{w0}$), leading to a positive ΔA signal, referred to as excited state absorption (ESA) or photoinduced absorption (PIA), as illustrated in Fig. 14k. Moreover, the semiconductor sample in the excited state is inherently unstable and returns to the ground state, through either stimulated or spontaneous radiation. During this transition, the semiconductor sample emits fluorescence, leading to an increased intensity of light detected by the detector ($I_w > I_{w0}$). This process results in a negative ΔA signal known as stimulated emission (SE), as shown in Fig. 14l.¹⁶⁵

Three distinct ΔA signals can be identified in fs-TAS measurements, each associated with specific electron transition and relaxation processes within semiconductors, as outlined in Fig. 14m. Based on the previously discussed ΔA signals, two main types of fs-TAS spectra can be identified. In a photoactivated semiconductor, when an excited electron moves from the energy levels of the CB to those of the VB, it loses energy through interactions with surrounding particles. This lost energy is predominantly released as heat, resulting in a difference between the energy of the excitation light and the emitted light, commonly known as fluorescence. As a result, the luminescence spectrum, also referred to as the fluorescence spectrum, shifts to lower energy levels, a phenomenon known as the Stokes shift.

The extent of the Stokes shift varies due to different physicochemical properties and energy level structures among various semiconductors.¹⁶⁶ In the fs-TAS spectrum, the ground state bleaching (GSB) signal aligns with the steady-state absorption spectrum, while the stimulated emission (SE) signal matches the fluorescence spectrum. When the Stokes

shift is minor, the wavelengths of the GSB and SE peaks overlap to some extent, resulting in the final fs-TAS spectrum being a composite of the GSB, SE, and excited state absorption (ESA) peaks, as shown in Fig. 15a. On the other hand, when there is a significant Stokes shift, the wavelength of the GSB peak does not overlap with that of the SE peak, leading to the differentiation of three distinct peaks in the fs-TAS spectrum, as illustrated in Fig. 15b. Heterojunction photocatalysts exhibit markedly higher photocatalytic efficiency compared to single photocatalysts, largely due to the spatial separation of charge carriers. To understand the mechanism behind this enhanced performance in heterojunctions, it is crucial to study the dynamics of photoinduced carriers within these photocatalysts, with a particular focus on the ultrafast interfacial electron transfer process. The application of fs-TAS measurements enables the observation of charge transfer processes at picosecond (ps) and femtosecond (fs) timescales, making it an effective tool for investigating heterojunction photocatalysts. Significant studies have been carried out to explore the kinetics of interfacial electron transfer in S-scheme photocatalysts using fs-TAS.

In this regard, Wang and co-workers studied the dynamics of photoexcited charge carriers in photocatalysts with a TiO_2 /polydopamine (TiO_2 /PDA) S-scheme heterojunction employing fs-TAS.¹⁶⁷ In their research, the fs-TAS spectra for both pure TiO_2 and the most efficient TiO_2 /PDA sample (referred to as TP0.5) showed ground-state bleach (GSB) peaks around 375 nm, as depicted in Fig. 15c. The analysis of the GSB recovery kinetics (Fig. 15d) indicated a quick decay of the GSB signal within just 30 ps. This rapid decay (τ_1) on the femtosecond timescale was attributed to electron trapping in the TiO_2 material, while slower decay (τ_2) was associated with electron transfer kinetics. Notably, TP0.5 had a larger proportion of τ_2 compared to pure TiO_2 , indicating a novel charge transfer mechanism in TP0.5. This mechanism was attributed to interfacial charge transport within the TiO_2 /PDA S-scheme heterojunction, with charge transfer from the CB of TiO_2 to the VB of PDA occurring within approximately 5 ps. Moreover, the average lifetime (τ_{ave}) value of TP0.5 in the time-resolved photoluminescence (TRPL) spectra indicated the band-to-band recombination of electrons and holes within TiO_2 and was estimated to be around 10 ns (Fig. 15e). In conclusion, the interfacial charge transfer process took place much faster than charge recombination, thus aiding in the effective separation of excitons within the TiO_2 /PDA S-scheme heterojunction photocatalysts, as illustrated in Fig. 15f. This study provides insights into the mechanism behind the enhanced performance of S-scheme heterojunction photocatalysts by elucidating the kinetics of interfacial electron transfer. Similarly, He and colleagues carried out an extensive investigation using fs-TAS to thoroughly explore electron transfer processes within the $\text{TiO}_2/\text{Bi}_2\text{O}_3$ S-scheme heterojunction.¹⁶⁸ Their study included fs-TAS measurements on two samples: pure TiO_2 (denoted as TO) and $\text{TiO}_2/\text{Bi}_2\text{O}_3$ with optimized photocatalytic performance (referred to as TBO40). In the fs-TAS spectra of both TO and TBO40, as depicted in Fig. 15g and h, notable features



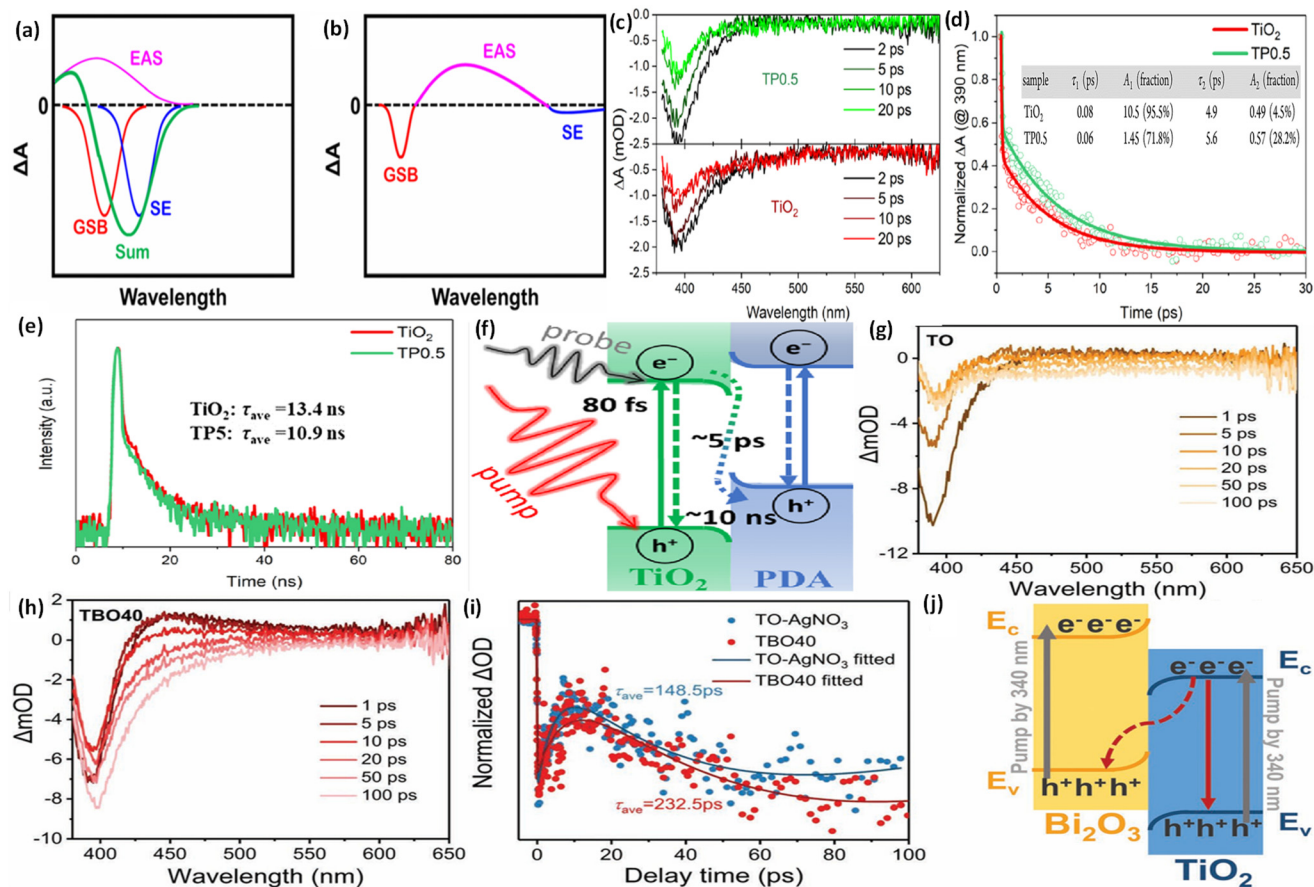


Fig. 15 Representative fs-TAS spectra for (a) a minor Stokes shift and (b) a major Stokes shift. The figures are adapted with permission from ref. 161. Copyright 2023, RSC. (c) fs-TAS. (d) GSB signal decay profiles for fs-TAS in TiO₂ and TP0.5. (e) TRPL spectra for TiO₂ and TP0.5. (f) Diagram showing the kinetics of electron transfer in TP0.5. The figures are adapted with permission from ref. 150. Copyright 2022, ACS. TAS of TO (g) and TBO40 (h) photocatalyst obtained using 340 nm excitation. (i) Fitted transient absorption decay curves for TO-AgNO₃ and TBO40 at 395 nm, captured within the 100 ps. (j) Diagrammatic representation of S-scheme charge transfer in the TBO40 photocatalyst. The figures are adapted with permission from ref. 168. Copyright 2022, Wiley-VCH.

were seen, including a GSB peak at approximately 395 nm and a broad ESA peak extending from 425 to 550 nm. To determine whether these spectral signals were attributed to electrons or holes, control experiments were performed using either an electron scavenger (such as AgNO₃ and benzoquinone) or a hole scavenger (like lactic acid and ethanol). Specifically, the fs-TAS spectra of TO were examined in the presence of an electron scavenger (AgNO₃) or a hole scavenger (furfuryl alcohol). The addition of these electron or hole scavengers resulted in noticeable changes to both GSB and ESA signals, indicating that the dynamics of photoexcited charge carriers played a role in both of these signals. By analyzing the fitting results of GSB recovery kinetics within the first 100 ps, as shown in Fig. 15i, it was found that the average lifetimes (τ_{ave}) of holes increased from 148.5 ps for TO-AgNO₃ to 232.5 ps for TBO40. This enhancement in hole lifetimes suggested the superior electron-accepting ability of Bi₂O₃ within the heterojunction. As a result, this indicated an efficient interfacial charge transfer process from the CB of TiO₂ to the VB of Bi₂O₃, as depicted in Fig. 15j.

Similarly, Cheng and colleagues used fs-TAS in their research to explore the dynamics of photogenerated carriers in a CdS/PDB S-scheme heterojunction.¹⁶⁹ Initially, two-dimensional mapping TA spectra were obtained to detect TA signals across femtosecond to nanosecond timescales, as shown in Fig. 16(a-d). Notably, an additional peak at 710 nm was observed in the CdS/PDB composite compared to pure CdS. This specific wavelength corresponded to an energy level of 1.75 eV, aligning with the energy difference between the CBM of CdS and the HOMO of PDB, as depicted in Fig. 16e. Subsequently, decay kinetic curve fitting was conducted to determine fluorescence lifetimes, as illustrated in Fig. 16f and g. The lifetimes τ_2 and τ_3 of CdS/PDB were significantly shorter than those of pure CdS. Additionally, a new lifetime, labeled as τ_4 , was introduced into the fitting process to achieve an accurate fit. These results provided strong evidence for the transfer of photoexcited electrons from the CB of CdS to the HOMO of PDB, as illustrated in Fig. 16h. The studies mentioned above have mainly offered indirect insights into interfacial electron transfer within S-scheme heterojunction photocatalysts,





Fig. 16 2D mapping of TA spectra for (a) pristine CdS and (b) CPDB5 photocatalyst. TAS signals of (c) CdS and (d) CPDB photocatalyst over fs–ns timescales. (e) Depiction of the energy gap between the CBM of CdS and the HOMO level of PDB. Normalized decay kinetics of (f) CdS and (g) CPDB5 measured at a wavelength of 510 nm. (h) Decay routes for photoinduced electrons within CdS and CPDB photocatalysts. The figures are adapted with permission from ref. 169. Copyright 2023, Wiley-VCH.

inferred from the analysis of electron transfer kinetics obtained by fitting the recovery kinetics of GSB. However, it should be noted that the recombination of electrons in the CB of the OSP and holes in the VB of the RSP can lead to fluorescence emission as well as a negative ΔA signal in fs-TAS spectra, a signal that is often overlooked. Future research could, therefore, focus on detecting and analyzing this negative ΔA signal, which arises from the interfacial charge transfer processes within S-scheme heterojunction photocatalysts. Such studies could provide a more detailed understanding of these intricate electron transfer dynamics.

The results from fs-TAS indicate that the improved photocatalytic performance of heterojunction photocatalysts is due

to rapid interfacial charge transfer and the effective use of photogenerated carriers in redox reactions at the right time.

5.4. DFT calculations

Density functional theory (DFT) serves as an indispensable computational tool for investigating the electronic structure and charge dynamics in many-electron systems, including Z/S-scheme heterojunctions commonly found in photocatalytic reactions. By modeling electron interactions at atomic and molecular levels, DFT provides insights into electronic properties. It generates essential information, including band structure, lattice parameters, and energies related to binding and adsorption, which are crucial for addressing challenges

like photocatalyst stability, substrate adsorption strength, etc.¹⁷⁰ In addition to offering theoretical guidance for regulating carrier behavior, DFT calculations have been particularly useful in indirectly confirming the charge flow dynamics in S-scheme photocatalytic systems, as evidenced in recent publications. However, it is important to note that DFT is a theoretical method and may not account for all complexities encountered under actual testing conditions.¹⁷¹ By delving into the electronic arrangement of the materials using DFT calculations, one is able to obtain a clearer understanding of charge transfer dynamics, enabling more effective regulation of electronic structures and more accurate prediction of material properties. One is able to gain a clearer understanding of the kinetics of charge transfer. The interfacial carrier mobility pathway as well as the interfacial electric field (IEF) direction in Z- or S-scheme photocatalysts can be confirmed through DFT simulations along with metrics like the variation in average planar electron density, denoted as $\Delta\rho(z)$, and the mapping of differential charge density. Simulating the interfacial electric field serves as a valuable approach for investigating the carrier transfer mechanism. The interfacial directional flow of electrons and holes within a heterojunction can be hypothesized through examining the interfacial electric field within the components of a heterojunction.¹⁷²

Generally, DFT is utilized to ascertain the work function (ϕ) of each component within a photocatalytic system. The Fermi energy level for each semiconductor can subsequently be verified using the formula $\phi = E_{\text{vac}} - E_{\text{f}}$, where ϕ signifies the work function and E_{vac} stands for the vacuum energy. Through the optimization of average potential distributions for each component, the work function (ϕ) is determined. Electron migration from one component of the photocatalytic system to another can be determined by computing the work functions of the two semiconductors. A three-dimensional differential charge density map shows the build-up of charge at the interface, with yellow and green denoting electron accumulation and depletion, respectively. The fluctuation in average electron density along the Z-axis serves as a guide for discerning the routes of electron transfer among the components of the photocatalytic system.^{171,172}

In this regard, Sun *et al.* confirmed the routes of charge transfer in the Sv-ZIS@3DA-CN S-scheme heterojunction through DFT analyses.¹⁷³ Clear differences in charge density at the interface are evident from DFT simulations, with the 3DA-CN side mainly appearing green and the Sv-ZIS side predominantly yellow, symbolizing an electron depletion zone and an accumulation zone, respectively (Fig. 17b and d). The distribution of electronic charge surrounding S atoms in Sv-ZIS is notably more localized than that surrounding C atoms in 3DA-CN, indicating an intense bond between S and C atoms. In the average planar electron density difference curve, the 3DA-CN side exhibits positive charge, indicative of negative electron density, while the Sv-ZIS side displays negative charge, indicative of positive electron density (Fig. 17c). Consequently, both the differential charge density map and the average planar electron density curve demonstrate that electrons are

transferred from 3DA-CN to Sv-ZIS (Fig. 17b–d). Fig. 17e illustrates the density of states (DOS) surrounding the Fermi levels of 3DA-CN, Sv-ZIS, and Sv-ZIS/CN composite. Notably, there is significant electron density near the Fermi level of Sv-ZIS/CN, indicating electron redistribution between 3DA-CN and Sv-ZIS, suggestive of a strong interaction between them. As a result, an interfacial built-in electric field (IEF) is formed and directed from 3DA-CN towards Sv-ZIS in the 3DA-CN@Sv-ZIS S-scheme photocatalytic system. The optimized geometric simulated structure yielded work function (Φ) values of 4.83 eV and 4.67 eV for Sv-ZIS and 3DA-CN, respectively, as depicted in Fig. 17a, f and g. Notably, the Sv-ZIS system has a higher work function and lower Fermi level compared to 3DA-CN. Consequently, upon interfacial close contact, spontaneous electronic migration occurs from the 3DA-CN component towards the Sv-ZIS component. This movement continued as long as the Fermi level became sufficiently flat to impact on band bending.

One useful tool for studying the carrier transfer mechanism is internal electric field simulation. This approach was used to examine the interfacial electric field as well as the interfacial charge transfer direction across TiO_2 and $\text{g-C}_3\text{N}_4$.¹¹⁸ The values of work function for TiO_2 along with $\text{g-C}_3\text{N}_4$ photocatalysts are 6.43 eV and 5.32 eV, respectively, implying electron migration from $\text{g-C}_3\text{N}_4$ to TiO_2 . A 3D visualization of the interfacial charge density difference (as shown in Fig. 17h) displays where charges accumulate (yellow) and are depleted (cyan). Additionally, a variation in average charge density along the Z-axis was observed (Fig. 17i), further confirming electron migration from $\text{g-C}_3\text{N}_4$ towards TiO_2 leading to the creation of holes on the $\text{g-C}_3\text{N}_4$ side.

In their research, Zhu and co-workers analyzed the charge transfer dynamics in different materials by computing their work functions.¹⁷⁴ The study indicated that the work functions for $\text{g-C}_3\text{N}_4$, SnS_2 , and $\text{O-C}_3\text{N}_4$ were 4.3, 6.0, and 3.6 eV, respectively, as depicted in Fig. 18a. This indicates that the Fermi level positions of $\text{g-C}_3\text{N}_4$ and $\text{O-C}_3\text{N}_4$ are more negative than that of SnS_2 . Fig. 18b visually represents the charge density difference, where accumulation and depletion regions of charge are highlighted in yellow and cyan colour. Within the $\text{g-C}_3\text{N}_4/\text{SnS}_2$ photocatalyst, the charge is primarily localized on $\text{g-C}_3\text{N}_4$ (blue) and on SnS_2 (yellow), implying charge transfer from $\text{g-C}_3\text{N}_4$ towards SnS_2 . A similar electron transfer is observed in the $\text{O-C}_3\text{N}_4/\text{SnS}_2$ system. Furthermore, the strengths of the interfacial electric field (IEF) within $\text{g-C}_3\text{N}_4/\text{SnS}_2$ as well as $\text{O-C}_3\text{N}_4/\text{SnS}_2$ S-scheme heterojunctions were found to be $1.32 \times 10^9 \text{ V m}^{-1}$ and $5.31 \times 10^9 \text{ V m}^{-1}$, respectively, as shown in Fig. 18c and d. These values suggest a stronger IEF along with efficient electron flow in the oxygen-doped system, aligning with the experimental observations that demonstrate superior photocatalytic activity in $\text{O-C}_3\text{N}_4/\text{SnS}_2$ compared to the $\text{g-C}_3\text{N}_4/\text{SnS}_2$ system. In conclusion, this study offered not only a theoretical understanding of the S-scheme mechanism within the $\text{g-C}_3\text{N}_4/\text{SnS}_2$ heterojunction but also introduced a new method for altering the strength of the IEF in S-scheme photocatalysts by incorporating nonmetal atoms.



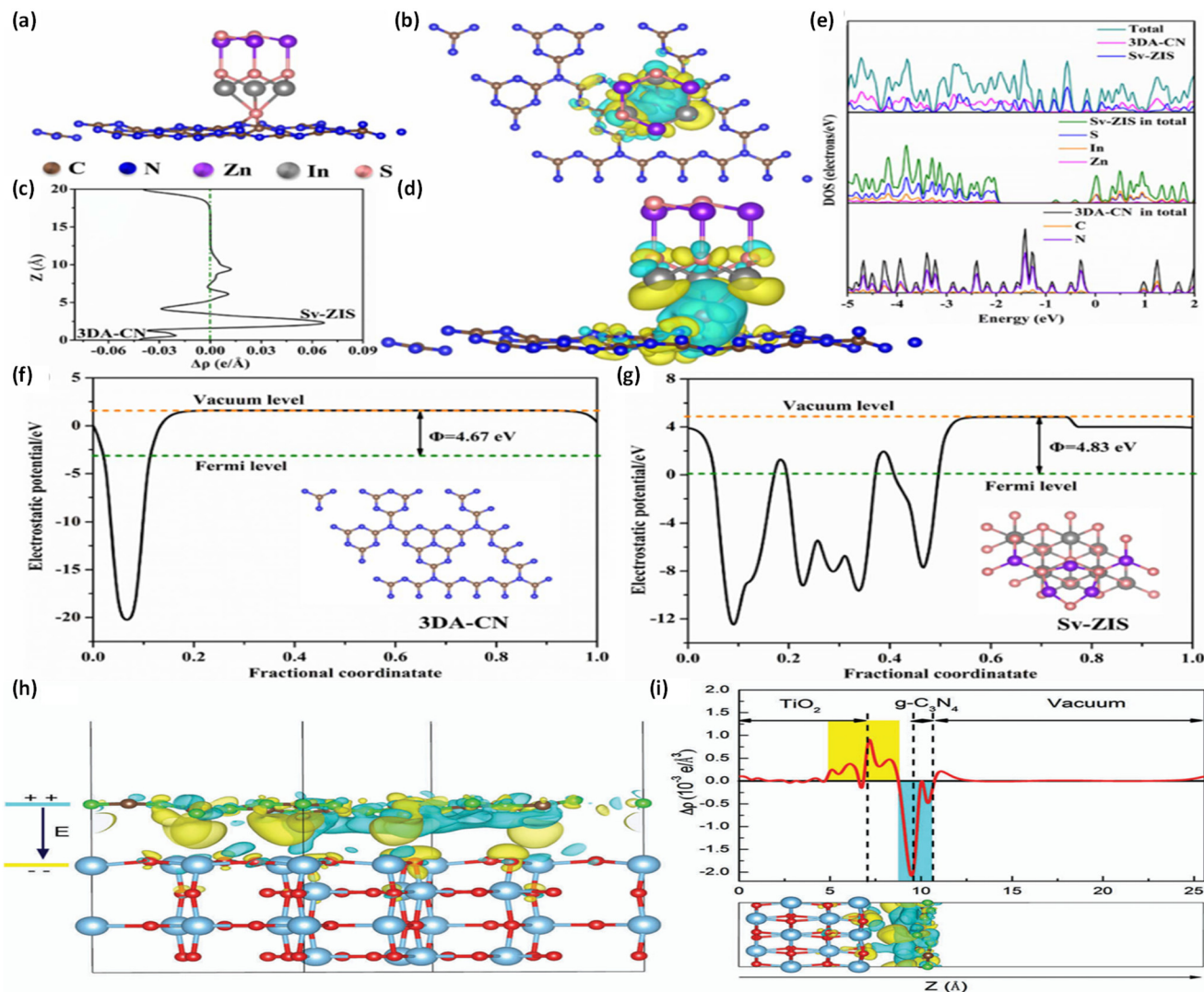


Fig. 17 (a) Lateral perspective of the Sv-ZIS/CN heterojunction following geometrical optimization. (b) Top view of the charge density difference. (c) Planar-averaged difference in electron density. (d) Side view of the charge density difference. (e) DOS for the Sv-ZIS/CN composite. Work functions for (f) 3DA-CN and (g) Sv-ZIS photocatalysts. The figures are adapted with permission from ref. 173. Copyright 2022, RSC. (h) Variation in charge density ($0.0004 \text{ e } \text{\AA}^{-3}$) across the $\text{g-C}_3\text{N}_4/\text{TiO}_2$ interface. (i) Planar-averaged difference in electron density ($\Delta\rho(z)$) for the $\text{g-C}_3\text{N}_4/\text{TiO}_2$ interface, with yellow regions showing electron accumulation, while cyan areas denote electron depletion. The figures are adapted with permission from ref. 118. Copyright 2016, RSC.

Hence, DFT analyses serve as a foundational tool for determining both IEF orientation and the charge carrier transfer pathway.

5.5. Reactive free radical trapping testing by EPR

It is well known that the photocatalytic process can produce a variety of reactive free radicals. Among these, holes must have a strong oxidative power in order to produce hydroxyl radicals, while electrons with strong reductive capabilities are the source of superoxide radicals. Within an S-scheme photocatalyst, the excitons with a weaker redox potential tend to recombine, leaving behind potent charge carriers of robust redox potential. Hence, evaluating the formation of hydroxyl ($\cdot\text{OH}$) and superoxide ($\cdot\text{O}_2^-$) radicals through EPR during the

photocatalytic reaction is an effective strategy to authenticate the more relevant S-scheme charge migration pathway.⁷⁸ In this regard, Fu and colleagues presented the EPR profiles for $\text{DMPO}\cdot\text{OH}$ and $\text{DMPO}\cdot\text{O}_2^-$ for WO_3 , $\text{g-C}_3\text{N}_4$, and 15% $\text{WO}_3/\text{g-C}_3\text{N}_4$ photocatalysts.¹⁰⁰ In Fig. 19b, $\text{g-C}_3\text{N}_4$ showcased an absence of $\text{DMPO}\cdot\text{OH}$ signals, because its photoinduced holes had a weak capacity for oxidation (2.14 V, in relation to NHE at pH = 0), as shown in Fig. 19a. However, both WO_3 and 15% $\text{WO}_3/\text{g-C}_3\text{N}_4$ composite showed a pronounced $\text{DMPO}\cdot\text{OH}$ response, proving that photogenerated holes of WO_3 did not migrate towards the VB of $\text{g-C}_3\text{N}_4$, but instead resided over the VB of WO_3 . Conversely, in Fig. 19c, pronounced $\text{DMPO}\cdot\text{O}_2^-$ responses were evident in $\text{g-C}_3\text{N}_4$ along with the 15% $\text{WO}_3/\text{g-C}_3\text{N}_4$ heterojunction, indicating that their photoexcited elec-





Fig. 18 (a) Work function values for g-C₃N₄, SnS₂, and O-C₃N₄ photocatalysts. (b) Charge density variations within the composite photocatalysts. Illustration of the S-scheme charge transfer routes for (c) g-C₃N₄/SnS₂ and (d) O-C₃N₄/SnS₂ heterojunctions. The figures are adapted with permission from ref. 174. Copyright 2021, Elsevier.

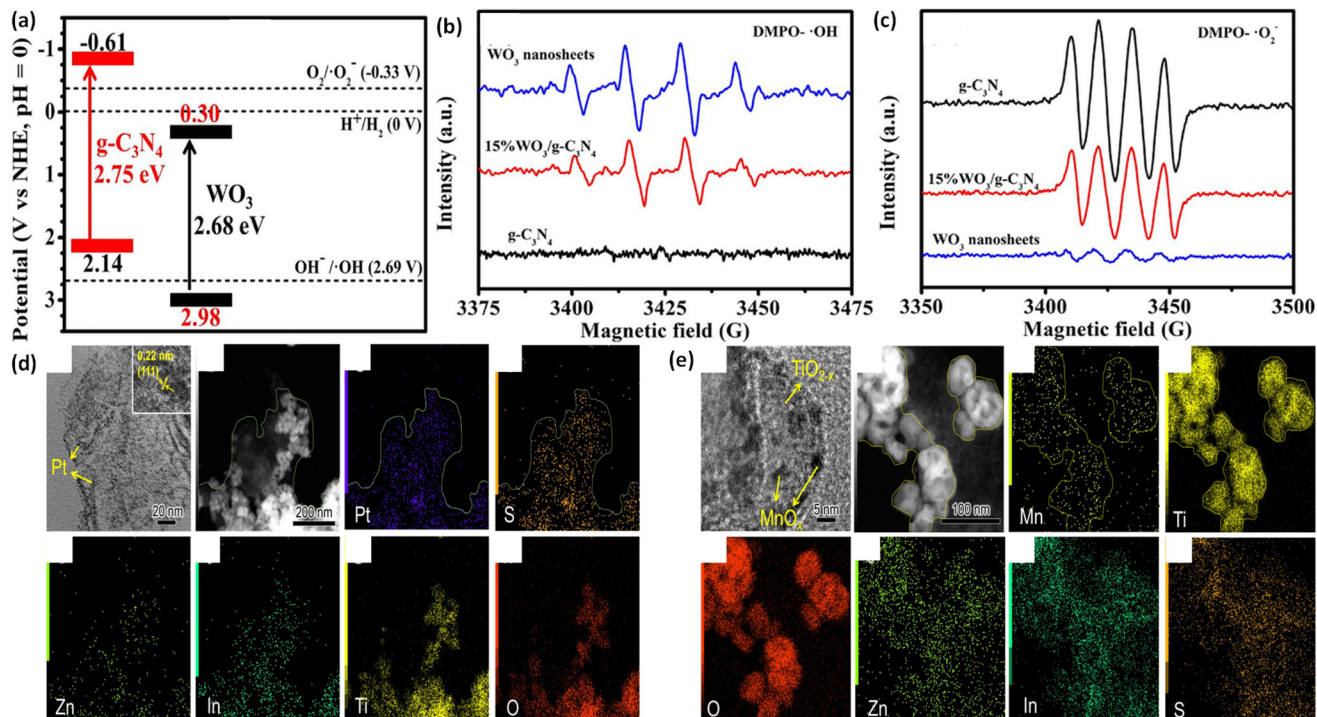


Fig. 19 (a) Band arrangements of g-C₃N₄ and WO₃ nanosheets. EPR spectra showing (b) DMPO-·OH in an aqueous solution and (c) DMPO-·O₂⁻ in a methanol dispersion, with g-C₃N₄, WO₃ nanosheets, and 15%WO₃/g-C₃N₄ photocatalysts. The figures are adapted with permission from ref. 100. Copyright 2019, Elsevier. (d) TEM, STEM, and EDX spectroscopy element mapping images of the Pt photodeposited O-ZIS/TiO_{2-x} heterojunction. (e) TEM, STEM, and EDX element mapping images of the MnO_x photodeposited O-ZIS/TiO_{2-x} photocatalyst. The figures are adapted with permission from ref. 175. Copyright 2022, Elsevier.

within the spectrometer and the surface of the specimen facilitates determination of the work function (Φ) of the respective material, a critical parameter representing the minimum energy needed to remove electrons from the E_f of the material, thus reflecting the challenge in electron mobility out of the material as follows:¹⁷⁷

$$\Phi = h\nu - \text{SECO}$$

Acquiring a UPS spectrum was straightforward, but deriving meaningful data could be challenging due to specimen preparation and surface charge accumulation concerns.¹⁵⁶ Whitten and co-workers proposed a specific protocol for UPS analysis to address these challenges.¹⁷⁶ To explore the charge transfer pathway in the Y-CeO₂@ZnIn₂S₄ heterojunction, UPS analysis was utilized. This technique, specifically applied to Y-CeO₂ and ZnIn₂S₄, facilitated the calculation of work functions (Φ) by subtracting the incident UV light energy (21.22 eV) from the energy of secondary electron cutoff (E_{SECO}), as demonstrated in Fig. 20d and e.¹⁷⁸ The results indicated a greater work function value for Y-CeO₂ (5.58 eV) than ZnIn₂S₄ (4.46 eV), suggesting a lower Fermi level (E_F) for the former. This inconsistency in E_F was further investigated using ESR spectra, VB-XPS, and UV-visible DRS. These investigations led to a proposed mechanism, illustrated in Fig. 20(f-h), where spontaneous interfacial electron transfer occurred from ZnIn₂S₄ to Y-CeO₂ to attain Fermi level equilibrium. This electron movement initiates an interfacial electric field (IEF), preventing further electron transfer. Y-doping in CeO₂ causes the band edge to shift downward, while ZnIn₂S₄ inclusion develops an upward band bending near the interface. When exposed to light, electrons move from the VB creating holes in the CB, leading to the recombination of photoexcited electrons and holes from the CB of Y-CeO₂ and the VB of ZnIn₂S₄, respectively. The study highlights the efficacy of UPS in determining Fermi levels and supporting the S-scheme carrier dynamics.

5.8. Steady-state PL spectroscopy

The application of steady-state photoluminescence (PL) spectroscopy is prevalent due to its non-destructive, rapid, and easier sample-preparation nature. This technique is essential for assessing optoelectronic characteristics across a variety of samples, such as heterostructures,¹⁷⁹ defect analysis,¹⁸⁰ and evaluating solar cell efficiency.¹⁸¹ The mechanism underlying PL is demonstrated in Fig. 21a, revealing distinct optical behaviors in organic *versus* inorganic semiconductors. Inorganic semiconductors, characterized by tightly bound atoms within a crystal lattice, exhibit delocalized electronic states, forming a broad VB and CB. In contrast, organic materials are better understood through organic semiconductor theory. This review focuses primarily on PL emissions from inorganic semiconductors. When a direct band gap semiconductor absorbs a photon, the energy of which exceeds the band gap (E_g), an electron from the VBM moves to the CBM, resulting in a vacancy in the VBM as shown in Fig. 21a. The photoexcited electron then moves to the lower energy state of CB, dissipating its excess energy as thermal energy. Ultimately, it transitions back

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Fig. 20 Schematic representation of a UPS spectrum. (a) Deep UV light excites electrons from the VB to above the vacuum level (E_{vac}) in a metal sample. (b) Secondary electrons. (c) The UPS spectrum comprises elastically reached photoelectrons and secondary electrons above E_{vac} . The sum of the spectrum width (w) and work function (ϕ) equals the photon energy. The figures are adapted with permission from ref. 176. Copyright 2023, Elsevier. (d) and (e) UPS spectra for Y-doped CeO_2 and ZnIn_2S_4 . The S-scheme heterojunction charge carrier transport process between Y-doped CeO_2 and ZnIn_2S_4 : (f) prior to contact, (g) post-contact, (h) during light exposure. The figures are adapted with permission from ref. 178. Copyright 2022, Elsevier. The PL spectra (i) and the TRPL spectra (j) of samples TF0, TF5, and FPS. The figures are adapted with permission from ref. 182. Copyright 2022, Wiley-VCH.

to the VBM, emitting photons in the process. In inorganic PL, two primary emission types are recognized: intrinsic and extrinsic emissions. Intrinsic (inter band) emissions involve the direct return of the electron to the VB, whereas extrinsic (sub-band-gap) emissions arise as the photoexcited electron becomes captured at defect or impurity sites inside the band gap, indicating the defect and impurity characteristics of the parent system.¹⁵⁶ The freshly generated photons must undergo

depletion of energy to successfully depart the surface of the catalyst (Fig. 21b). Without this loss, photons may reflect back, preventing their escape. Fig. 21c illustrates three key extrinsic radiation mechanisms. One trapping level is involved in extrinsic emissions of both type I and type II, with the energy gap that separates the inter band and sub-band-gap emission lines precisely mirroring the trap energy position inside E_g . However, type III extrinsic radiation demands multiple trap



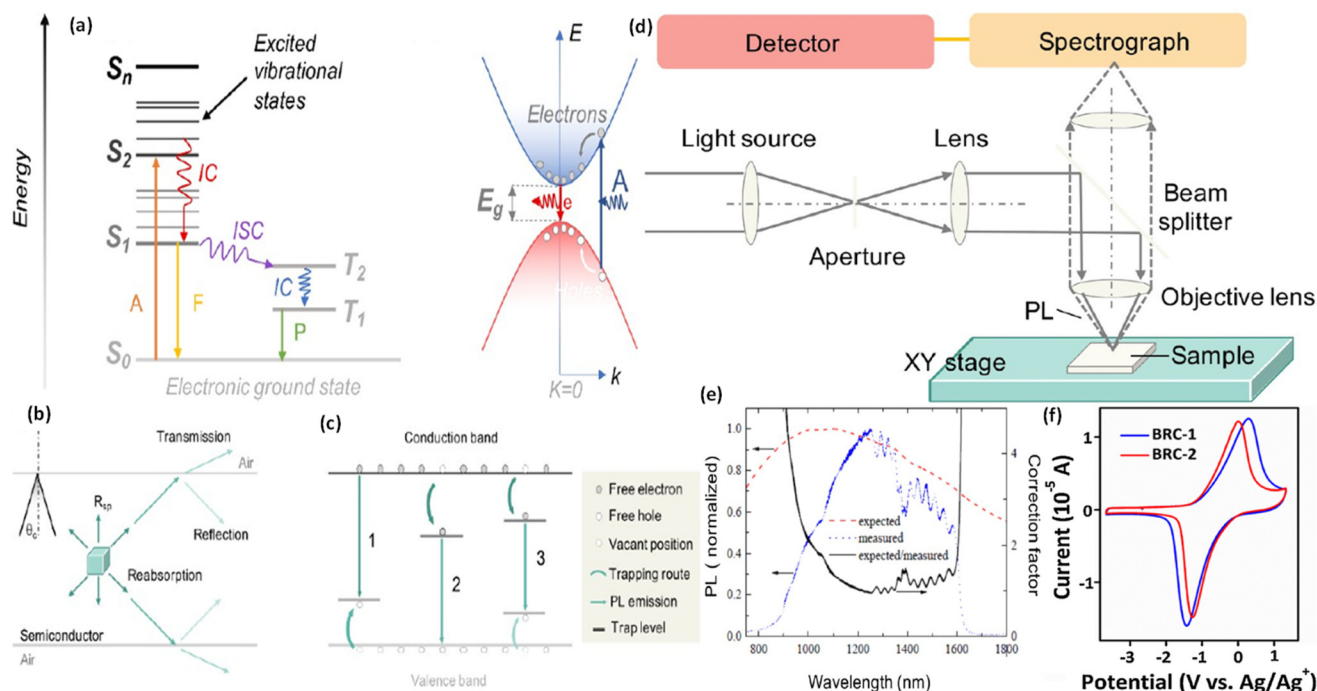


Fig. 21 (a) PL phenomena in organic and inorganic materials with direct bandgaps. Abbreviations: IC (internal conversion), P (phosphorescence), A (absorption), F (fluorescence), ISC (intersystem crossing), e (emission), E_g (bandgap). E and k represent the kinetic energy and wave vector of electrons or holes. Schematic illustration depicting (b) loss mechanisms of spontaneously generated photons within a semiconductor and (c) potential sub-bandgap luminescence pathways arising from defects and impurities. (d) Micro-PL spectroscopy system with reflection geometry and confocal optics. (e) Normalized spectra of a tungsten-halogen light source, showing interference oscillation from 1200 to 1600 nm. The figures are adapted with permission from ref. 181. Copyright 2020, ACS. (f) Cyclic voltammetry curve of BRC-1 and BRC-2 photocatalysts, referenced against the Ag/Ag^+ electrode. The figures are adapted with permission from ref. 183. Copyright 2017, Elsevier.

levels for both holes and electrons. For type III, it is impractical to identify the trap energy position by examining the energy gap that separates the inter band and sub-band-gap emission lines. Nonetheless, in scenarios where the emissions from defects or impurities involve two trap energy positions of type III, one being a deep trapping level (situated at a considerable distance from the band edge) and the other a shallow trapping level (close to opposite band edge), the emissions are characterized by pronounced thermal quenching. At elevated temperatures, carriers stuck in the shallow condition can undergo thermal activation, moving towards the closest band edge, which consequently results in a reduction of emission intensity. The concept also holds true for both type I and type II once the trap zone is near a band edge. The standard configuration for steady-state PL spectroscopy is depicted in Fig. 21d, featuring an appropriate light source for sample excitation, a spectrometer to gather emission spectra, a highly responsive detection device for detecting the scattered radiation, plus an electronic device for optical-electrical data conversion. Within PL spectroscopy, the responses of opto-electronic elements change with light frequency, leading to a spectrum detected by the detector of the system that differs from the sample's original emission spectrum, as depicted in Fig. 21e. Such a difference emphasises the importance of considering the PL spectroscopy system's overall spectral response. An adjustment variable, derived from correlating the

system's anticipated and observed spectra, is employed to adjust subsequent measurements, ensuring precise steady PL spectra analysis, despite system-specific deviations.¹⁸¹

In this context, the $\text{FePS}_3/\text{TiO}_2$ (TiO_2/FPS) heterojunction system is utilized as a case study.¹⁸² Both PL and time-resolved photoluminescence (TRPL) techniques were employed to elucidate exciton dynamics. Fig. 20(i) presents the PL spectra of samples (TF0 and TF5), showing two prominent peaks around 408 nm followed by 467 nm, equating to energy values of 3.04 eV and 2.66 eV, respectively. The PL peak near 408 nm indicates band-to-band emission activity, whereas the PL peak close to 468 nm is likely to be due to band edge-free excitons. The PL intensity of TiO_2 decreases noticeably, when TiO_2 nanoparticles are deposited onto FPS nanosheets, suggesting a lower rate of exciton recombination of the TiO_2/FPS composite (TF5) than that of pure TiO_2 (TF0). Besides, an emission peak of 826 nm is visible in the PL spectra of the FPS composite, relating to the inter band emission of the composite photocatalyst. Further understanding can be gained by examining the exciton lifespans through TRPL analysis, as illustrated in Fig. 20(j). The fitted and average exciton lifetimes of the TF5 composite are significantly higher than those in TF0, suggesting efficient charge separation and migration. Likewise, the TRPL spectra and associated exciton lifetimes for FPS nanosheets are shown in Fig. 20(j). FPS demonstrates a shorter average exciton lifespan than those of TiO_2 and TF5,

suggesting a more rapid recombination of excitons. These observations are in line with the minimal photocatalytic performance observed in FPS, when compared to TF0 and TF5, highlighting the enhanced photocatalytic efficiency of the TiO_2/FPS photocatalyst.

5.9. Cyclic voltammetry (CV)

Cyclic voltammetry (CV) is another technique that, although not yet validated for the S-scheme charge transfer pathway, has proved to be successful in Z-scheme heterojunctions. In this method, the cyclic voltammogram provides the oxidation and reduction capability of the semiconductor, indicated by the peak and trough points, respectively. When the reduction–oxidation potential of a heterojunction system is higher than that of the pristine semiconductor, it suggests an enhancement in the redox power of the photocatalytic system, thereby indicating the creation of a Z-scheme heterostructure. This is in contrast to the type II double charge transfer mechanism, which is expected to reduce the redox potential of the system (Fig. 21f).¹⁸³ In this regard, Ding *et al.* verified the formation of a direct Z-scheme heterojunction within the $\text{BiO}_{1-x}\text{Br}/\text{Bi}_2\text{O}_2\text{CO}_3$ photocatalytic system.¹⁸³ To effectively apply this method, one should compare the CV plot of both the composite photocatalyst and the pristine semiconductor to realise an enhanced redox power in the heterojunction system. Hence, this examination can also serve to validate the direct Z- or more relevant S-scheme interfacial charge transfer within the heterojunctions. For clarity, Table 3 summarizes the specific characterization techniques employed to confirm the charge transfer pathway in direct Z- or S-scheme heterojunctions.

6. Fundamentals and reaction mechanisms of photocatalytic H_2O_2 production over $\text{g-C}_3\text{N}_4$

The process of producing H_2O_2 through light-driven methods using $\text{g-C}_3\text{N}_4$ as a semiconductor photocatalyst encompasses a series of intricate and ongoing reactions. When $\text{g-C}_3\text{N}_4$ is exposed to light energy that is sufficiently higher than the band gap energy, electrons within the VB become energized and move to the CB, leaving behind positively charged holes (h^+) in the VB (Fig. 22a). These photogenerated electrons and holes migrate from the inner part of $\text{g-C}_3\text{N}_4$ to its surface. However, during this migration, there is a tendency for these carriers to recombine, leading to the conversion of energy, which is either emitted as light or generates heat. The carriers that evade recombination reach the catalyst's surface, and some engage in surface reduction or oxidation reactions with oxygen and water molecules, respectively, while others inevitably experience recombination (Fig. 22b). Two significant challenges in H_2O_2 production are the limited ability of the photocatalyst to harness light effectively and the undesirable recombination of charge carriers, which is often attributed to the disorganized flow of charges after their separation. Moreover, the

dynamics of how reactant molecules adhere and become activated on the catalyst's surface play a vital role in this process. Additionally, understanding the specific mechanisms of H_2O_2 formation, along with the thermodynamic energy involved, is crucial for enhancing the efficiency of photocatalytic H_2O_2 generation. According to ongoing research developments, the pathways for the photocatalytic production of H_2O_2 involve the oxygen reduction reaction (ORR) and the water oxidation reaction (WOR).

6.1. Oxygen reduction reaction (ORR) pathway

The photocatalytic oxygen reduction reaction (ORR) follows/encompasses three distinct reaction pathways facilitated by one-, two-, and four-electron transfers, as outlined in eqn (4), (7) and (8). Typically, the formation of H_2O_2 through photocatalysis is predominantly realized by the proton-coupled two-electron ORR, where protons are chiefly sourced from water or organic electron donors.¹⁸⁴ This two-electron ORR can transpire through an indirect stepwise/sequential single electron transfer pathway, as depicted in eqn (4) and (5), or alternatively, through a concerted two-electron pathway, as illustrated in eqn (7). Given that the ORR processes are significantly influenced by the energy position of the CB edge, O_2 is reduced by photoexcited electrons in the CB. In the indirect, sequential one-electron-transfer ORR, O_2 is first reduced to $\text{O}_2^{\cdot-}$, as depicted in eqn (4), which is subsequently followed by the formation of H_2O_2 , as illustrated in eqn (5). Given that the redox potential of $\text{O}_2/\text{O}_2^{\cdot-}$ is set at -0.33 V versus NHE, it is a thermodynamic prerequisite for a semiconductor engaging in a sequential one-electron-transfer ORR to have a CB position that is more negative than -0.33 V versus NHE.

Importantly, this specific CB position not only satisfies the conditions for the one-electron-transfer ORR but also aligns with the thermodynamic prerequisites for the concerted two-electron-transfer ORR.¹⁸⁵ When compared to the direct two-electron-transfer route, the indirect stepwise single-electron-transfer ORR is kinetically desirable due to only one electron being required in each step.¹⁸⁶ Nevertheless, to uphold thermodynamic viability, it necessitates a larger bandgap, consequentially restricting the light absorption capacity. Moreover, complications arise as $\text{O}_2^{\cdot-}$ has the potential to interact with holes, producing singlet oxygen ($^1\text{O}_2$), as shown in eqn (6), which subsequently decreases the selectivity for H_2O_2 .³⁰ Therefore, to prevent such side reactions and inefficiencies due to the presence of unpredictable reactions at more negative potentials, the direct two-electron-transfer ORR is recommended as it holds promising implications for the enhanced production and selectivity of H_2O_2 . Conversely, the semiconductor with CB positions falling between the $\text{O}_2/\text{O}_2^{\cdot-}$ redox potential (-0.33 V vs. NHE) and $\text{O}_2/\text{H}_2\text{O}_2$ redox potential ($+0.68 \text{ V}$ vs. NHE) can produce H_2O_2 directly through the two-electron-transfer pathway, as shown in eqn (7). Hence, the concerted two-electron pathway proves to be more favorable thermodynamically for the photoinduced generation of H_2O_2 in an ORR because it requires less energy in the CB level. However, the synthesis of H_2O_2 *via* the two-electron-transfer



Table 3 Summary of characterization techniques used to verify the charge transfer route in direct Z- or S-scheme heterojunctions

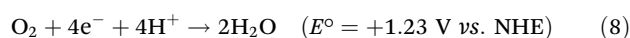
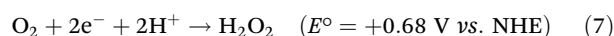
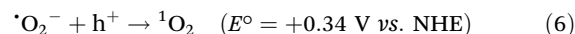
Entry	Characterization method	Operational concept	Overview of procedures	Information shared	Process involved in charge dynamics
1	<i>Ex situ</i> XPS	Variations in electron density	Detailed energy shifts indicate either an increase or decrease in electron density, offering insights into the direction of electrons when determining band positions through methods such as the Mulliken electronegativity principle, XPS, or M-S plot	Loss/gain of electrons	Electron transfer from RSP to OSP
2	<i>In situ</i> irradiated XPS	Loss/acceptance of photogenerated electrons causes a reduction/an increase in electron density and an increase/a decrease in elemental binding energy (E_b)	A combination of high-energy X-rays and ultraviolet-visible (UV-vis) light is employed to irradiate the sample's surface. When subjected to light, photoinduced electrons in the CB of OSP are driven by the interfacial built-in electric field (IEF) to move to the VB of the RSP, resulting in a decrease in the electron density of the OSP and an increase in the RSP. As a result, under light irradiation, the elemental E_b of the OSP increases, and that of the RSP decreases within the heterojunction photocatalyst	Loss/gain of photoinduced electrons	Photoinduced electron transfer from the OSP to the RSP
3	<i>In situ</i> irradiated KPFM	Surface potential distribution of the heterogeneous interface	Typically, when a semiconductor receives electrons, its Fermi level rises, leading to a subsequent reduction in surface potential. Conversely, when it loses electrons, the Fermi level goes down, resulting in an increase in surface potential	Loss/gain of photoinduced electrons	Photoinduced electron transfer from the OSP to the RSP
4	fs-TAS	Detecting the ultrafast interfacial charge transfer signal at the interface of oxidation and reduction photocatalysts	The peak at a specific wavelength in TA spectra is associated with the energy released from the recombination of electrons in the OSP and holes in the RSP	TA spectra signal shows the interfacial transfer of photogenerated electrons from the OSP to the RSP	Recombination of electrons in the OSP and holes in the RSP
5	DFT	Theoretical machine learning tool designed to forecast band structure and behavior	Various parameters are configured to anticipate the behavior of semiconductor band structures and ascertain their electronic arrangement, aiding in the prediction of interfacial charge transfer	Work function, loss or gain of electrons	Dissimilar Fermi levels between the RSP and the OSP, electron transfer from the RSP to the OSP
6	EPR	Records signals during trapping experiments	DMPO signals, produced by radicals, are captured by the instrument with or without light irradiation for comparison purposes, particularly when evaluating pristine semiconductors against various synthesized composites	Production of $\cdot\text{O}_2^-$ and $\cdot\text{OH}$ radicals	Electrons confined within the CB of the RSP and holes retained in the VB of the OSP
7	Metal photodeposition	$\text{M}^{2+} + ze^- \rightarrow \text{M}^0$	Photoreduction of metals occurs where electrons accumulate between the components of the heterojunction and gives the possible mechanism that occurs for such accumulation. Identify the electron-rich zone or reduction site as well as electron-deficient zone or oxidation site of a heterojunction	Loss/gain of photogenerated electrons	Photogenerated electrons retained within the CB of the RSP and holes confined in the VB of the OSP
8	UPS	Determination of E_F , CB, and VB positions	The UPS spectra can be linearly approximated to derive the band structures of semiconductor photocatalysts, enabling the design of charge transfer mechanisms with the assistance of the radicals identified during trapping experiments	Work function	Dissimilar Fermi levels between the RSP and the OSP



Table 3 (Contd.)

Entry	Characterization method	Operational concept	Overview of procedures	Information shared	Process involved in charge dynamics
10	TRPL	Band-to-band (intrinsic) and sub-band-gap (extrinsic) emissions	The fitted and average exciton lifetimes in the composite are significantly higher than those in the pristine sample, suggesting efficient charge separation and migration. A shorter average exciton lifespan suggests a more rapid recombination of excitons	Lifetimes of charge carriers	Lifetime decay kinetics
11	CV	The curve shows reduction and oxidation potentials of a material	Contrasting the CV curves of pristine semiconductors with those of the composite will indicate whether the redox capability in the composite is enhanced as a result of direct Z- or S-scheme, given that type II typically diminishes the redox capability	Redox power of the photocatalytic system	Electrons confined within the CB of the RSP and holes retained in the VB of the OSP

ORR pathway presents a formidable challenge, chiefly due to unsatisfactory selectivity, determined by the activation energy, stemming from the competing four-electron-transfer pathway, which enjoys a more favorable thermodynamic barrier (Fig. 22c and d). Precisely, the redox potential of $\text{O}_2/\text{H}_2\text{O}$ (+1.23 V *vs.* NHE) is more positive compared to $\text{O}_2/\text{H}_2\text{O}_2$ (+0.68 V *vs.* NHE), establishing H_2O as the prevalent product. Particularly, semiconductors with a CB more positive than +0.68 V *versus* NHE will find H_2O_2 synthesis thermodynamically impeded/prohibited, favoring the four-electron-transfer process to yield H_2O instead.



6.2. Water oxidation reaction (WOR) pathway

Contrary to the ORR, the WOR is initiated by photoinduced holes within the VB of g- C_3N_4 . Similar to the ORR, the WOR can proceed through three distinct reaction pathways, involving one-, two-, and four-electron transfers, represented by eqn (10), (9) and (12), respectively. Remarkably, the redox potential for the 2e^- transfer pathway is +1.76 V *versus* NHE (eqn (9)), which is higher than +1.23 V *versus* NHE for the 4e^- transfer pathway (eqn (12)). This signifies that the formation of H_2O_2 is thermodynamically less favorable compared to the oxygen evolution reaction (OER). Consequently, this thermodynamic preference results in the predominant generation of O_2 and poses a challenge for H_2O_2 production during the WOR. The production of H_2O_2 through water oxidation can occur *via* a concerted 2e^- transfer WOR or an alternative indirect, stepwise single e^- transfer WOR pathway. In the indirect route, when the VB edge surpasses +2.73 V *versus* NHE, the single electron transfer WOR has the potential to generate $\cdot\text{OH}$, as illustrated by eqn (10), and subsequently, a pair of $\cdot\text{OH}$ can merge to produce H_2O_2 , in accordance with eqn (11). However, the realization of this process is entangled with difficulties attributed to the high standard potential (+2.73 V *vs* NHE), sluggish reaction rates, and diminished selectivity over the OER process.¹⁸⁷ The pronounced oxidation potential of the $\text{H}_2\text{O}/\cdot\text{OH}$ couple restricts the formation of $\cdot\text{OH}$, which also plays a pivotal role in the decomposition of H_2O_2 .¹⁸⁵ Relative to the indirect step, the direct concerted 2e^- transfer WOR, represented by eqn (9), demonstrates superior thermodynamic favorability for the synthesis of H_2O_2 . This necessitates the VB edge position of the photocatalyst to be located within the +1.76 and +2.73 V range *versus* NHE. However, this photoinduced WOR route, indicated by eqn (9), invariably intertwines with competing reactions, such as the single-electron WOR generating $\cdot\text{OH}$ (eqn (10)) and the four-electron reaction resulting in O_2 (eqn (12)). While the process involving



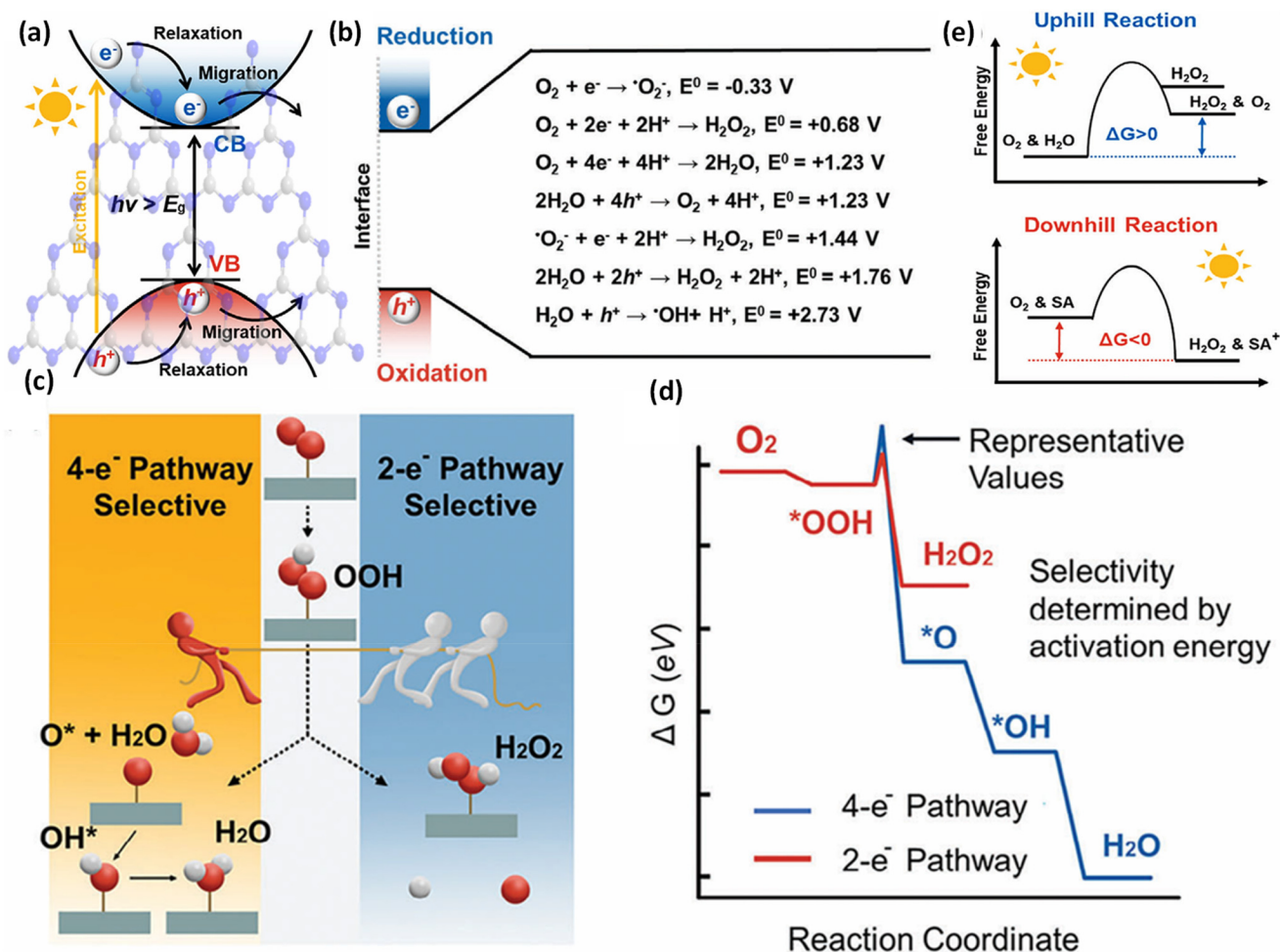


Fig. 22 Illustrations of various stages of (a) photoexcitation and transfer of charge carriers. (b) Surface redox reaction processes relevant to solar H_2O_2 formation. (c and d) The competition between two-electron and four-electron routes in the oxygen reduction reaction, represented by a free energy diagram. (e) The concept of uphill and downhill processes in this production process. The figures are reproduced with permission from ref. 189. Copyright 2024, Wiley-VCH.

the formation of H_2O_2 through the pairing of hydroxyl radicals induced by holes is theoretically feasible (as outlined in eqn (11)), the actual yield of H_2O_2 is constrained by the necessity of having a high concentration of these hydroxyl radicals. This requirement significantly limits the production efficiency of H_2O_2 . Additionally, the light-driven two-electron WOR path, which is essential in this process, requires a high oxidation potential. This high potential, unfortunately, leads to a situation where the newly formed H_2O_2 is prone to rapid decomposition, further complicating the effective generation of H_2O_2 . The photocatalytic WOR for synthesizing H_2O_2 typically does not occur in isolation, mainly due to its inherent limitations. However, an innovative approach involves coupling the two-electron WOR pathway with the hydrogen evolution reaction (HER). This coupling results in a unique intermediate photocatalytic process that simultaneously produces H_2 and H_2O_2 . Furthermore, H_2O_2 synthesis can be effectively achieved through a dual-pathway strategy, which integrates both the four-electron WOR and the two-electron WOR.¹⁸⁴ In

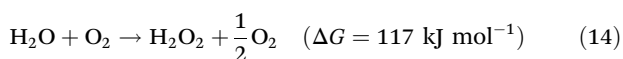
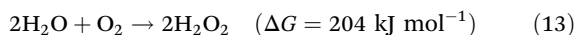
this synergistic process, the four-electron WOR pathway supplies oxygen for the ORR pathway, which in turn facilitates the generation of H_2O_2 .



6.3. Integrated dual-channel pathway

H_2O_2 can be produced through a novel approach by combining the ORR and the WOR. For instance, merging the ORR pathway with the WOR pathway can yield H_2O_2 via dual path-

ways from both O_2 and H_2O , enabling 100% atom utilization efficiency as all atoms of O_2 and H_2O contribute to forming H_2O_2 (eqn (13)), integrating the two-electron ORR and the two-electron WOR, which is a combination of eqn (7) and (9).¹⁸⁸ This integrated approach harnesses the full energy of photoproduced electrons and holes, thus optimizing the photocatalysis process. Additionally, it enables H_2O_2 formation without utilizing sacrificial agents. Another way to synthesize H_2O_2 involves combining the four-electron WOR process with the two-electron ORR process, utilizing H_2O as an electron donor. This process is outlined using water and oxygen as the sole reactants. Thermodynamic considerations reveal a challenge in the direct synthesis of H_2O_2 through two-electron water oxidation driven by photogenerated holes, as detailed in eqn (9). This difficulty arises because the oxidation of water to oxygen (O_2) in a four-electron process, which occurs at a potential of +1.23 V *versus* NHE, is more thermodynamically favorable than the two-electron process leading to H_2O_2 , which happens at +1.76 V *versus* NHE. It is important to note, however, that this alternative route described in eqn (14), combining eqn (7) and (12), generates excess O_2 , resulting in less than 100% atom utilization efficiency. In the production of H_2O_2 , as outlined in eqn (13) and (14), the water oxidation half-reaction is thermodynamically challenging, requiring an uphill effort with a notable gain in free energy, specifically 204 kJ mol^{-1} and 117 kJ mol^{-1} respectively. This process of generating H_2O_2 from O_2 and H_2O , without the use of sacrificial agents, aligns well with the principles of a photosynthesis process, as characterized by a positive free energy change ($\Delta G > 0$) (Fig. 22e).¹⁸⁹ In this scenario, solar energy is effectively harnessed and stored in the form of H_2O_2 through photosynthesis. Conversely, when employing a hole scavenger, like organic alcohols, in the oxidation half-reaction (seen in eqn (15)), the production of H_2O_2 shifts to a photocatalytic process. This is because it is a thermodynamically favorable or “downhill” reaction, where the free energy change is negative ($\Delta G < 0$) (Fig. 22e).¹⁸⁹ In such photocatalytic processes, while solar light speeds up the reaction, it does not result in the storage of solar energy.¹⁸⁹ It is important to note that the terms “photosynthesis” and “photocatalytic” are often used interchangeably to describe the H_2O_2 generation reaction. However, a clear understanding and differentiation of these terms is essential for accurate scientific communication, especially considering their distinct thermodynamic properties and the role of solar energy in each process.



Electrochemical investigations have shown that the CB of g- C_3N_4 is situated at approximately -1.13 V *versus* NHE. This level is adequately negative, surpassing the required potentials for both O_2/H_2O_2 (0.68 V *vs.* NHE) and O_2/O_2^- (-0.33 V *vs.* NHE) conversions, endowing it with the necessary

reduction potential to generate H_2O_2 . However, the VB of g- C_3N_4 , at around 1.51 V *vs.* NHE, does not meet the 1.76 V *vs.* NHE threshold needed for H_2O_2 production through the WOR. Such findings show that g- C_3N_4 possesses a reduction potential that is adequate for H_2O_2 synthesis *via* the ORR under the influence of visible light.⁴⁹ In the context of overall photocatalytic H_2O_2 generation, the OER plays a pivotal role, as illustrated in eqn (12). The VB potential of g- C_3N_4 , estimated to be around 1.51 V *vs.* NHE, is sufficiently high to facilitate water oxidation, yielding oxygen (1.23 V *vs.* NHE) and thereby driving the photocatalytic OER. Nonetheless, the overpotential associated with the OER often acts as a bottleneck in oxygen evolution, thereby impeding the overall efficiency of the photocatalytic production of H_2O_2 . Thus, enhancing the OER reaction kinetics is vital for boosting overall H_2O_2 production efficiency.

Despite the adequacy of the CB and VB of g- C_3N_4 for initiating the reaction, the photocatalytic efficiency remains limited. The efficiency of surface reactions on photocatalysts is largely influenced by the nature of the surface atoms present, the microstructure, and the density of active sites. Consequently, for effective photocatalytic H_2O_2 generation, it is crucial to modify g- C_3N_4 to better support the adsorption and activation of O_2 and H_2O molecules.

7. Dynamics of hydrogen peroxide formation and breakdown

Hydrogen peroxide is inherently unstable, readily decomposing when exposed to ultraviolet (UV) light, under alkaline conditions, or at elevated temperatures. Additionally, the failure to promptly remove H_2O_2 from the surface of the catalyst can lead to further reactions with electrons or holes, thus diminishing the efficiency of photocatalytic H_2O_2 production. During the one-step reduction of H_2O_2 , $\cdot OH$ radicals are formed, whereas h^+ can interact with H_2O_2 to produce $\cdot O_2^-$ (see eqn (16) and (17)).^{184,185,188}



The kinetics of H_2O_2 photoproduction is characteristically reversible, attributed to the simultaneous occurrence of its formation and decomposition, which hampers satisfactory yields of H_2O_2 . This photocatalytic production is a balance between the formation and decomposition processes of H_2O_2 . The kinetics of H_2O_2 formation and decomposition are characterized by zeroth- and first-order processes, respectively, with the overall behavior described by empirical eqn (18) and (19).

$$\ln\left(\frac{[H_2O_2]_t}{[H_2O_2]_0}\right) = tk_d \quad (18)$$

$$[H_2O_2] = \frac{k_f}{k_d}(1 - e^{-k_d t}) \quad (19)$$



Here, k_f and k_d represent the rate constants for the formation ($\mu\text{mol L}^{-1} \text{min}^{-1}$) and decomposition (min^{-1}) of H_2O_2 , respectively, where t denotes time (min) and $[\text{H}_2\text{O}_2]_t$ ($\mu\text{mol L}^{-1}$) refers to the concentration of H_2O_2 at a given time t . Consequently, a higher k_f coupled with a lower k_d indicates increased activity towards H_2O_2 generation, highlighting the efficiency of the process. The complexity of H_2O_2 decomposition is influenced by various factors, including the intensity of light and the surface properties of the photocatalyst, where reducing light energy by employing visible light or decreasing the adsorption capacity of the photocatalyst for H_2O_2 can affect the process.³⁰

8. Photocatalytic generation of H_2O_2 by g- C_3N_4

Shiraishi *et al.* initially explored the mechanism behind the photocatalytic generation of H_2O_2 by g- C_3N_4 , highlighting the

crucial function of O_2 .⁷⁴ Through employing 5,5-dimethyl-1-pyrroline *N*-oxide (DMPO), a reagent for spin-trapping, their study demonstrated the limited occurrence of one-electron O_2 reduction to form the $\cdot\text{OOH}$ radical on g- C_3N_4 . This conclusion was supported by electron spin resonance (ESR) analysis, as shown in Fig. 23a, where there was the presence of a negligible adduct signal, when g- C_3N_4 served as the photocatalyst. This minimal signal infers that the electron prefers to quickly reduce the superoxo radical (transitioning from d to f) rather than engaging in one-electron O_2 reduction (transitioning from d to e). Analysis of the Raman spectra, as presented in Fig. 23b, reveals that isotopic labeling leads to the appearance of new broadband signals at 891 cm^{-1} in the EtOH/ $\text{H}_2\text{O}/^{16}\text{O}_2$ system and at 861 cm^{-1} in the EtOH/water/ $^{18}\text{O}_2$ system, signifying the generation of 1,4-endoperoxide species on the tri-s-triazine unit of the photoexcited g- C_3N_4 surface, *via* a two-electron oxygen reduction pathway (illustrated in Fig. 23c, from d to f). The virtually nonexistent $\cdot\text{OOH}$ radical formation (refer-

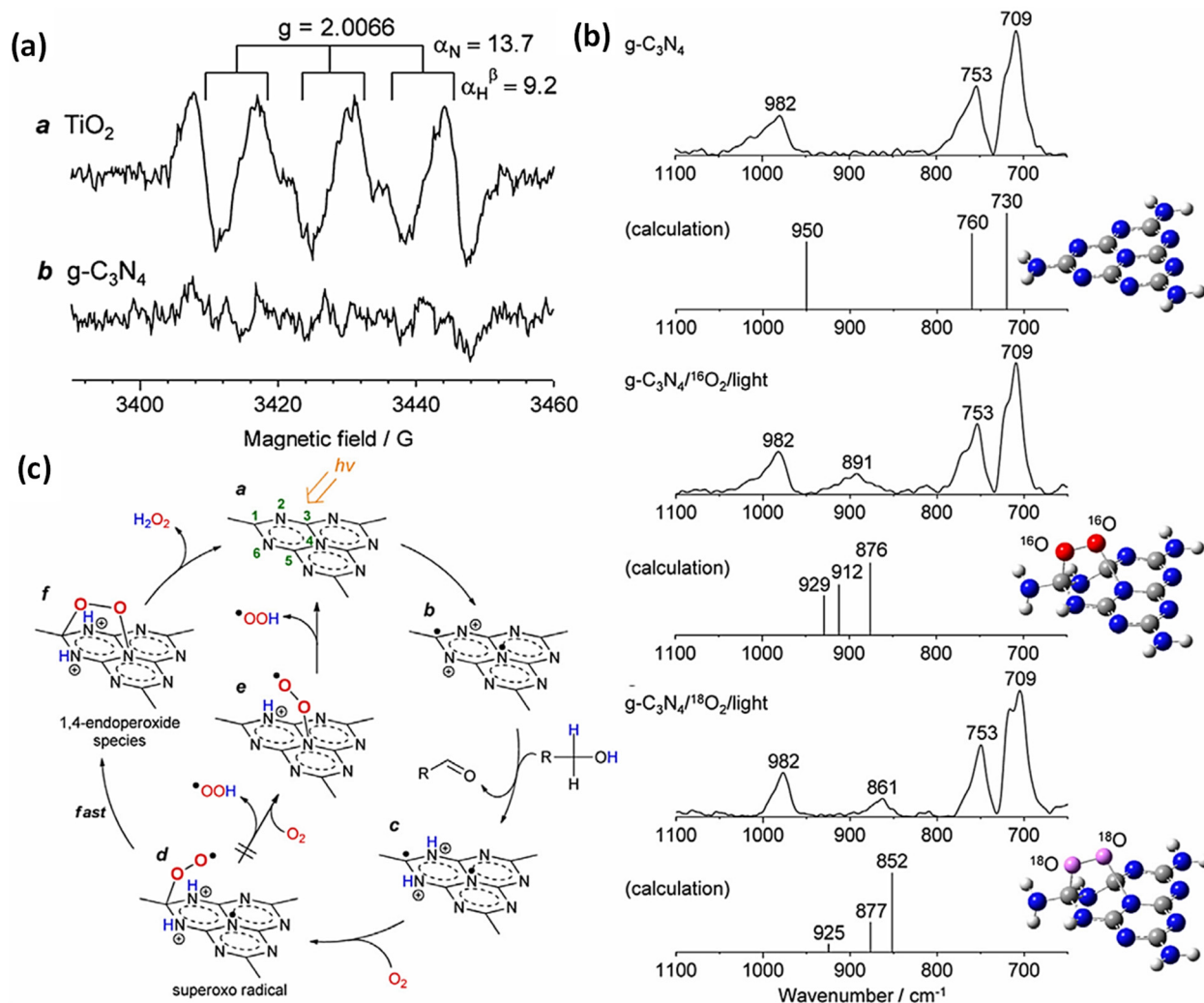


Fig. 23 (a) ESR spectra of solutions resulting from the photoillumination of TiO_2 and g- C_3N_4 in an ethanol/water/ O_2 system. (b) Raman spectra and calculated Raman shifts for g- C_3N_4 following photoreaction with $^{16}\text{O}_2$ and $^{18}\text{O}_2$ in an ethanol/water mixture. (c) The mechanism for the selective formation of H_2O_2 on g- C_3N_4 under visible light illumination. The figures are reproduced with permission from ref. 66. Copyright 2023, Wiley-VCH.



enced in Fig. 23c; from d to e) likely results from the rapid reduction of the superoxo radical (transitioning from d to f), facilitated by the stabilization of endoperoxide species at the C1 and N4 positions of the triazine ring. Consequently, this mechanism effectively hinders/inhibits one-electron O₂ reduction (d → e → a), favoring instead a preferential two-electron reduction pathway. Such a process explains the exceptionally high selectivity of g-C₃N₄ (around 90%) for H₂O₂ production.

Drawing from the aforementioned information, Shiraishi *et al.* introduced the mechanism for the photocatalytic production of H₂O₂ by g-C₃N₄, as shown in Fig. 23c. Initially, illumination of g-C₃N₄ generates photogenerated charges (a). These charges then separate, with electrons localizing at the C1 and N4 sites of the triazine ring and holes at the N2 and N6 sites (b). The α- and β-hydrogens of the alcohol remove these holes, generating an aldehyde (b to c), while oxygen captures the electrons from either the C1 or N4 site to form a superoxo radical (c to d). Subsequently, this radical is quickly reduced by another electron at the *para* position, leading to the formation of the 1,4-endoperoxide species (d to f). The cycle is completed with the protonation of this species, producing H₂O₂ (f to a), thereby finishing the photocatalytic process.

9. Performance evaluation method: apparent quantum yields (AQYs) and solar-to-chemical conversion (SCC) efficiencies

The apparent quantum yield (AQY) and solar-to-chemical conversion (SCC) efficiency serve as pivotal parameters for assessing the photocatalytic performances of photocatalysts, specifically in the domain of H₂O₂ production. The AQY is essentially determined by the ratio of the number of electrons transferred for H₂O₂ production to the number of incident photons at a given wavelength, and is calculated according to eqn (20)–(22).^{42,190}

$$\text{AQY (\%)} = \frac{2 \times n_{\text{H}_2\text{O}_2}}{N_{\text{aph}}} \times 100\% \quad (20)$$

$$N_{\text{aph}} = \frac{E \times A_d}{U_\lambda} \quad (21)$$

$$U_\lambda = \frac{h \times c \times N_A}{\lambda} \quad (22)$$

In the above formulas, $n_{\text{H}_2\text{O}_2}$ represents the molar amount of H₂O₂ produced, N_{aph} is the number of incident photons entering the reaction vessel, and E signifies the measured difference in light intensity transmitted before and after being absorbed by the photocatalyst (mW cm⁻²). Additionally, A_d denotes the area of the light collector part of the radiometer (cm²), U_λ is the molar photon energy of the given wavelength λ (J mol_{photon}⁻¹), $h = 6.626 \times 10^{-34}$ J s⁻¹ is the Planck constant, $c = 3 \times 10^8$ m s⁻¹ represents the speed of light in a vacuum, $N_A = 6.022 \times 10^{23}$ mol⁻¹ is the Avogadro number, and λ specifies the

given wavelength of incident photons (nm). AQY measurements, pivotal for understanding photocatalytic H₂O₂ production performance, are conventionally executed in a borosilicate glass bottle, utilizing an air mass (AM) 1.5 solar simulator in conjunction with wavelength-dependent band-pass filters, facilitating a meticulous and detailed evaluation of photocatalytic efficiency under varying conditions.

Moreover, solar-to-chemical conversion (SCC) efficiency also plays an integral role in the comprehensive evaluation of photocatalysts, providing a nuanced understanding of the conversion efficiency of solar energy into chemical energy, enriching the overall interpretative framework for analyzing photocatalytic performances and their optimization. The SCC efficiency is a critical metric and is instrumental in evaluating the transformation of captured solar energy into H₂O₂. The methodology for measuring SCC efficiency aligns closely with the conditions employed for AQY measurements, with the noteworthy exception being the incorporation of a $\lambda > 420$ nm cutoff filter. This filter is indispensable for preventing the consequential decomposition of synthesized H₂O₂ by ultraviolet light, ensuring the integrity of the measurement.

The mathematical representation for calculating SCC efficiency is given by eqn (23):^{185,190}

$$\text{SCC efficiency (\%)} = \frac{\Delta G \times n_{\text{H}_2\text{O}_2}}{P \times t} \times 100\% \quad (23)$$

Here, $\Delta G = 117$ kJ mol⁻¹ symbolizes the Gibbs free energy required for the generation of H₂O₂ from H₂O and 1/2O₂, P represents the power of the incident photons, denoted in watts (W), and t delineates the illumination time, measured in seconds (s). The number of incident photons, coupled with the average intensity of irradiation, can be meticulously quantified by a radiometer, rendering a more accurate depiction of the solar energy harnessed for H₂O₂ production.

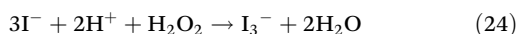
In essence, SCC efficiency provides a meticulous evaluation of the capability to convert captured solar energy into H₂O₂, extending a nuanced understanding of the operational efficacy of photocatalysts in harnessing solar energy for chemical transformations, thereby enriching the analysis and optimization potential of photocatalytic processes.

10. Quantification method for photogenerated H₂O₂

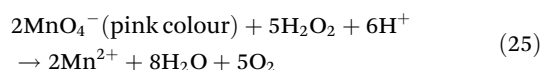
Accurate measurement of photogenerated H₂O₂ is crucial for advancing the field of photocatalytic hydrogen peroxide production since the concentrations achieved through photocatalytic methods generally range from the micromolar to millimolar levels. Presently, the primary methods for this quantification are spectrophotometric analysis and chemical titration techniques. In spectrophotometry, the concentration of H₂O₂ is typically ascertained by employing redox reactions involving H₂O₂ and specific colour-forming agents. These reactions transform colourless H₂O₂ into substances with distinct colours, which are then quantified *via* UV-visible or fluo-



rescence spectrophotometry supported by pre-established calibration curves. One classical approach employs iodometry, where H_2O_2 oxidizes iodide ions to form triiodide ions, displaying a unique absorbance peak around 350–353 nm (eqn (24)).³⁰ To facilitate this redox reaction, a surplus of potassium iodide (KI) and a catalytic amount ammonium molybdate ($(\text{NH}_4)_2\text{MoO}_4$) are introduced into the initial colourless medium, where the stoichiometric reduction of H_2O_2 occurs.



A variety of indicators have been investigated for their efficacy, including the catalysis of potassium iodide by potassium hydrogen phthalate, the oxidation of *N,N*-diethyl-*p*-phenylenediamine (DPD) facilitated by peroxidase (POD) and other reactions such as the oxidation of VO_3^- salts, the acid-catalyzed oxidation of *o*-tolidine, and the oxidation of oxo(5,10,15,20-tetra(4-pyridyl)porphyrinato) titanium(IV) ($\text{TiO}(\text{tpypH}_4)^{4+}$). Additionally, the reduction of Cu(II) in the presence of 2,9-dimethyl-1,10-phenanthroline (DMP), the reduction of cerium(IV) salts, and the horseradish peroxidase (HRP)-catalyzed dimerization of *p*-hydroxyphenylacetic acid (POHPAA) have been studied. However, the reliability of these colorimetric indicators can be compromised in the presence of specific organic electron donors. For instance, *p*-benzoquinone has been found to interfere with DPD and VO_3^- , leading to inaccuracies in H_2O_2 quantification. Chemical titration, specifically using potassium permanganate (KMnO_4), is another commonly employed method for detecting H_2O_2 . This technique capitalizes on the reductive decolorization of KMnO_4 by H_2O_2 (eqn (25)). The reaction can be summarized as follows:



However, this titration method is susceptible to interference from aromatic compounds and suffers from the issue of over-oxidation of a variety of species including H_2O_2 due to the robust oxidizing nature of KMnO_4 , thus affecting the accuracy of H_2O_2 quantification. Thus, spectrophotometric techniques appear to offer more targeted and reliable results than titration methods, primarily because the resulting products are identifiable by their specific wavelengths. Despite the range of available H_2O_2 detection methods, there is a pressing need for a standardized, accurate method for quantifying H_2O_2 concentrations in photocatalytic systems.

11. Advancements in g- C_3N_4 -based direct Z-scheme and S-scheme catalysts for photocatalytic hydrogen peroxide generation

In this section, we provide an overview of recent studies on g- C_3N_4 -based direct Z-scheme and more relevant S-scheme

heterostructures aimed at generating hydrogen peroxide (H_2O_2) through photocatalysis. We provide a concise overview of the results from different research groups and include Tables 4 and 5, which outline the reaction conditions and efficiencies documented in each study. The development of a heterostructure based on g- C_3N_4 , either in the form of a direct Z-scheme or the increasingly significant S-scheme, when combined with oxidation-type photocatalysts, enables the overall photosynthesis of H_2O_2 by facilitating the simultaneous production of H_2O oxidation and O_2 reduction products by utilizing the spatially separated oxidation and reduction components.¹⁹¹ This system simultaneously enhances the photocatalytic activity by broadening light absorption, improving stability, and boosting charge carrier and redox active site separation and modulating their transportation, while also prolonging carrier lifetimes and optimizing redox potential. It also aligns with the optical responses of adjacent components, induces band bending, and creates an IEF with preferred band alignment, promoting the segregation of useful photoinduced charge carriers, concurrently addressing the aforementioned challenges of g- C_3N_4 . This topic is currently at the forefront of research in artificial photocatalysis. Our goal is to provide an understanding of how to create efficient g- C_3N_4 -based photocatalysts for the generation of H_2O_2 .

In research conducted by Shiraishi *et al.*, it was found that resorcinol-formaldehyde (RF) resins could function as a metal-free photocatalyst for generating H_2O_2 in the absence of a sacrificial agent.¹⁹² The SCC efficiency of the resin synthesized at 250 °C achieved a global high of 0.5%. Studies have shown that RF resins created at low hydrothermal temperatures (below 200 °C) display weak photocatalytic activity. This is attributed to the lack of quinone units ($\text{C}=\text{O}$ group), which act as electron acceptors (A), thereby impeding the production of H_2O_2 . The formation of the quinone group during hydrothermal synthesis at high temperatures (above 250 °C) requires auto-pressurization, which is a crucial step in the process. To overcome the issues associated with high-temperature synthesis, the group of Su introduced g- C_3N_4 into RF resins using a low-cost, solvent-free ball milling mechanochemical method. This innovative approach effectively lowered the temperature required for quinone group formation from 250 °C to 180 °C, making the process more accessible (Fig. 24a).¹⁹³ This Z-scheme structure led to an extended visible light absorption range beyond 800 nm, resulting in the production of 72.8 μmol of H_2O_2 within 12 hours when exposed to visible light without the need for sacrificial agents. This represents a 2.37-fold enhancement in comparison with the performance of the unmodified RF resin (Fig. 24b). This innovative approach offers fresh perspectives on the preparation of Z-scheme photocatalysts and the formation of quinone groups in RF resin, contributing to advancements in generating H_2O_2 within sacrificial agent free systems using visible light, and presenting possibilities for widespread applications. In a different study, Li and colleagues developed a metal-free, entirely organic S-scheme heterojunction, PDINH/PCN, by depositing perylene-3,4,9,10-tetracarboxylic diimide (PDINH)



Table 4 Summary of recent g-C₃N₄-based direct Z-scheme systems used for photocatalytic H₂O₂ production

Entry	Photocatalyst	Electron donor	Concentration of photocatalyst	Irradiation conditions	H ₂ O ₂ production	AQY	Ref.
1	g-C ₃ N ₄ /perylene imides	None	50 mg catalyst in 50 mL of distilled water	300 W Xe lamp with a 420 nm cutoff filter Vis ($\lambda > 420$ nm)	120 μmol (2 h)	3.2% ($\lambda = 420$ nm)	195
2	ZnPPc/NB-g-C ₃ N ₄	None	Catalyst (10 mg) in H ₂ O (20 mL)	Xe lamp through a UV cutoff filter (800 nm $> \lambda > 400$ nm)	114 $\mu\text{mol g}^{-1} \text{h}^{-1}$	N/A	196
3	Ti ₃ C ₂ /g-C ₃ N ₄ /BiOCl	IPA	50 mg catalyst in 50 mL mixed aqueous solution containing 2.5 mL isopropanol (IPA, 5 vol%)	300 W Xe lamp, simulated sunlight	1275 μM (60 min)	NA	205
4	Bi ₄ O ₇ Br ₂ /g-C ₃ N ₄	None	50 mg catalyst in 50 mL water	300 W Xe lamp visible-light ($\lambda > 420$ nm)	124 μM (60 min)	11.8% (420 nm)	50
5	α -Fe ₂ O ₃ /CQD@g-C ₃ N ₄	None	5.0 mg catalyst in 10 mL of water	300 W Xe-lamp (420 nm cutoff)	1.16 $\mu\text{mol L}^{-1} \text{min}^{-1}$	17.80% at 420 nm	207
6	TiO ₂ /B-doped g-C ₃ N ₄	EtOH	20 mg catalyst in 20 mL of DI water containing 1 mL of EtOH	250 W visible light	110 $\mu\text{mol h}^{-1}$	NA	214
7	K ⁺ -doped g-C ₃ N ₄ (KCN)/WO ₃	EtOH	0.2 g catalyst in 200 mL of deionized water, and 5 mL of ethanol	300 W xenon lamp	1.33 mmol L ⁻¹ in 4 h	NA	210
8	Cu ₂ (OH)PO ₄ /g-C ₃ N ₄	None	0.2 g catalyst in deionized water (200 mL)	Solar simulator (300 W Xe lamp and 200 W infrared light)	7.2 mmol L ⁻¹	NA	198
9	Cu ₂ (OH) ₂ CO ₃ /g-C ₃ N ₄	None	0.2 g catalyst in deionized water (200 mL)	Simulated solar light source	8.9 mmol L ⁻¹ (18 h)	NA	199
10	RF resin/g-C ₃ N ₄	None	0.05 g of catalyst in 30 mL pure water (1.67 g L ⁻¹)	300 W xenon lamp with a 420 nm cutoff filter	72.8 μmol (12 h)	NA	193
11	Cd _{0.6} Zn _{0.4} S/g-C ₃ N ₄	Ethanol	10 mg catalyst in 100 mL deionized water containing 10% ethanol	300 W Xe lamp with a 420 nm cutoff filter	1098.5 $\mu\text{mol g}^{-1} \text{h}^{-1}$	NA	11
12	rGO-decorated W ₁₈ O ₄₉ @g-C ₃ N ₄	None	10 mg of the photocatalyst in 50 mL of ultrapure water	300 W Xe lamp with a 400 nm cutoff filter visible light source (400 $< \lambda < 780$ nm)	(71, 58.5, and 9 $\mu\text{mol g}^{-1} \text{h}^{-1}$) under simulated solar, visible (> 400 nm), and NIR light (> 800 nm)	5.8% at 380 nm	208
13	W ₁₈ O ₄₉ /crystalline g-C ₃ N ₄	IPA	50 mg of the photocatalyst in 90 mL of water and 10 mL of the IPA mixture	Full spectrum	5550 $\mu\text{M g}^{-1} \text{h}^{-1}$	NA	211
14	S vacancy (MoS _{2-x})/carbon nitride nanotube (TCN)	IPA	20 mg catalyst in the solution containing 19 mL of deionised water and 1 mL of ethanol	300 W Xe lamp ($\lambda > 420$ nm)	1879 $\mu\text{mol g}^{-1} \text{h}^{-1}$	NA	202
15	Ni ₃ P ₂ /C/N-ZnO@B-doped g-C ₃ N ₄	EtOH	10 mg of catalyst in 50 mL of mixed solution containing 10% of isopropyl alcohol.	UV-visible light irradiation (250 W Hg lamp)	2873.46 $\mu\text{mol h}^{-1} \text{g}^{-1}$	NA	209
16	O-doped g-C ₃ N ₄ /ZnIn ₂ S ₄ -Zn	IPA	10 mg catalyst in 50 mL of mixed solution containing 10% of isopropyl alcohol.	300 W Xe lamp ($\lambda > 420$ nm)	168.67 $\mu\text{mol L}^{-1}$ in 80 minutes	18.61% at 400 nm	200



Table 5 Summary of recent g-C₃N₄-based S-scheme systems used for photocatalytic H₂O₂ production

Entry	Photocatalyst	Electron donor	Concentration of photocatalyst	Irradiation conditions	H ₂ O ₂ production	AQY	Ref.
17	ZnO/g-C ₃ N ₄	EtOH	20 mg catalyst in 45 mL of water and 5 mL of the ethanol mixture	300 W xenon lamp ($\lambda > 350$ nm)	1544 $\mu\text{mol L}^{-1}$	NA	152
18	C ₃ N ₄ /PDA	EtOH	Photocatalyst (20 mg) in an ethanol solution (20%)	300 W xenon arc lamp (simulated sunlight illumination)	3801.25 $\mu\text{mol g}^{-1} \text{h}^{-1}$	2.22% at 400 nm	153
19	S-pCN/WO _{2.72}	None	50 mg catalyst in 100 mL of deionized water	300 W Xe arc lamp ($\lambda > 420$ nm)	87 μM in 3 h	1.5% at 420 nm	212
20	PDI-Ala/S-C ₃ N ₄	None	50 mg photocatalyst in 50 mL distilled water	300 W xenon lamp (420 nm $< \lambda < 780$ nm)	28.3 $\mu\text{mol h}^{-1} \text{g}^{-1}$	NA	146
21	PDINH@PCN	IPA	50 mg catalyst in 50 mL water/IPA with a volume ratio of 9 : 1	300 W xenon lamp	922.4 $\mu\text{mol h}^{-1} \text{g}^{-1}$	NA	194
22	Sv-ZnIn ₂ S ₄ @g-C ₃ N ₄	IPA	Catalyst (20 mg) in solution (45 mL H ₂ O and 5 mL isopropanol)	300 W xenon lamp ($\lambda \geq 420$ nm)	1310.18 μM	NA	174
23	Sulfur-doped g-C ₃ N ₄ /TiO ₂	None	10 mg catalyst in 50 mL of deionized water	300 W Xe lamp	2128 $\mu\text{mol h}^{-1} \text{g}^{-1}$	0.61% at 365 nm	213
24	Zn-TCPP/g-C ₃ N ₄	EtOH	Catalyst (30 mg) in 50 mL of ethanol aqueous solution (10 vol%)	300 W Xe lamp	532.7 $\mu\text{mol L}^{-1}$ in 90 min	7.01% at 365 nm	197
25	g-C ₃ N ₄ /HMoP	EtOH	0.1 g catalyst in 10 mL of ethanol and 190 mL of deionized water	300 W xenon lamp ($\lambda > 420$ nm)	Simulated sunlight (137.1 $\mu\text{mol L}^{-1} \text{h}^{-1}$), visible light (113.1 $\mu\text{mol L}^{-1} \text{h}^{-1}$)	NA	215
26	CuInS ₂ /PCN	IPA	20 mg of photocatalyst in 5% isopropanol aqueous solution (50 mL)	Visible light	1247.6 $\mu\text{mol L}^{-1} \text{h}^{-1}$	16.0% at 420 nm	201
27	g-C ₃ N ₄ /α-MnS	None	50 mg catalyst in 50 mL of deionized water	300 W Xe lamp with visible light cutoff filter	209.4 $\mu\text{M h}^{-1}$	8.5% at 450 nm	203
28	α-MnO ₂ @B/O-g-C ₃ N ₄ /d-Ti ₃ C ₂	EtOH	0.02 g catalysts in 18 mL of DI water and 2 mL of ethanol	250 W Xe lamp	2846.4 $\mu\text{mol h}^{-1} \text{g}^{-1}$	NA	206
29	K ⁺ /I ⁻ -CN/CdSe-D	None	Catalyst (10 mg) in water (50 mL)	Visible light irradiation ($\lambda > 400$ nm).	2240.23 $\mu\text{mol h}^{-1} \text{g}^{-1}$	NA	204





Fig. 24 (a) Schematic depiction of RF-CN-bm preparation. (b) H_2O_2 generation comparison for $\text{g-C}_3\text{N}_4$, RF, RF-CN, and RF-CN-bm. The figures are adapted with permission from ref. 193. Copyright 2023, Elsevier. (c) H_2O_2 formation by the CNP-4 heterojunction under varying conditions. (d) Histogram showing H_2O_2 yield after 1 h of illumination. (e) ESR spectra of the $\text{DMPO}\cdot\text{O}_2^-$ adduct for U-CN and CNP-4 in the absence and presence of light irradiation. (f) Koutecky-Levich plots from RDE analysis of U-CN and CNP-4 at a fixed potential of -1.0 V versus NHE. The figures are adapted with permission from ref. 152. Copyright 2023, Wiley-VCH. (g) H_2O_2 formation over time when exposed to simulated sunlight. (h) Schematic of the photocatalytic mechanisms in the Zn-TCPP/CN S-scheme heterojunction for H_2O_2 generation. The figures are adapted with permission from ref. 197. Copyright 2023, Elsevier.

onto porous carbon nitride (PCN) through a crystallization process.¹⁹⁴ This structure includes PDINH nanosheets, which are formed through interactions involving hydrogen bonding and π - π stacking, combined with PCN nanosheets. The PDINH/PCN composite achieved a peak rate of H_2O_2 production at $922.4 \mu\text{mol h}^{-1} \text{g}^{-1}$, significantly surpassing those of individual PCN and PDINH, as evidenced by ESR spectra showing strong $\cdot\text{O}_2^-$ and $\cdot\text{OH}$ radical signals. This indicates that H_2O_2 synthesis occurs through ORR and WOR dual pathways, utilizing the CB electrons of PCN and the HOMO holes of PDINH in the S-scheme heterojunction for these processes.

Organic/inorganic hybrid heterostructures are emerging as effective solutions for H_2O_2 photosynthesis, typically formed through weak noncovalent interactions like electrostatic interactions, van der Waals forces, and hydrogen bonds. However, efficient charge transfer at the organic-inorganic interface remains a challenge. Using specifically tailored polymer structures, which can covalently bond, may overcome this issue by reducing interfacial charge transfer resistance and enhancing

charge migration. Metal-free Z-scheme photocatalysts are particularly promising in this regard, given the wide range of suitable organic moieties for heterostructure creation. For instance, the Z-scheme photocatalyst $\text{PI}_x\text{-NCN}$, created by covalently attaching polyimides (PIs) to $\text{g-C}_3\text{N}_4$ nanosheets, demonstrates efficient stepwise single-electron ORR and WOR processes for H_2O_2 production.¹⁹⁵ Notably, the optimized $\text{PI}_{5.0}\text{-NCN}$ variant shows a threefold increase in H_2O_2 production rate to $60 \mu\text{mol h}^{-1}$ compared to pristine NCN. Zhang and co-workers developed a novel S-scheme photocatalyst named $\text{C}_3\text{N}_4/\text{PDA}$ (CNP) by combining ultrathin $\text{g-C}_3\text{N}_4$ (U-CN) with *in situ* self-polymerized polydopamine (PDA).¹⁵² This photocatalyst significantly enhances H_2O_2 production, reaching $3801.25 \mu\text{mol g}^{-1} \text{h}^{-1}$, when exposed to light, surpassing the rates of U-CN and PDA by approximately 2 and 11 times, respectively. The S-scheme structure of CNP facilitates improved light utilization, charge carrier segregation, and transmission, resulting in its enhanced efficiency in producing H_2O_2 through photocatalysis. The production process, inhibited under $\cdot\text{O}_2^-$ scavenging conditions, involves an indirect

Bismuth oxyhalides, Bi-rich materials recognized for their outstanding mass transfer properties, stability under light exposure, and responsiveness to visible light, effectively catalyze water oxidation owing to their high VB potential. In this context, Zhang and colleagues created a direct Z-scheme photocatalyst, $\text{Bi}_4\text{O}_5\text{Br}_2/\text{g-C}_3\text{N}_4$, by affixing $\text{Bi}_4\text{O}_5\text{Br}_2$ nanorods onto $\text{g-C}_3\text{N}_4$ nanosheets through a water-assisted self-assembly technique.⁶⁴ This innovative heterostructure demon-

Moreover, combining conventional narrow bandgap semiconductors with g-C₃N₄ to form heterostructures has emerged as a successful approach for creating photocatalysts that are responsive to near-infrared (NIR) light. This enhances solar absorption in the NIR region and improves the separation of charges. In this context, Wang and colleagues created a Z-scheme photocatalyst, Cu₂(OH)PO₄/g-C₃N₄, capable of a full-spectrum response for producing H₂O₂, which was achieved by using an *in situ* hydrothermal method.¹⁹⁸ Cu₂(OH)PO₄, with strong NIR absorption (800–1200 nm), as shown in Fig. 25g, enhances the overall solar absorption of the composite. Additionally, the [PO₄]^{3−} content of Cu₂(OH)PO₄ improves O₂ adsorption, crucial for photocatalytic H₂O₂ production, as indicated by the O₂-TPD signal (Fig. 25h). The optimized CN/CuPO (20%) photocatalyst achieves a 7.2 mmol L^{−1} H₂O₂ concentration under simulated sunlight without sacrificial agents, outperforming neat g-C₃N₄ and Cu₂(OH)PO₄ by 13 and 31.3 times, respectively. Likewise, Li and collaborators prepared a



Fig. 25 3D surface charge potential distribution and corresponding line-scanning profiles of (a) UCN, (b) Cd_{0.6}Zn_{0.4}S, and (c) Cd_{0.6}Zn_{0.4}S/UCN-2 composite in the dark, and (d) the Cd_{0.6}Zn_{0.4}S/UCN-2 heterojunction photocatalyst under illumination. (e) Production rate comparison of UCN and Cd_{0.6}Zn_{0.4}S/UCN composites using visible light. (f) Free energy diagrams illustrating O₂ conversion to H₂O₂ by UCN and Cd_{0.6}Zn_{0.4}S/UCN-2 systems. The figures are adapted with permission from ref. 11. Copyright 2023, RSC. (g) UV-vis spectra comparison of g-C₃N₄, Cu₂(OH)PO₄, and CN/CuPO(20%) samples. The figures are adapted with permission from ref. 198. Copyright 2018, ACS.

Cu₂(OH)₂CO₃/g-C₃N₄ composite capable of responding to the full spectrum of light.¹⁹⁹ They achieved this using a self-sacrificial method, wherein partial decomposition of g-C₃N₄ resulted in a Cu₂(OH)₂CO₃/g-C₃N₄ composite with a highly effective combined interface. This composite exhibited significant absorption in the near-infrared (NIR) range (800–1200 nm) and achieved a H₂O₂ concentration of 8.9 mmol L⁻¹ when exposed to simulated sunlight. This performance surpasses those of pristine g-C₃N₄ and Cu₂(OH)₂CO₃ by more than 16 and 26.9 times, respectively. This highlights the importance of integrating NIR-based semiconductors into Z-scheme photocatalysts for enhanced H₂O₂ production.

In another report, Liu *et al.* developed a 2D/2D Z-scheme photocatalyst in the O-doped g-CN/ZnInS-Zn (ZIS-Z/OCN) system with defect engineering for improved photoinduced ROS production.²⁰⁰ ZIS-Z/OCN, featuring a better interfacial electric field (IEF), reduced charge transport distances, and zinc vacancies, efficiently minimizes hot charge-carrier recombination and speeds up charge movement at the hetero-interface. This leads to exceptional molecular oxygen activation under visible light, surpassing those of pristine ZIS-Z and OCN. Consequently, the 40ZIS-Z/OCN sample produces 168.67 μmol L⁻¹ of H₂O₂ during 80 min of visible light exposure. Furthermore, Sun *et al.* developed a unique photocatalyst by merging agaric-like microporous g-C₃N₄ with sulfur vacancy-modified, flower-like ZnIn₂S₄, forming an S-scheme

heterojunction (g-C₃N₄/Sv-ZnIn₂S₄) that showed a H₂O₂ production efficiency of 1310.18 μM, which was four times higher than that of pristine g-C₃N₄ (Fig. 26a).¹⁷³ The efficiency of the catalyst is enhanced by its strategic morphology, sulfur vacancies, and the design of interfacial S-C bonds, along with an interfacial built-in electric field that guides the S-scheme electron transfer. H₂O₂ generation follows an indirect two-step single-electron transfer route. The charge migration path is evidenced by EPR spectra: under light, the g-C₃N₄/Sv-ZnIn₂S₄ composites show stronger DMPO·O₂⁻ and DMPO·OH signals compared to their individual components, indicating enhanced ·O₂⁻ and ·OH radical production and effective charge migration facilitated by the S-C bonds and S-scheme heterojunction, thus boosting H₂O₂ production (Fig. 26b and c). Jiang and co-workers developed an iron-free photo-Fenton-like (PFL) reaction system using a direct Z-scheme heterostructure composed of sulfur vacancy modified MoS₂ with carbon nitride nanotubes (MoS_{2-v}/TCN), offering a breakthrough for generating hydrogen peroxide over a wide pH range and addressing the traditional limitations of Fenton oxidation (Fig. 27a).²⁰¹ The band structure of MoS_{2-v}/TCN facilitates the rapid segregation of photoexcited electrons and holes. DFT results reveal that the Z-scheme charge dynamics lowers the energy barrier for *tOOH and *HO₂⁻ formation, while S vacancies on MoS_{2-v} improve photoinduced electron utilization by MoS_{2-v}/TCN (Fig. 27b and c). This





Fig. 26 (a) TEM images showing the Sv-ZIS/CN composite. ESR spectra of (b) DMPO-[•]O₂⁻ and (c) DMPO-[•]OH for Sv-ZIS/CN, Sv-ZIS, and 3DA-CN samples. The figures are adapted with permission from ref. 173. Copyright 2022, RSC. (d) H₂O₂ production rates over the catalysts under visible light ($\lambda > 400$ nm) illumination. (e) Schematic depicting the charge transfer mechanism in the K⁺/I⁻/CN/CdSe-D S-scheme heterojunction. The figures are adapted with permission from ref. 204. Copyright 2024, Wiley-VCH.

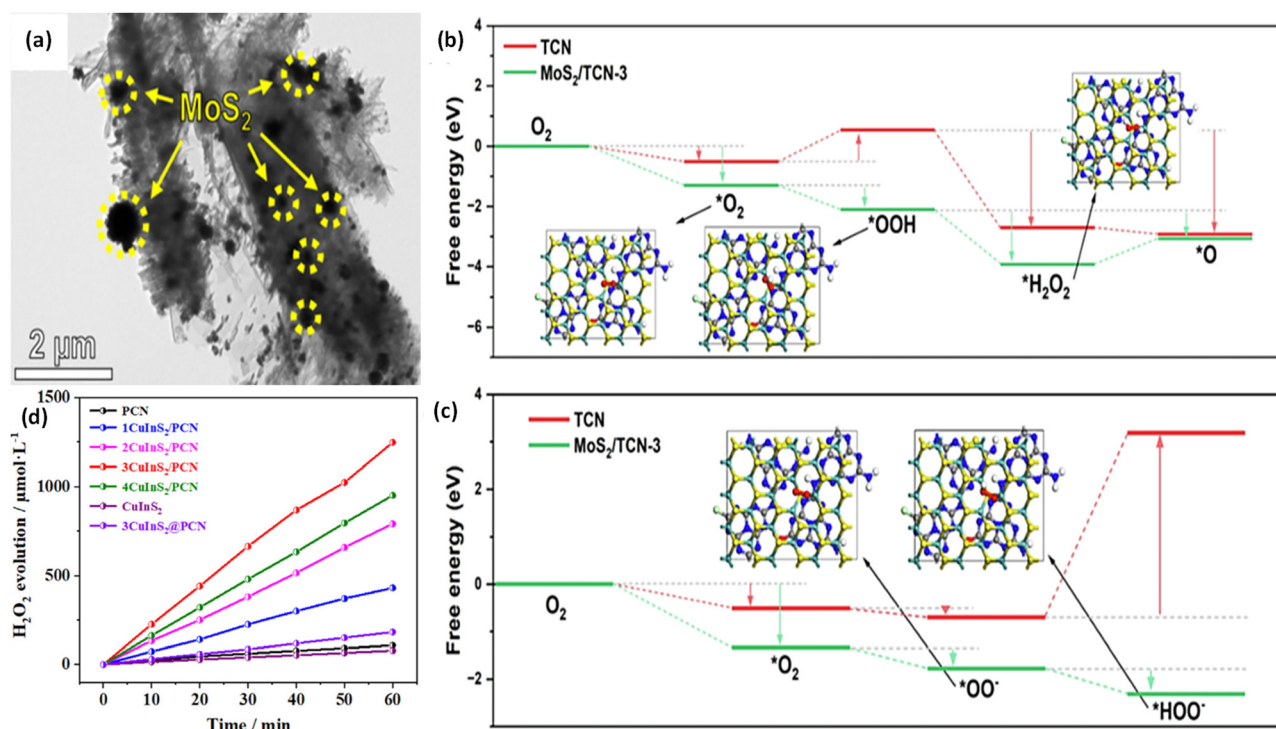


Fig. 27 (a) SEM images of MoS₂-TCN-3. Free energy change graphs for the [•]HO₂⁻ 2e⁻ ORR pathway under (b) acidic and (c) alkaline conditions. The figures are adapted with permission from ref. 201. Copyright 2023, Elsevier. (d) Photocatalytic H₂O₂ generation by PCN, CuInS₂, 3CuInS₂@PCN, and xCuInS₂/PCN samples. The figures are adapted with permission from ref. 202. Copyright 2023, Elsevier.

results in a high performance and stable H_2O_2 generation ($254.8\text{--}269.9\ \mu\text{mol g}^{-1}\text{ h}^{-1}$ in pure water, $1879\ \mu\text{mol g}^{-1}\text{ h}^{-1}$ in 10% isopropanol) over the pH range of 3–9. This approach provides an innovative strategy for on-site generation and activation of H_2O_2 in Fenton oxidation reactions. In related research by Zhang *et al.*, an S-scheme heterojunction, $\text{CuInS}_2/\text{PCN}$, was developed through an *in situ* low-temperature hydrothermal method.²⁰² The catalytic efficiency of the optimized sample, $3\text{CuInS}_2/\text{PCN}$, showed a H_2O_2 production rate of $1247.6\ \mu\text{mol L}^{-1}\text{ h}^{-1}$, substantially exceeding the performance of the separate components. It was 11.6 times higher than that of PCN ($107.4\ \mu\text{mol L}^{-1}\text{ h}^{-1}$) and 16.0 times higher than that of CuInS_2 ($78.0\ \mu\text{mol L}^{-1}\text{ h}^{-1}$) (Fig. 27d). Furthermore, the apparent quantum yield for H_2O_2 generation using $3\text{CuInS}_2/\text{PCN}$ achieved 16.0% at a wavelength of 420 nm.

Additionally, Wang *et al.* developed an S-scheme p–n heterojunction photocatalyst, PCN/MnS , by combining p-type $\alpha\text{-MnS}$ with n-type protonated $\text{g-C}_3\text{N}_4$ (PCN) through a one-step synthesis method.²⁰³ This composite develops a nanosphere morphology of $\alpha\text{-MnS}$ with lamellar-derived protonated $\text{g-C}_3\text{N}_4$ layers on its surface, forming a heterojunction that improves the surface area, light absorption capacity, and charge migration. This structure significantly boosts the photocatalytic production rate of H_2O_2 to $209.4\ \mu\text{M h}^{-1}$, outperforming pure $\alpha\text{-MnS}$ by 1.5 times in air without needing O_2 gas bubbling or sacrificial agents. Moreover, the group of He synthesized a $\text{K}^+/\text{I}^-/\text{CN}/\text{CdSe-D}$ S-scheme photocatalyst by incorporating potassium and iodide ions intercalated into carbon nitride together with diethylenetriamine modified cadmium selenide through a dual approach involving molten salt and microwave-assisted hydrothermal techniques.²⁰⁴ The incorporation of I^- and K^+ ions into C_3N_4 improves light harvesting and reduces the distance required for charge transfer between layers. Additionally, the formation of interfacial C–Se bonds effectively regulates the charge migration process. The $40\%\text{K}^+/\text{I}^-/\text{CN}/\text{CdSe-D}$ composite demonstrated an outstanding H_2O_2 formation rate of $2240.23\ \mu\text{mol h}^{-1}\text{ g}^{-1}$ in the absence of a sacrificial donor through a stepwise single-electron ORR route (Fig. 26d). This method of combined interfacial chemical bonding with ionic intercalation and an S-scheme heterojunction offers a novel approach for reducing the recombination of photoexcited charge carriers and improving the efficiency of H_2O_2 photosynthesis (Fig. 26e).

The incorporation of cocatalysts onto $\text{g-C}_3\text{N}_4$ is a commonly employed method to improve its photocatalytic performance for generating H_2O_2 . Cocatalysts can capture photoinduced electrons from $\text{g-C}_3\text{N}_4$ and provide catalytic centers to promote surface redox reactions. Additionally, certain cocatalysts can improve the light absorption capabilities of $\text{g-C}_3\text{N}_4$. MXene, CQD, rGO, and metallic transition metal compounds such as metal phosphides are frequently used as cocatalysts. They can create Schottky junctions with $\text{g-C}_3\text{N}_4$, serving as efficient electron sinks because of their high work functions, which substantially decrease inherent recombination of electron–hole pairs. Ti_3C_2 MXene, a layered two-dimensional transition metal carbide known for its superior electrical conductivity,

forms a Schottky junction when combined with n-type semiconductors. In this regard, Yang and team members developed a $\text{Ti}_2\text{C}_3/\text{g-C}_3\text{N}_4/\text{BiOCl}$ (TC/g-CN/BOC) composite consisting of both a Z-scheme and Schottky junction with significantly enhanced H_2O_2 production efficiency.²⁰⁵ This composite, under sunlight exposure, enables the transfer of photoexcited electrons from the CB of BiOCl to the VB of $\text{g-C}_3\text{N}_4$ to merge with holes, encouraging oxidation in the VB of BiOCl. Concurrently, electrons from the CB of $\text{g-C}_3\text{N}_4$ transfer towards Ti_3C_2 , aiding in the reduction of O_2 to H_2O_2 . This TC/g-CN/BOC composite shows impressive photocatalytic H_2O_2 production, reaching $1275\ \mu\text{M}$ in 60 min under simulated sunlight. Similarly, Parida *et al.* developed a Schottky functionalized direct Z-scheme ternary heterojunction photocatalyst, $\alpha\text{-MnO}_2@B/\text{O-g-C}_3\text{N}_4/\text{d-Ti}_3\text{C}_2$, employing a simple two-step synthesis method for photocatalytic H_2O_2 production.²⁰⁶ The 5-MX/MBOCN variant, with 10% ethanol, achieved an optimal photocatalytic H_2O_2 formation rate of $2846.4\ \mu\text{mol h}^{-1}\text{ g}^{-1}$, which was 2.5 times higher than its binary MBOCN counterpart. The enhanced performance is owing to the combination of direct Z-scheme charge migration and the incorporation of a metallic delaminated MXene cocatalyst in the Schottky junction, providing a novel approach for optimizing charge migration and boosting H_2O_2 photosynthesis efficiency. Furthermore, Chen *et al.* developed a ternary system, $\alpha\text{-Fe}_2\text{O}_3/\text{CQD}@g\text{-C}_3\text{N}_4$, using a solvothermal process.²⁰⁷ The $\alpha\text{-Fe}_2\text{O}_3/\text{CQD}@g\text{-C}_3\text{N}_4$ hybrid experiences boosted e^-/h^+ separation efficiency due to the established Z-scheme heterojunction along with the electron capturing ability of carbon quantum dots (CQDs), which in turn improved the H_2O_2 production rate. The photocatalyst attains a H_2O_2 production rate of $1.16\ \mu\text{mol L}^{-1}\text{ min}^{-1}$ when exposed to visible light, outperforming pure $\text{g-C}_3\text{N}_4$ by 19 times. Additionally, the inclusion of Fe_2O_3 shifts H_2O_2 formation from a sequential single-electron indirect ORR to a direct two-electron ORR, providing active sites for H_2O_2 formation *via* the 2e^- WOR route, owing to its VB position being more positive than the $\text{H}_2\text{O}_2/\text{H}_2\text{O}$ electrode potential. Similarly, Li *et al.* synthesized a ternary Z-scheme composite, rGO-decorated $\text{W}_{18}\text{O}_{49}@g\text{-C}_3\text{N}_4$ (r-CNW), by employing a straightforward *in situ* hydrothermal technique for H_2O_2 production, in which rGO acted as both a charge transfer facilitator and a co-catalyst for the oxygen reduction reaction.²⁰⁸ The optimal r-CNW-2 sample showed significantly improved H_2O_2 generation rates (71 , 58.5 , and $9\ \mu\text{mol g}^{-1}\text{ h}^{-1}$) under simulated solar, visible ($>400\text{ nm}$), and NIR light ($>800\text{ nm}$), which were 1.3 and 2 times greater than those of $\text{g-C}_3\text{N}_4$ (Fig. 28a). This improvement in performance, especially under NIR light, is credited to the transfer of LSPR hot electrons to the CB of $\text{g-C}_3\text{N}_4$, which boosts the oxygen reduction reaction. The Parida group created a ternary nanohybrid $\text{CNZ}/\text{BCN-Ni}_x\text{P}_{y-x}$ using ZIF-8 derived C,N-codoped ZnO (CNZ) and B-doped $\text{g-C}_3\text{N}_4$ (BCN) decorated with Ni_xP_y nanoparticles through a facile calcination–phosphidation strategy.²⁰⁹ The optimized $\text{CNZ}/\text{BCN-Ni}_x\text{P}_{y-2}$ photocatalyst notably achieved a high H_2O_2 production rate of $2873.46\ \mu\text{mol h}^{-1}\text{ g}^{-1}$ when exposed to light, nearly twice the performance of the binary





Fig. 28 (a) H₂O₂ production by g-C₃N₄ and r-CNW-2 under simulated solar, visible, and NIR light illumination for 1 h. The figures are adapted with permission from ref. 208. Copyright 2023, Elsevier. (b) H₂O₂ generation rates of CNZ/BCN(1:1) and CNZ/BCN-Ni_xP_y-x samples. (c) Diagram of photocatalytic H₂O₂ and H₂ formation mechanisms by the CNZ/BCN-Ni_xP_y-x composite. The figures are adapted with permission from ref. 209. Copyright 2023, ACS. (d) Diagrams of the S-scheme heterojunction between WO_{3.72} and 0.5S-pCN before and after contact, showing IEF formation and band bending. The figures are adapted with permission from ref. 212. Copyright 2021, Elsevier. (e) N₂ adsorption-desorption isotherms and pore size distribution profiles. (f) H₂O₂ photocatalysis by samples under UV-vis light. The figures are adapted with permission from ref. 151. Copyright 2021, ACS. *In situ* DRIFTS spectra of SCN/T9 during H₂O₂ generation at (g) 600–4000 cm⁻¹, (h) 600–900 cm⁻¹, and (i) 1300–1550 cm⁻¹. The figures are adapted with permission from ref. 213. Copyright 2023, Elsevier.

CNZ/BCN (1:1) composite (Fig. 28b). This improvement is attributed to the complex intimate contact of the CNZ and BCN Z-scheme heterojunction, along with Ni_xP_y cocatalyst integration, which improves photogenerated charge separation, mobilizes photoexcitons, increases surface reactive sites, and enhances photon absorption (Fig. 28c). Oxygen vacancies also play a crucial role, acting as active sites for H₂O₂ generation, increasing photoexciton transmission, and reducing electron-hole recombination.

Shi *et al.* developed a Z-scheme heterojunction composite, KCN/WO₃, by thermally copolymerizing K⁺-doped g-C₃N₄ (KCN) with WO₃ nanoparticles.²¹⁰ The K⁺ doping of the g-C₃N₄ layers reduced electronic localization and expanded the π conjugated system, facilitating electron transmission. The process of K⁺ doping and WO₃ coupling realised an enhanced charge segregation in g-C₃N₄. The KCN10/WO₃(10%) composite, leveraging the low CB of KCN10 and the high VB of WO₃, signifi-

cantly increased H₂O₂ photocatalytic production to 1.33 mmol L⁻¹ in 4 h without O₂ bubbling, a 27-fold improvement over undoped g-C₃N₄. W₁₈O₄₉, a sub-stoichiometric tungsten oxide with a tunable bandgap and broad light absorption from visible to NIR, is favored for g-C₃N₄ modification due to its abundant oxygen vacancies and LSPR effect, similar to noble metals. These vacancies lead to collective charge oscillations, enhancing the LSPR effect. Based on this concept, Zhang and co-workers developed a W₁₈O₄₉@g-C₃N₄ two-dimensional layered Z-scheme heterostructure, using *in situ* solvothermal growth of W₁₈O₄₉ nanobelts over the surface of g-C₃N₄ nanosheets.²¹¹ The heterostructure composite using crystalline g-C₃N₄ (W₁₈O₄₉-CCN) exhibited higher crystallinity and an improved interface compared to its amorphous counterpart (W₁₈O₄₉-ACN), enhancing the photogenerated charge carrier transport efficiency. This resulted in extended light absorption from Vis to NIR and significantly higher charge separation/

transport efficiency in $W_{18}O_{49}$ -CCN. $W_{18}O_{49}$ -CCN achieved a H_2O_2 evolution rate of $5550 \mu M g^{-1} h^{-1}$ under the full spectrum, which was about 2.4 times that of $W_{18}O_{49}$ -ACN. This performance is attributed to the synergistic effect of the Z-scheme structure and improved interfacial structure in $W_{18}O_{49}$ -CCN. Similarly, Li and colleagues synthesized a 2D S-scheme photocatalyst by combining sulfur-doped porous $g-C_3N_4$ (S-pCN) and tungsten oxide ($WO_{2.72}$) semiconductors *via* a solvent evaporation-induced self-assembly.²¹² This novel composite, showcasing optimal contact and excellent photocatalytic performance, achieved a H_2O_2 yield of $87 \mu M$ in 3 h under illumination without sacrificial agents in distilled water. This efficiency is due to the oxygen vacancies and the tunable localized surface plasmon resonance (LSPR) effect of $WO_{2.72}$, alongside the S-scheme mechanism (Fig. 28d).

Liu *et al.* created a $ZnO/g-C_3N_4$ (ZCN) S-scheme heterojunction photocatalyst featuring a hierarchical porous structure, specifically designed for H_2O_2 production, through calcining the urea-impregnated ZIF-8 MOF.¹⁵¹ The formation of macropores in ZCN12 was observed in FESEM images, resulting from ZIF-8 micropore expansion and rupture due to the release of NH_3 gas during calcination, while N_2 physisorption confirmed the presence of micropores and mesopores, as shown in Fig. 28e. This unique hierarchical porous structure of ZCN12 not only enhances mass transport and light absorption but also expands its surface area, offering additional active sites on the surface for photocatalytic H_2O_2 generation. The *in situ* development of $g-C_3N_4$ on ZnO forms a tightly integrated S-scheme heterojunction, leading to the composite's exceptional H_2O_2 production rate of $1544 \mu mol L^{-1} h^{-1}$. This rate is 3.4 and 5 times greater than those of $g-C_3N_4$ and ZnO individually, respectively (Fig. 28f). The improvement in H_2O_2 production is ascribed to both the S-scheme charge transfer mechanism along with the sponge-like architecture of the photocatalyst.

Jiang *et al.* successfully engineered a 3DOM SCN/T S-scheme composite by electrostatically combining TiO_2 nanoparticles with sulfur-doped $g-C_3N_4$ in a 3D ordered macroporous (3DOM) architecture, achieving a high yield of $2128 \mu mol h^{-1} g^{-1}$ in H_2O_2 production from pure water.²¹³ This performance is credited to the combined effects of the 3DOM structure, which enhances surface reactive sites, amplifies light absorption (*via* multiple scattering and the slow photon effect), and facilitates mass transfer, together with the S-scheme heterojunction that enhances exciton separation and redox efficiency. Additionally, this system effectively combines the strong oxidation properties of TiO_2 with the strong reduction capabilities of SCN, enabling efficient ORR and WOR processes for H_2O_2 production. *In situ* DRIFTS analysis after visible-light irradiation revealed enhanced absorption peaks at 805, 877, 995, 1100–1250, and 1330–1514 cm^{-1} , corresponding to tri-triazine units, adsorbed H_2O_2 , adsorbed $\cdot O_2^-$ and $\cdot OOH$ species, and C–N stretching in aromatic rings (Fig. 28h and i). Conversely, water absorption bands at 3500 and 1573 cm^{-1} decreased, indicating its consumption as a proton carrier in O_2 reduction (Fig. 28g), with no $\cdot OH$ bands being detected. This suggests that the triazine structure

in the 3DOM SCN/T S-scheme heterojunctions predominantly facilitate the O_2 reduction pathway in photocatalytic H_2O_2 formation.

Again, the Parida group developed a Z-scheme heterojunction by attaching mixed-phase, macroporous TiO_2 (n-type) nanoparticles onto B-doped $g-C_3N_4$ (BCN) (p-type) nanosheets, using sonication and calcination methods.²¹⁴ Their optimal photocatalyst, TBCN-8, demonstrated the highest efficacy, producing $110 \mu mol h^{-1}$ of H_2O_2 . Liu *et al.* developed an S-scheme heterojunction named CN-HMoP by embedding polyoxometalate (HMoP) nanoparticles into $g-C_3N_4$ nanosheets using a calcination–post hydrothermal method.²¹⁵ This process involves the formation of Mo–N bonds between the Mo atoms of HMoP and the amino groups and N atoms of the triazine rings of $g-C_3N_4$. These bonds facilitate the layer-by-layer insertion of HMoP nanoparticles into the $g-C_3N_4$ lamellae, leading to enhanced charge transfer and reduced carrier transfer resistance by exfoliating $g-C_3N_4$ nanosheets. Furthermore, the resultant S-scheme heterostructure not only facilitates the effective spatial separation of exciton pairs but also maintains high redox potentials, contributing to its superior photocatalytic performance. Under simulated sunlight and visible light, H_2O_2 generation rates of CN-HMoP were 137.1 and 113.1 $\mu mol L^{-1} h^{-1}$, respectively, significantly outperforming those of pristine CN by 17.7 and 16.8 times.

12. Summary, challenges and future prospects

Hydrogen peroxide (H_2O_2), widely used in chemical synthesis, wastewater treatment, metal extraction, and textile bleaching, is gaining global importance for its eco-friendliness. The photocatalytic production of H_2O_2 , utilizing water, oxygen, and solar energy, emerges as a sustainable and cost-effective method, offering a greener and more efficient solution compared to the traditional, polluting anthraquinone process. This approach aligns with carbon-neutral objectives and is ideal for local, decentralized H_2O_2 production. $g-C_3N_4$, a metal-free polymer semiconductor, is promising for photocatalysis due to its attributes like high activity, non-toxicity, stability, effective electronic structure, visible light absorption, readily available precursors, and affordability. Its tri-s-triazine-based structure efficiently drives two-electron transfer to O_2 under visible light, forming superoxo radicals and 1,4-endoperoxide, thus enhancing H_2O_2 production through the ORR pathway. However, the OER is crucial but hindered by its high overpotential, limiting overall H_2O_2 production. Addressing challenges like improving OER kinetics, increasing H_2O_2 selectivity, managing the competition between the 4-electron ORR and HER, and enhancing the driving force are crucial for optimizing H_2O_2 production efficiency using $g-C_3N_4$. Despite its potential, the photocatalytic performance of $g-C_3N_4$ in H_2O_2 production is impeded by several factors: rapid recombination of photo-induced charges, a narrow optical response range, weak oxidation capability, and low H_2O_2 yield and selectivity.



Additionally, its practical application is hindered by a low specific surface area, poor electronic conductivity, and the need for sacrificial agents to consume photoinduced holes, all of which restrict its effectiveness for H_2O_2 generation. Thus, the construction of a $\text{g-C}_3\text{N}_4$ -based direct Z- or S-scheme heterostructure with oxidation-type photocatalysts enables the overall photosynthesis of H_2O_2 by facilitating the simultaneous production of H_2O oxidation and O_2 reduction products by utilizing the spatially separated oxidation and reduction components. This system simultaneously enhances photocatalytic activity by broadening light absorption, improving stability, and boosting charge carrier and redox active site separation, while also prolonging carrier lifetimes and optimizing redox potential. It also aligns with the optical responses of adjacent components, induces band bending, and creates an IEF with preferred band alignment, facilitating the spatial separation of valuable photoinduced carriers, concurrently addressing the mentioned challenges of $\text{g-C}_3\text{N}_4$. Oxidation semiconductors, designed to respond to visible light, should have a more positive VB oxidation potential than that of H_2O , which is essential for the realization of the WOR pathway. Typically, inorganic metal oxides and oxyhalides exhibit excellent stability, potent oxidation capabilities, and effective affinity for surface hydroxyl (*OH) species, aiding the selective formation of H_2O_2 through the WOR. Thus, combining $\text{g-C}_3\text{N}_4$ with oxide/oxyhalide photocatalysts can capitalize on their robust redox potential for enhanced photocatalytic performance. The efficiency of photocatalytic H_2O_2 production significantly relies on several factors: the capacity to harvest light, the rates of charge generation and recombination, the efficiency of charge separation and transfer to the surface of the catalyst, the degree of oxygen adsorption, and the rate of surface redox reactions. Recent research indicates the mechanism of the ORR based on the initial configuration of O_2 adsorption: end-on mode adsorption leads to a stepwise ORR pathway due to the differing reactivities of the oxygen atoms, typical of inorganic photocatalysts, in which O_2 binds to metal sites or oxygen vacancies through one of the oxygen atoms. Conversely, $\text{g-C}_3\text{N}_4$ favors a bridging adsorption mode, with both oxygen atoms attached to the surface *via* π - π interactions, enabling the simultaneous occurrence of both sequential single-electron and concerted two-electron ORR pathways when combined with oxide/oxyhalide photocatalysts.

In recent years, significant progress has been made in photocatalytic H_2O_2 production using $\text{g-C}_3\text{N}_4$ -based direct Z- or S-scheme photocatalysts. However, despite these advancements, the technology remains far from practical, scaled-up application and is still in its infancy, facing numerous challenges that hinder commercial viability and practical applications. This review offers a comprehensive analysis of the current state of the art and suggests further research directions to bridge the gap towards industrial application. The focus for future work should be on enhancing performance and developing high-performance photocatalysts to facilitate the transition to economically viable and industrially feasible photocatalytic H_2O_2 production. Our insights are intended to both

guide and inspire the development of high-performance $\text{g-C}_3\text{N}_4$ -based direct Z- or S-scheme photocatalysts, highlighting the potential for innovative next-generation photocatalyst development in this promising yet challenging field.

(1) In photocatalytic H_2O_2 generation, reaction routes are crucial for selectivity and yield. The 2e^- WOR is inefficient due to a high oxidative potential, while the lower potential of the 4e^- WOR not only produces O_2 for the 2e^- oxygen reduction reaction (ORR), but also facilitates ORR kinetics through intelligently designed interfaces and active sites. Identifying these sites and understanding electron transfer mechanisms are vital. Recent studies show that adjusting the conduction band edge negatively in $\text{g-C}_3\text{N}_4$ semiconductors enhances the one-electron ORR, leading to superoxide radical formation, crucial for H_2O_2 generation *via* the two-step ORR process. The adsorption of these radicals on the surface of the catalyst is key for improving the selectivity and efficiency of H_2O_2 production. Additionally, the choice of electron donor significantly affects the ORR routes in these systems, although the mechanisms behind this are not fully understood. Further research is essential to understand the active site nature, reaction pathways, and their role in high catalytic performance for effective photochemical H_2O_2 generation and the design of novel catalytic systems.

(2) Mesoporous structures in catalysts enhance rapid mass diffusion, aiding in displacing H_2O_2 from the surface and preventing its decomposition, while simplifying the separation process. Focusing on visible light absorption, rather than UV light, further decreases H_2O_2 decomposition. Utilizing heterogeneous reaction systems, such as two- or three-phase systems, helps detach H_2O_2 from catalysts, minimizing decomposition and improving oxygen solubility and diffusion. Surface functionalization to increase hydrophobicity plays a crucial role in creating a barrier between the catalyst and H_2O_2 , thus preventing excess reduction of H_2O_2 and boosting efficient H_2O_2 production under visible light. This hydrophobic modification also enhances oxygen diffusion to active sites while preventing H_2O_2 adsorption during the ORR process.

(3) The DFT method is used to calculate the oxygen adsorption energy and photoinduced carrier distribution, aiding in a deeper understanding of photocatalytic reaction pathways. Techniques like transient-photoinduced current (TPC), transient-photoinduced voltage (TPV), and *in situ* X-ray absorption spectroscopy (XAS) offer atom-level insights into H_2O_2 photo-production. Analyzing O_2 adsorption behaviors, surface effects on O_2 adsorption and activation, intermediate states in H_2O_2 generation, and the influence of active species is essential. *In situ* IR and Raman spectroscopy verify conformational changes to the catalyst and intermediates in reactions. However, existing gas-solid *in situ* methods inadequately represent the liquid-solid reaction environment in photocatalytic H_2O_2 synthesis, necessitating liquid-solid *in situ* spectral technology for an accurate understanding of H_2O and O_2 interactions. Theoretical calculations like band structures, charge density mappings, adsorption energies, and reaction pathways serve as supplementary evidence to support the reliability of the photo-



catalytic synthesis mechanism. Techniques including *in situ* environmental transmission electron microscopy (ETEM), *in situ* Fourier transform infrared (FTIR) spectroscopy, and ultrafast transient absorption (TA) spectroscopy contribute to microscale observations of photocatalyst structures and reactivity, interface reactions, intermediate formation, adsorption/desorption processes and the kinetics of electron transfer during photocatalysis.

(4) The development of standardized protocols for measuring photocatalytic H_2O_2 production is crucial. Consistent standards are essential for accurately comparing the efficacy of different research findings in this field.

(5) Photocatalytic hydrogen peroxide (H_2O_2) production often uses sacrificial agents and powdered catalysts in water, posing recyclability challenges. Embedding these catalysts on films or glass improves recyclability but reduces H_2O_2 yield due to a smaller surface area. The key challenge is to balance high yield with catalyst recycling, requiring innovative designs. Charge carrier separation is the key to producing H_2O_2 efficiently. However, employing organic scavengers to improve this results in byproducts and decomposition problems, which complicate H_2O_2 purification and reduce its scalability. Thus, there is a growing need for scavenger-free photocatalysts that work efficiently under ambient conditions, utilizing photoexcited holes and electrons for the ORR and WOR. Moreover, developing self-sustaining O_2 systems for solar-to-chemical conversion is more economically viable than relying on external oxygen sources.

(6) An innovative approach for enhancing solar energy efficiency involves a photosynthesis system for H_2O_2 that also conducts other oxidation reactions to produce valuable chemicals. Currently, most reactions use low-value sacrificial agents like isopropanol (IPA), which prevent carrier recombination but contaminate H_2O_2 , increasing purification costs. IPA, which is converted into isopropyl aldehyde, could be replaced with compounds like benzyl alcohol or lactic acid, which have oxidized products with higher commercial value, improving h^+ use and adding value to the process.

(7) Focusing on utilizing seawater and wastewater for H_2O_2 production offers a sustainable and cost-effective approach, addressing the issue of freshwater scarcity. The abundance of seawater makes it an ideal alternative for H_2O_2 generation. Using $\text{g-C}_3\text{N}_4$ -based photocatalysts for this purpose could notably reduce costs and boost the feasibility of photocatalytic H_2O_2 evolution technologies.

(8) The photoproduction of H_2O_2 is influenced by factors like reactor design, light intensity, reaction conditions, temperature, catalyst dosages, and variations in ions and pH levels. Despite their importance, these critical factors have been underexplored in recent research. Hence, a thorough understanding of their impact on catalytic efficiency is crucial for enhancing H_2O_2 production for industrial applications.

(9) Enhancing Z- and S-scheme heterojunction performance requires using appropriate preparation techniques to ensure robust connections between reductive and oxidative photocatalysts and minimizing interfacial charge carrier resistance. The templated hydrothermal approach merges the RSP and OSP

effectively and involves preparing one type of photocatalyst as a substrate, onto which the other type of precursor electrostatically attaches and is eventually converted into a bonded photocatalyst on the substrate under supercritical hydrothermal conditions. For stable Z- and S-scheme heterojunctions with polymeric photocatalysts, on-surface thermal polymerization is commonly used.

(10) Over time, $\text{g-C}_3\text{N}_4$ -based heterojunction photocatalysts can lose their effectiveness due to reduced component interactions, affecting charge transfer efficiency and performance. Enhancing interactions and stability in $\text{g-C}_3\text{N}_4$ systems for real-world applications requires further research. Cost reduction in H_2O_2 production can be achieved through efficient synthesis and separation processes, but there are challenges to address, such as long-term stability and the need for additional purification due to the powdered nature of the materials. The production of H_2O_2 , which requires a constant oxygen flow and sacrificial agents, could be simplified and made more cost-effective by using oxygen from the air and water from abundant sources like seawater or wastewater, eliminating the need for sacrificial agents.

(11) The Z- or S-scheme-based heterojunctions, with their strong interfacial electric fields, effectively encourage the anisotropic separation of e^- and h^+ , reducing recombination in bulk and surface areas. However, optimizing this field is challenging due to charge carrier and defect saturation. A suggested and effective strategy to counter this involves enhancing the interfacial electric field (IEF) and charge carrier separation through piezoelectric effects, using piezoelectric and ferroelectric polarization fields, particularly in semiconductors with non-centrosymmetric polar structures. For $\text{g-C}_3\text{N}_4$ -based heterostructures, developing piezoelectric and ferroelectric polarization through specific modifications can improve carrier transfer efficiency and suppress recombination, making the research and development of these piezoelectric heterojunctions a promising field.

In conclusion, this research opens new avenues for designing cost-effective, highly selective photocatalysts with enhanced activity and stability, which could revolutionize the field of photocatalytic H_2O_2 production and have far-reaching implications for renewable energy, environmental remediation, and green chemistry.

Author contributions

Subrat Kumar Sahoo: thought design, concept analysis, visualization, writing – original draft, and revising the manuscript. Lopamudra Acharya, Lijarani Biswal and Priyanka Priyadarshini: writing – reviewing, editing and finalising. Kulamani Parida: supervision, reviewing and revising the manuscript.

Conflicts of interest

There are no conflicts to declare.



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